

4.3 - The Scattering Matrix

Reading Assignment: pp. 174-183

Admittance and Impedance matrices use the quantities $I(z)$, $V(z)$, and $Z(z)$ (or $Y(z)$).

Q: *Is there an **equivalent** matrix for transmission line activity expressed in terms of $V^+(z)$, $V^-(z)$, and $\Gamma(z)$?*

A: Yes! Its called the **scattering matrix**.

HO: THE SCATTERING MATRIX

Q: *Can we likewise determine something **physical** about our device or network by simply **looking** at its scattering matrix?*

A: **HO: MATCHED, RECIPROCAL, LOSSLESS**

EXAMPLE: A LOSSLESS, RECIPROCAL DEVICE

Q: *Isn't all this linear algebra a bit **academic**? I mean, it can't help us design components, can it?*

A: It sure can! An analysis of the scattering matrix can tell us if a certain device is **even possible** to construct, and if so, what the **form** of the device must be.

HO: THE MATCHED, LOSSLESS, RECIPROCAL 3-PORT NETWORK

HO: THE MATCHED, LOSSLESS, RECIPROCAL 4-PORT NETWORK

Q: *But how are scattering parameters useful? How do we use them to solve or analyze real microwave circuit problems?*

A: Study the **examples** provided below!

EXAMPLE: THE SCATTERING MATRIX

EXAMPLE: SCATTERING PARAMETERS

Q: *OK, but how can we determine the scattering matrix of a device?*

A: We must carefully apply our **transmission line theory!**

EXAMPLE: DETERMINING THE SCATTERING MATRIX

Q: *Determining the Scattering Matrix of a multi-port device would seem to be particularly laborious. Is there any way to simplify the process?*

A: Many (if not most) of the useful devices made by us humans exhibit a high degree of **symmetry**. This can greatly **simplify** circuit analysis—if we **know how** to exploit it!

HO: CIRCUIT SYMMETRY

EXAMPLE: USING SYMMETRY TO DETERMINING A SCATTERING MATRIX

Q: *Is there any **other** way to use circuit symmetry to our advantage?*

A: Absolutely! One of the most **powerful** tools in circuit analysis is **Odd-Even Mode** analysis.

HO: SYMMETRIC CIRCUIT ANALYSIS

HO: ODD-EVEN MODE ANALYSIS

EXAMPLE: ODD-EVEN MODE CIRCUIT ANALYSIS

Q: *Aren't you **finished** with this section yet?*

A: Just **one more** very important thing.

HO: GENERALIZED SCATTERING PARAMETERS

EXAMPLE: THE SCATTERING MATRIX OF A CONNECTOR

The Scattering Matrix

At “**low**” frequencies, we can completely characterize a **linear** device or network using an **impedance** matrix, which relates the currents and voltages at **each** device terminal to the currents and voltages at **all** other terminals.

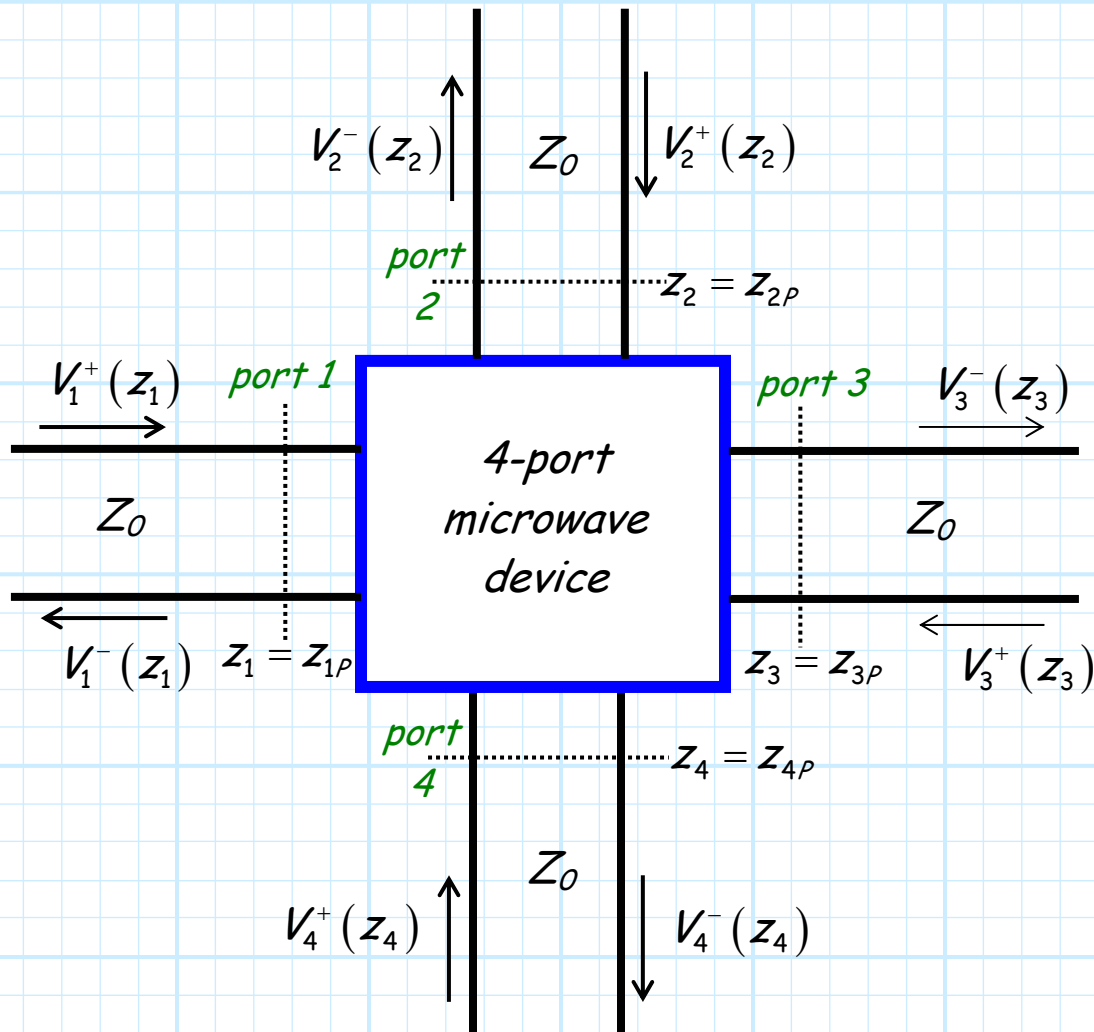
But, at microwave frequencies, it is **difficult** to measure total currents and voltages!



- * Instead, we can measure the **magnitude** and **phase** of each of the two transmission line **waves** $V^+(z)$ and $V^-(z)$.
- * In other words, we can determine the relationship between the incident and reflected wave at **each** device terminal to the incident and reflected waves at **all** other terminals.

These relationships are completely represented by the **scattering matrix**. It **completely** describes the behavior of a linear, multi-port device at a **given frequency** ω , and a given line impedance Z_0 .

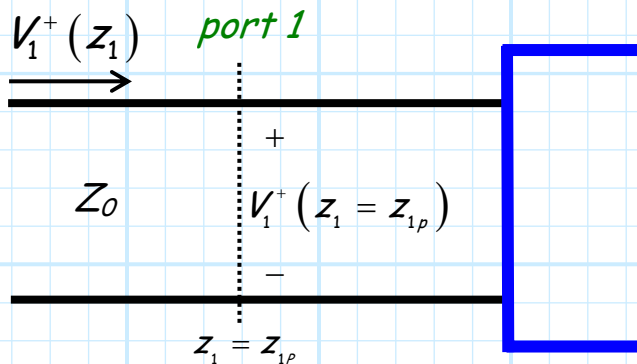
Consider now the **4-port** microwave device shown below:



Note that we have now characterized transmission line activity in terms of incident and "reflected" waves. Note the negative going "reflected" waves can be viewed as the waves **exiting** the multi-port network or device.

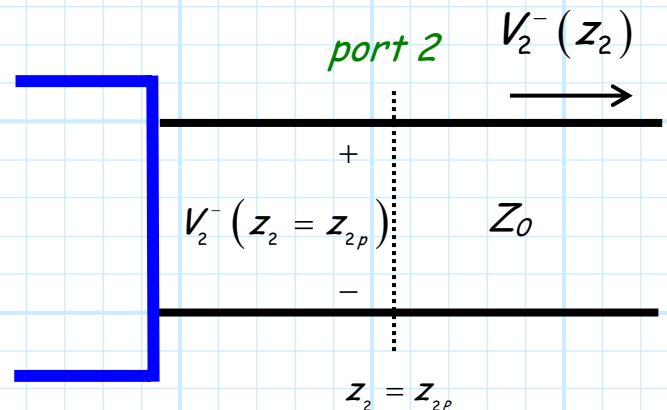
→ Viewing transmission line activity this way, we can fully characterize a multi-port device by its **scattering parameters!**

Say there exists an **incident wave on port 1** (i.e., $V_1^+(z_1) \neq 0$), while the incident waves on all other ports are known to be **zero** (i.e., $V_2^+(z_2) = V_3^+(z_3) = V_4^+(z_4) = 0$).



Say we measure/determine the voltage of the wave flowing **into port 1**, at the port 1 **plane** (i.e., determine $V_1^+(z_1 = z_{1p})$).

Say we then measure/determine the voltage of the wave flowing **out of port 2**, at the port 2 plane (i.e., determine $V_2^-(z_2 = z_{2p})$).



The complex ratio between $V_1^+(z_1 = z_{1p})$ and $V_2^-(z_2 = z_{2p})$ is known as the **scattering parameter S_{21}** :

$$S_{21} = \frac{V_2^-(z_2 = z_{2p})}{V_1^+(z_1 = z_{1p})} = \frac{V_{02}^- e^{+j\beta z_{2p}}}{V_{01}^+ e^{-j\beta z_{1p}}} = \frac{V_{02}^-}{V_{01}^+} e^{+j\beta(z_{2p} + z_{1p})}$$

Likewise, the scattering parameters S_{31} and S_{41} are:

$$S_{31} = \frac{V_3^-(z_3 = z_{3p})}{V_1^+(z_1 = z_{1p})} \quad \text{and} \quad S_{41} = \frac{V_4^-(z_4 = z_{4p})}{V_1^+(z_1 = z_{1p})}$$

We of course could **also** define, say, scattering parameter S_{34} as the ratio between the complex values $V_4^+(z_4 = z_{4p})$ (the wave **into** port 4) and $V_3^-(z_3 = z_{3p})$ (the wave **out of** port 3), given that the input to all other ports (1,2, and 3) are zero.

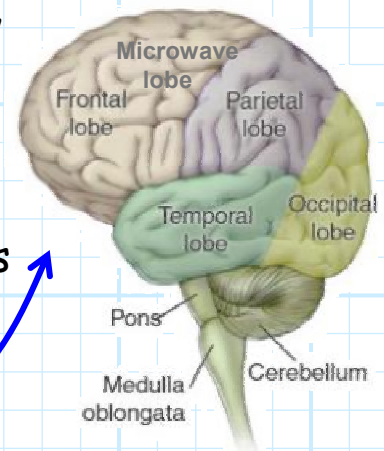
Thus, more **generally**, the ratio of the wave incident on port n to the wave emerging from port m is:

$$S_{mn} = \frac{V_m^-(z_m = z_{mp})}{V_n^+(z_n = z_{np})} \quad (\text{given that } V_k^+(z_k) = 0 \text{ for all } k \neq n)$$

Note that frequently the port positions are assigned a **zero** value (e.g., $z_{1p} = 0, z_{2p} = 0$). This of course **simplifies** the scattering parameter calculation:

$$S_{mn} = \frac{V_m^-(z_m = 0)}{V_n^+(z_n = 0)} = \frac{V_{0m}^- e^{+j\beta 0}}{V_{0n}^+ e^{-j\beta 0}} = \frac{V_{0m}^-}{V_{0n}^+}$$

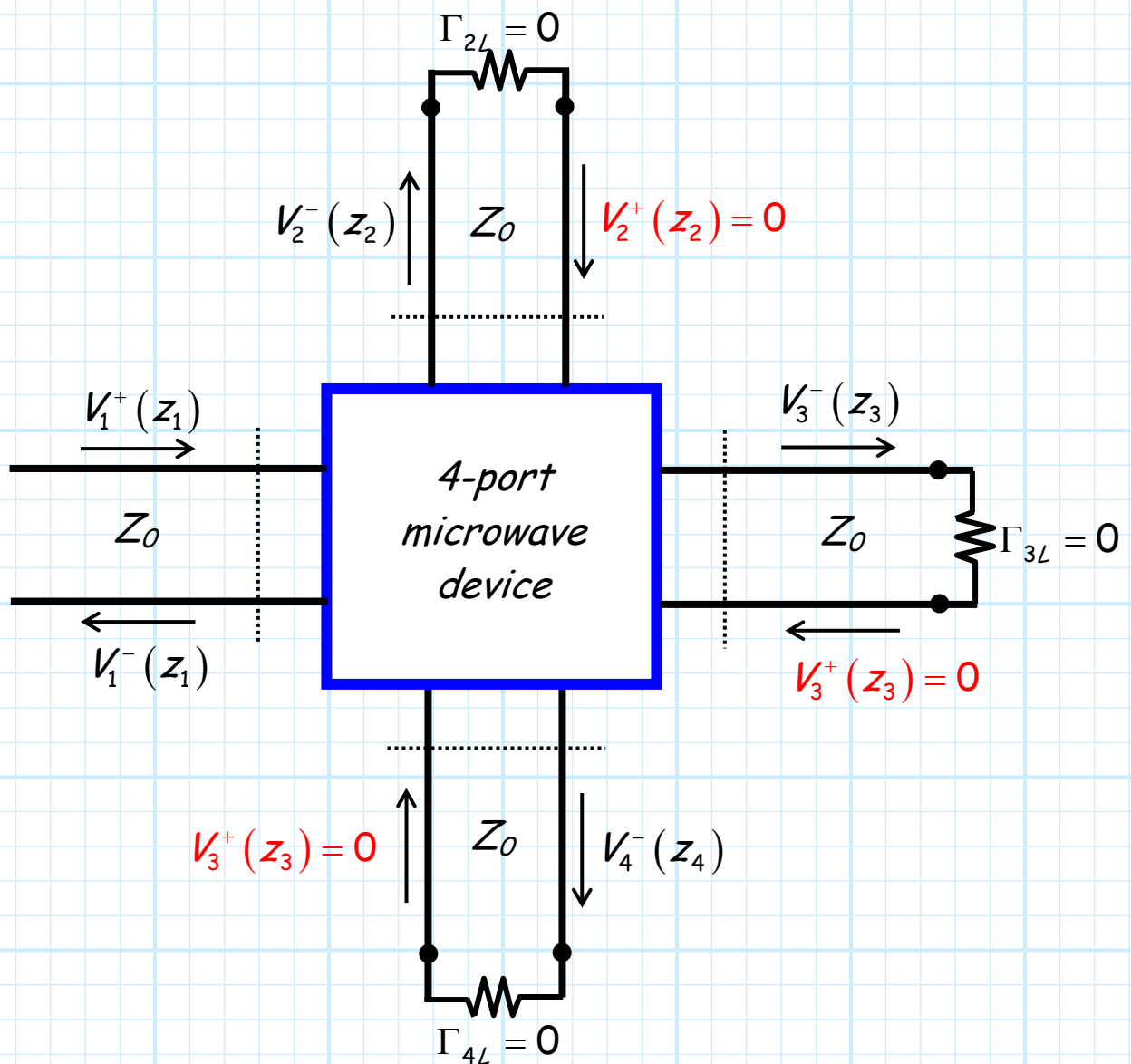
We will **generally assume** that the port locations are defined as $z_{np} = 0$, and thus use the **above** notation. But **remember** where this expression came from!





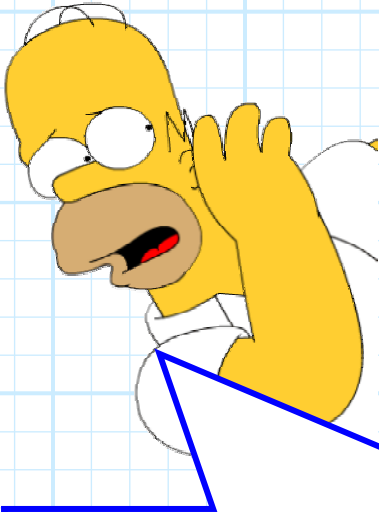
Q: *But how do we ensure that only one incident wave is non-zero?*

A: **Terminate all other ports with a matched load!**



Note that if the ports are terminated in a **matched load** (i.e., $Z_L = Z_0$), then $\Gamma_{nL} = 0$ and therefore:

$$V_n^+(z_n) = 0$$



In other words, terminating a port ensures that there will be **no signal** incident on that port!

Q: *Just between you and me, I think you've messed this up! In all previous handouts you said that if $\Gamma_L = 0$, the wave in the **minus** direction would be zero:*

$$V^-(z) = 0 \quad \text{if} \quad \Gamma_L = 0$$

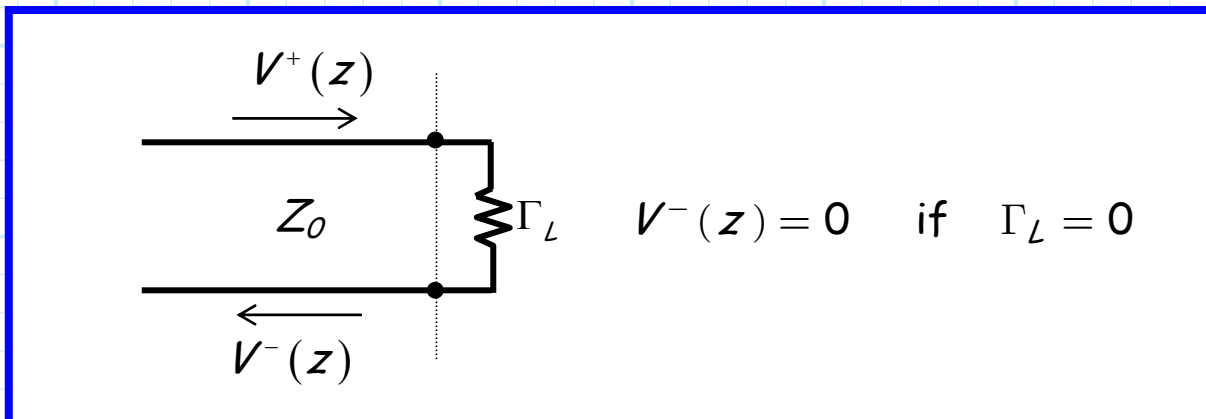
*but just **now** you said that the wave in the **positive** direction would be zero:*

$$V^+(z) = 0 \quad \text{if} \quad \Gamma_L = 0$$

*Of course, there is **no way** that **both** statements can be correct!*

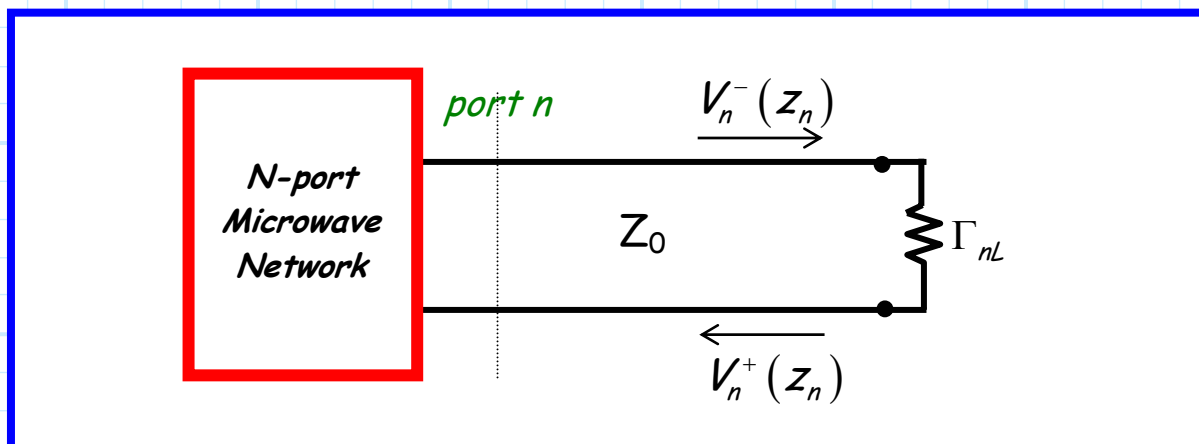
A: Actually, **both** statements are correct! You must be careful to understand the **physical definitions** of the plus and minus directions—in other words, the propagation directions of waves $V_n^+(z_n)$ and $V_n^-(z_n)$!

For example, we **originally** analyzed this case:



In this original case, the wave **incident** on the load is $V^+(z)$ (**plus** direction), while the **reflected** wave is $V^-(z)$ (**minus** direction).

Contrast this with the case we are **now** considering:

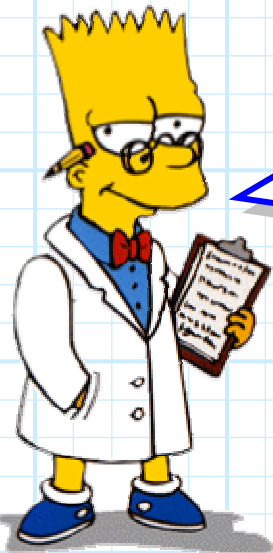


For this current case, the situation is **reversed**. The wave incident on the load is **now** denoted as $V_n^-(z_n)$ (coming **out** of port n), while the wave reflected off the load is **now** denoted as $V_n^+(z_n)$ (going **into** port n).

As a result, $V_n^+(z_n) = 0$ when $\Gamma_{nL} = 0$!

Perhaps we could more **generally** state that for some load Γ_L :

$$V^{\text{reflected}}(z = z_L) = \Gamma_L V^{\text{incident}}(z = z_L)$$



*For each case, you must be able to correctly identify the mathematical statement describing the wave **incident** on, and **reflected** from, some passive load.*

*Like most equations in engineering, the **variable names** can change, but the **physics** described by the mathematics will **not**!*

Now, **back** to our discussion of **S-parameters**. We found that if $z_{np} = 0$ for all ports n , the scattering parameters could be directly written in terms of wave **amplitudes** V_{0n}^+ and V_{0m}^- .

$$S_{mn} = \frac{V_{0m}^-}{V_{0n}^+} \quad (\text{when } V_k^+(z_k) = 0 \text{ for all } k \neq n)$$

Which we can now **equivalently** state as:

$$S_{mn} = \frac{V_{0m}^-}{V_{0n}^+} \quad (\text{when all ports, except port } n, \text{ are terminated in **matched loads**)}$$

One more **important** note—notice that for the ports terminated in matched loads (i.e., those ports with **no** incident wave), the voltage of the exiting **wave** is also the **total** voltage!

$$\begin{aligned} V_m(z_m) &= V_{0m}^+ e^{-j\beta z_m} + V_{0m}^- e^{+j\beta z_m} \\ &= 0 + V_{0m}^- e^{+j\beta z_m} \\ &= V_{0m}^- e^{+j\beta z_m} \quad (\text{for all terminated ports}) \end{aligned}$$

Thus, the value of the exiting wave **at** each terminated **port** is likewise the value of the total voltage **at** those ports:

$$\begin{aligned} V_m(0) &= V_{0m}^+ + V_{0m}^- \\ &= 0 + V_{0m}^- \\ &= V_{0m}^- \quad (\text{for all terminated ports}) \end{aligned}$$

And so, we can express **some** of the scattering parameters equivalently as:

$$S_{mn} = \frac{V_m(0)}{V_{0n}^+} \quad (\text{for terminated port } m, \text{ i.e., for } m \neq n)$$

You might find this result **helpful** if attempting to determine scattering parameters where $m \neq n$ (e.g., S_{21} , S_{43} , S_{13}), as we can often use traditional **circuit theory** to easily determine the **total** port voltage $V_m(0)$.

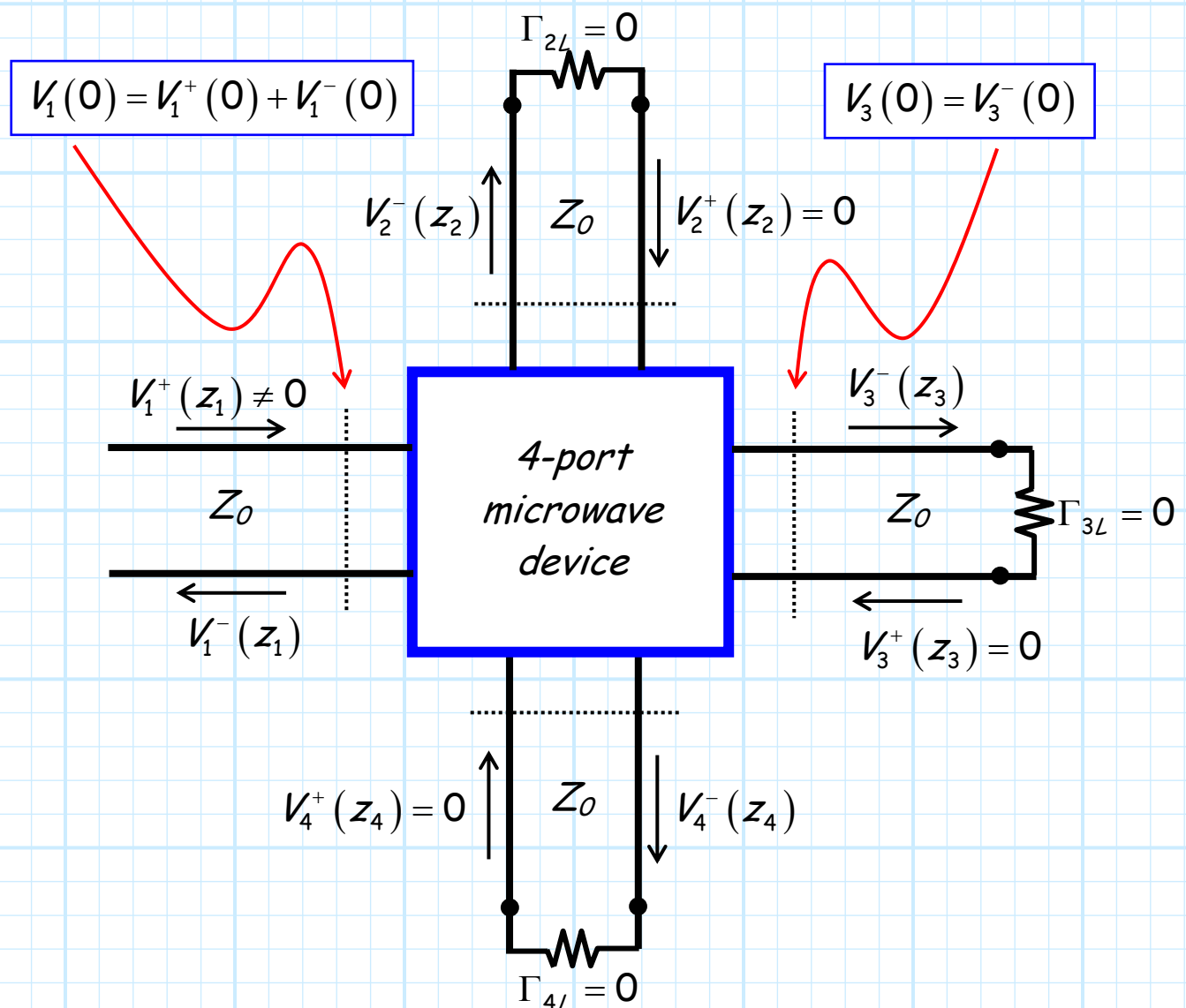
However, we **cannot** use the expression above to determine the scattering parameters when $m = n$ (e.g., S_{11} , S_{22} , S_{33}).



Think about this! The scattering parameters for these cases are:

$$S_{nn} = \frac{V_{0n}^-}{V_{0n}^+}$$

Therefore, port n is a port where there actually is some incident wave V_{0n}^+ (port n is **not** terminated in a matched load!). And thus, the total voltage is **not** simply the value of the exiting wave, as **both** an incident wave and exiting wave exists at port n .



Typically, it is **much** more difficult to determine/measure the scattering parameters of the form S_{nn} , as opposed to scattering parameters of the form S_{mn} (where $m \neq n$) where there is **only** an **exiting** wave from port m !

We can use the scattering matrix to determine the solution for a more **general** circuit—one where the ports are **not** terminated in matched loads!



Q: *I'm not understanding the importance scattering parameters. How are they useful to us microwave engineers?*

A: Since the device is **linear**, we can apply **superposition**. The output at any port due to **all** the incident waves is simply the coherent **sum** of the output at that port due to **each** wave!

For example, the **output** wave at port 3 can be determined by (assuming $z_{nP} = 0$):

$$V_{03}^- = S_{34} V_{04}^+ + S_{33} V_{03}^+ + S_{32} V_{02}^+ + S_{31} V_{01}^+$$

More **generally**, the output at port m of an N -port device is:

$$V_{0m}^- = \sum_{n=1}^N S_{mn} V_{0n}^+ \quad (z_{nP} = 0)$$

This expression can be written in **matrix** form as:

$$\mathbf{V}^- = \mathbf{S} \mathbf{V}^+$$

Where \mathbf{V}^- is the **vector**:

$$\mathbf{V}^- = [V_{01}^-, V_{02}^-, V_{03}^-, \dots, V_{0N}^-]^T$$

and \mathbf{V}^+ is the vector:

$$\mathbf{V}^+ = [V_{01}^+, V_{02}^+, V_{03}^+, \dots, V_{0N}^+]^T$$

Therefore \mathbf{S} is the **scattering matrix**:

$$\mathbf{S} = \begin{bmatrix} S_{11} & \dots & S_{1n} \\ \vdots & \ddots & \vdots \\ S_{m1} & \dots & S_{mn} \end{bmatrix}$$

The scattering matrix is a N by N matrix that **completely characterizes** a linear, N -port device. Effectively, the scattering matrix describes a multi-port device the way that Γ_L describes a single-port device (e.g., a load)!



But **beware!** The values of the scattering matrix for a particular device or network, just like Γ_L , are **frequency dependent!** Thus, it may be more instructive to **explicitly** write:

$$\mathcal{S}(\omega) = \begin{bmatrix} \mathcal{S}_{11}(\omega) & \cdots & \mathcal{S}_{1n}(\omega) \\ \vdots & \ddots & \vdots \\ \mathcal{S}_{m1}(\omega) & \cdots & \mathcal{S}_{mn}(\omega) \end{bmatrix}$$

Also realize that—also just like Γ_L —the scattering matrix is dependent on **both** the **device/network** and the Z_0 value of the **transmission lines connected** to it.

Thus, a device connected to transmission lines with $Z_0 = 50\Omega$ will have a **completely different scattering matrix** than that same device connected to transmission lines with $Z_0 = 100\Omega$!!!

Matched, Lossless, Reciprocal Devices

As we discussed earlier, a device can be **lossless** or **reciprocal**. In addition, we can likewise classify it as being **matched**.

Let's examine **each** of these three characteristics, and how they relate to the **scattering matrix**.

Matched

A matched device is another way of saying that the **input impedance** at each port is **equal to Z_0** when **all other** ports are terminated in matched loads. As a result, the **reflection coefficient** of each port is **zero**—no signal will be come out of a port if a signal is incident on that port (but **only** that port!).

In other words, we want:

$$V_m^- = S_{mm} V_m^+ = 0 \quad \text{for all } m$$

a result that occurs when:

$$S_{mm} = 0 \quad \text{for all } m \text{ if matched}$$

We find therefore that a matched device will exhibit a scattering matrix where all **diagonal elements** are zero.

Therefore:

$$\mathbf{S} = \begin{bmatrix} 0 & 0.1 & j0.2 \\ 0.1 & 0 & 0.3 \\ j0.2 & 0.3 & 0 \end{bmatrix}$$

is an example of a scattering matrix for a **matched**, three port device.

Lossless

For a lossless device, all of the power that delivered to each device port must eventually find its way **out!**

In other words, power is not **absorbed** by the network—no power to be **converted to heat!**

Recall the **power incident** on some port m is related to the amplitude of the **incident wave** (V_{0m}^+) as:

$$P_m^+ = \frac{|V_{0m}^+|^2}{2Z_0}$$

While power of the **wave exiting** the port is:

$$P_m^- = \frac{|V_{0m}^-|^2}{2Z_0}$$

Thus, the power **delivered** to (absorbed by) that port is the **difference** of the two:

$$\Delta P_m = P_m^+ - P_m^- = \frac{|V_{0m}^+|^2}{2Z_0} - \frac{|V_{0m}^-|^2}{2Z_0}$$

Thus, the **total power incident** on an N -port device is:

$$P^+ = \sum_{m=1}^N P_m^+ = \frac{1}{2Z_0} \sum_{m=1}^N |V_{0m}^+|^2$$

Note that:

$$\sum_{m=1}^N |V_{0m}^+|^2 = (\mathbf{V}^+)^H \mathbf{V}^+$$

where operator H indicates the **conjugate transpose** (i.e., Hermetian transpose) operation, so that $(\mathbf{V}^+)^H \mathbf{V}^+$ is the **inner product** (i.e., dot product, or scalar product) of complex vector \mathbf{V}^+ with itself.

Thus, we can write the **total power incident** on the device as:

$$P^+ = \frac{1}{2Z_0} \sum_{m=1}^N |V_{0m}^+|^2 = \frac{(\mathbf{V}^+)^H \mathbf{V}^+}{2Z_0}$$

Similarly, we can express the **total power of the waves exiting** our M -port network to be:

$$P^- = \frac{1}{2Z_0} \sum_{m=1}^N |V_{0m}^-|^2 = \frac{(\mathbf{V}^-)^H \mathbf{V}^-}{2Z_0}$$

Now, recalling that the incident and exiting wave amplitudes are **related** by the **scattering matrix** of the device:

$$\mathbf{V}^- = \mathbf{S} \mathbf{V}^+$$

Thus we find:

$$P^- = \frac{(\mathbf{V}^-)^H \mathbf{V}^-}{2Z_0} = \frac{(\mathbf{V}^+)^H \mathbf{S}^H \mathbf{S} \mathbf{V}^+}{2Z_0}$$

Now, the **total power delivered** to the network is:

$$\Delta P = \sum_{m=1}^M \Delta P = P^+ - P^-$$

Or explicitly:

$$\begin{aligned} \Delta P &= P^+ - P^- \\ &= \frac{(\mathbf{V}^+)^H \mathbf{V}^+}{2Z_0} - \frac{(\mathbf{V}^+)^H \mathbf{S}^H \mathbf{S} \mathbf{V}^+}{2Z_0} \\ &= \frac{1}{2Z_0} (\mathbf{V}^+)^H (\mathbf{I} - \mathbf{S}^H \mathbf{S}) \mathbf{V}^+ \end{aligned}$$

where \mathbf{I} is the **identity matrix**.

Q: *Is there actually some **point** to this long, rambling, complex presentation?*

A: Absolutely! If our M-port device is lossless then the total power exiting the device must **always** be equal to the total power incident on it.

If network is **lossless**, then $P^+ = P^-$.

Or stated another way, the total **power delivered** to the device (i.e., the power absorbed by the device) must always be **zero** if the device is lossless!

If network is **lossless**, then $\Delta P = 0$

Thus, we can conclude from our math that for a **lossless device**:

$$\Delta P = \frac{1}{2Z_0} (\mathbf{V}^+)^H (\mathbf{I} - \mathbf{S}^H \mathbf{S}) \mathbf{V}^+ = 0 \quad \text{for all } \mathbf{V}^+$$

This is true **only** if:

$$\mathbf{I} - \mathbf{S}^H \mathbf{S} = 0 \quad \Rightarrow \quad \mathbf{S}^H \mathbf{S} = \mathbf{I}$$

Thus, we can conclude that the **scattering matrix** of a **lossless** device has the **characteristic**:

If a network is **lossless**, then $\mathbf{S}^H \mathbf{S} = \mathbf{I}$

Q: *Huh? What exactly is this supposed to tell us?*

A: A matrix that satisfies $\mathbf{S}^H \mathbf{S} = \mathbf{I}$ is a special kind of matrix known as a **unitary matrix**.

If a network is **lossless**, then its scattering matrix S is **unitary**.

Q: How do I **recognize** a unitary matrix if I see one?

A: The **columns** of a unitary matrix form an **orthonormal set**!

$$S = \begin{bmatrix} S_{11} & S_{12} & S_{13} & S_{14} \\ S_{21} & S_{22} & S_{23} & S_{24} \\ S_{31} & S_{32} & S_{33} & S_{34} \\ S_{41} & S_{42} & S_{43} & S_{44} \end{bmatrix}$$

**matrix
columns**

In other words, each **column** of the scattering matrix will have a **magnitude equal to one**:

$$\sum_{m=1}^N |S_{mn}|^2 = 1 \quad \text{for all } n$$

while the inner product (i.e., dot product) of **dissimilar columns** must be **zero**.

$$\sum_{n=1}^N S_{ni} S_{nj}^* = S_{1i} S_{1j}^* + S_{2i} S_{2j}^* + \cdots + S_{Ni} S_{Nj}^* = 0 \quad \text{for all } i \neq j$$

In other words, dissimilar columns are **orthogonal**.

Consider, for example, a lossless **three-port** device. Say a signal is incident on port 1, and that **all other ports are terminated**. The power **incident** on port 1 is therefore:

$$P_1^+ = \frac{|V_{01}^+|^2}{2Z_0}$$

while the power **exiting** the device at each port is:

$$P_m^- = \frac{|V_{0m}^-|^2}{2Z_0} = \frac{|S_{m1}V_{01}^-|^2}{2Z_0} = |S_{m1}|^2 P_1^+$$

The **total** power exiting the device is therefore:

$$\begin{aligned} P^- &= P_1^- + P_2^- + P_3^- \\ &= |S_{11}|^2 P_1^+ + |S_{21}|^2 P_1^+ + |S_{31}|^2 P_1^+ \\ &= (|S_{11}|^2 + |S_{21}|^2 + |S_{31}|^2) P_1^+ \end{aligned}$$

Since this device is **lossless**, then the incident power (**only** on port 1) is **equal** to exiting power (i.e, $P^- = P_1^+$). This is true **only** if:

$$|S_{11}|^2 + |S_{21}|^2 + |S_{31}|^2 = 1$$

Of course, this will likewise be true if the incident wave is placed on **any** of the **other** ports of this lossless device:

$$\begin{aligned} |S_{12}|^2 + |S_{22}|^2 + |S_{32}|^2 &= 1 \\ |S_{13}|^2 + |S_{23}|^2 + |S_{33}|^2 &= 1 \end{aligned}$$

We can state in general then that:

$$\sum_{m=1}^3 |S_{mn}|^2 = 1 \quad \text{for all } n$$

In other words, the columns of the scattering matrix must have **unit magnitude** (a requirement of all **unitary** matrices). It is apparent that this must be true for energy to be conserved.

An **example** of a (unitary) scattering matrix for a **lossless** device is:

$$\mathbf{S} = \begin{bmatrix} 0 & 1/2 & j\sqrt{3}/2 & 0 \\ 1/2 & 0 & 0 & j\sqrt{3}/2 \\ j\sqrt{3}/2 & 0 & 0 & 1/2 \\ 0 & j\sqrt{3}/2 & 1/2 & 0 \end{bmatrix}$$

Reciprocal

Recall **reciprocity** results when we build a **passive** (i.e., unpowered) device with **simple** materials.

For a reciprocal network, we find that the elements of the scattering matrix are **related** as:

$$S_{mn} = S_{nm}$$

For example, a **reciprocal** device will have $S_{21} = S_{12}$ or $S_{32} = S_{23}$. We can write reciprocity in matrix form as:

$$\mathbf{S}^T = \mathbf{S} \quad \text{if reciprocal}$$

where T indicates (non-conjugate) transpose.

An **example** of a scattering matrix describing a **reciprocal**, but **lossy** and **non-matched** device is:

$$\underline{\underline{\mathbf{S}}} = \begin{bmatrix} 0.10 & -0.40 & -j0.20 & 0.05 \\ -0.40 & j0.20 & 0 & j0.10 \\ -j0.20 & 0 & 0.10 - j0.30 & -0.12 \\ 0.05 & j0.10 & -0.12 & 0 \end{bmatrix}$$

Example: A Lossless, Reciprocal Network

A **lossless, reciprocal** 3-port device has S -parameters of $S_{11} = 1/2$, $S_{31} = 1/\sqrt{2}$, and $S_{33} = 0$. It is likewise known that all scattering parameters are **real**.



→ Find the remaining 6 scattering parameters.

Q: *This problem is clearly impossible—you have not provided us with sufficient information!*

A: Yes I have! Note I said the device was **lossless** and **reciprocal**!

Start with what we **currently** know:

$$\mathcal{S} = \begin{bmatrix} 1/2 & S_{12} & S_{13} \\ S_{21} & S_{22} & S_{23} \\ 1/\sqrt{2} & S_{32} & 0 \end{bmatrix}$$

Because the device is **reciprocal**, we then also know:

$$S_{21} = S_{12}$$

$$S_{13} = S_{31} = 1/\sqrt{2}$$

$$S_{32} = S_{23}$$

And therefore:

$$\mathcal{S} = \begin{bmatrix} 1/2 & \mathcal{S}_{21} & 1/\sqrt{2} \\ \mathcal{S}_{21} & \mathcal{S}_{22} & \mathcal{S}_{32} \\ 1/\sqrt{2} & \mathcal{S}_{32} & 0 \end{bmatrix}$$

Now, since the device is **lossless**, we know that:

$$\begin{aligned} 1 &= |\mathcal{S}_{11}|^2 + |\mathcal{S}_{21}|^2 + |\mathcal{S}_{31}|^2 \\ &= (1/2)^2 + |\mathcal{S}_{21}|^2 + (1/\sqrt{2})^2 \end{aligned}$$

$$\begin{aligned} 1 &= |\mathcal{S}_{12}|^2 + |\mathcal{S}_{22}|^2 + |\mathcal{S}_{32}|^2 \\ &= |\mathcal{S}_{21}|^2 + |\mathcal{S}_{22}|^2 + |\mathcal{S}_{32}|^2 \end{aligned}$$

$$\begin{aligned} 1 &= |\mathcal{S}_{13}|^2 + |\mathcal{S}_{23}|^2 + |\mathcal{S}_{33}|^2 \\ &= (1/2)^2 + |\mathcal{S}_{32}|^2 + (1/\sqrt{2})^2 \end{aligned}$$

Columns have
unit magnitude.

and:

$$\begin{aligned} 0 &= \mathcal{S}_{11}\mathcal{S}_{12}^* + \mathcal{S}_{21}\mathcal{S}_{22}^* + \mathcal{S}_{31}\mathcal{S}_{32}^* \\ &= 1/2 \mathcal{S}_{21}^* + \mathcal{S}_{21}\mathcal{S}_{22}^* + 1/\sqrt{2} \mathcal{S}_{32}^* \end{aligned}$$

$$\begin{aligned} 0 &= \mathcal{S}_{11}\mathcal{S}_{13}^* + \mathcal{S}_{21}\mathcal{S}_{23}^* + \mathcal{S}_{31}\mathcal{S}_{33}^* \\ &= 1/2 (1/\sqrt{2}) + \mathcal{S}_{21}\mathcal{S}_{32}^* + 1/\sqrt{2} (0) \end{aligned}$$

$$\begin{aligned} 0 &= \mathcal{S}_{12}\mathcal{S}_{13}^* + \mathcal{S}_{22}\mathcal{S}_{23}^* + \mathcal{S}_{32}\mathcal{S}_{33}^* \\ &= \mathcal{S}_{21} (1/\sqrt{2}) + \mathcal{S}_{22}\mathcal{S}_{32}^* + \mathcal{S}_{32} (0) \end{aligned}$$

Columns are
orthogonal.

These six expressions simplify to:

$$|S_{21}| = 1/2$$

$$1 = |S_{21}|^2 + |S_{22}|^2 + |S_{32}|^2$$

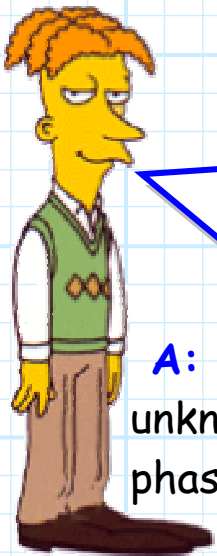
$$|S_{32}| = 1/\sqrt{2}$$

$$0 = 1/2 S_{21} + S_{21} S_{22} + 1/\sqrt{2} S_{32}$$

$$0 = 1/(2\sqrt{2}) + S_{21} S_{32}$$

$$0 = S_{21} (1/\sqrt{2}) + S_{22} S_{32}$$

where we have used the fact that since the elements are all **real**, then $S_{21}^* = S_{21}$ (etc.).



Q: *I count the expressions and find 6 equations yet only a paltry 3 unknowns. Your typical buffoonery appears to have led to an over-constrained condition for which there is **no** solution!*

A: Actually, we have **six** real equations and **six** real unknowns, since scattering element has a magnitude and phase. In this case we know the values are **real**, and thus the phase is either 0° or 180° (i.e., $e^{j0} = 1$ or $e^{j\pi} = -1$); however, we do not know which one!

From the first three equations, we can find the **magnitudes**:

$$|S_{21}| = 1/2$$

$$|S_{22}| = 1/2$$

$$|S_{32}| = 1/\sqrt{2}$$

and from the last three equations we find the **phase**:

$$S_{21} = 1/2$$

$$S_{22} = 1/2$$

$$S_{32} = -1/\sqrt{2}$$

Thus, the scattering matrix for this **lossless, reciprocal** device is:

$$\mathbf{S} = \begin{bmatrix} 1/2 & 1/2 & 1/\sqrt{2} \\ 1/2 & 1/2 & -1/\sqrt{2} \\ 1/\sqrt{2} & -1/\sqrt{2} & 0 \end{bmatrix}$$

A Matched, Lossless Reciprocal 3-Port Network

Consider a 3-port device. Such a device would have a scattering matrix :

$$\mathcal{S} = \begin{bmatrix} S_{11} & S_{12} & S_{13} \\ S_{21} & S_{22} & S_{23} \\ S_{31} & S_{32} & S_{33} \end{bmatrix}$$

Assuming the device is passive and made of simple (isotropic) materials, the device will be **reciprocal**, so that:

$$S_{21} = S_{12} \quad S_{31} = S_{13} \quad S_{23} = S_{32}$$

Likewise, if it is **matched**, we know that:

$$S_{11} = S_{22} = S_{33} = 0$$

As a result, a **lossless, reciprocal** device would have a scattering matrix of the form:

$$\mathcal{S} = \begin{bmatrix} 0 & S_{21} & S_{31} \\ S_{21} & 0 & S_{32} \\ S_{31} & S_{32} & 0 \end{bmatrix}$$

Just **3** non-zero scattering parameters define the **entire** matrix!

Likewise, if we wish for this network to be **lossless**, the scattering matrix must be **unitary**, and therefore:

$$\begin{aligned} |S_{21}|^2 + |S_{31}|^2 &= 1 & S_{31}^* S_{32} &= 0 \\ |S_{21}|^2 + |S_{32}|^2 &= 1 & S_{21}^* S_{32} &= 0 \\ |S_{31}|^2 + |S_{32}|^2 &= 1 & S_{21}^* S_{31} &= 0 \end{aligned}$$

Since each complex value S is represented by **two real numbers** (i.e., real and imaginary parts), the equations above result in **9** real equations. The problem is, the 3 complex values S_{21} , S_{31} and S_{32} are represented by only **6** real unknowns.

We have **over constrained** our problem! There are **no solutions** to these equations!



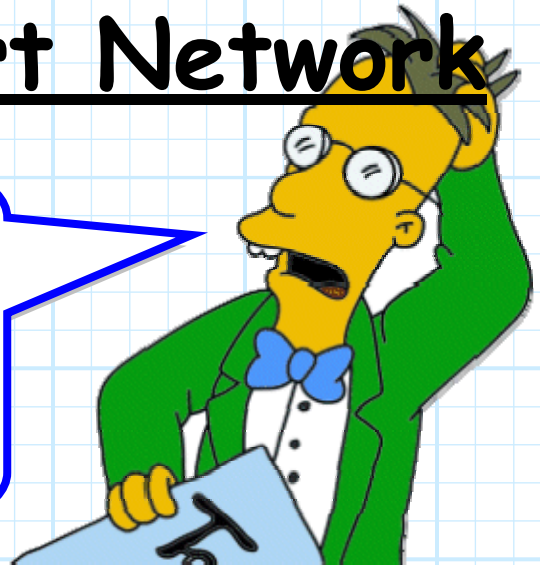
*As unlikely as it might seem, this means that a matched, lossless, reciprocal 3-port device of **any kind** is a **physical impossibility!***

*You **can** make a lossless reciprocal 3-port device, **or** a matched reciprocal 3-port device, **or even** a matched, lossless (but non-reciprocal) 3-port network.*

*But try as you might, you **cannot** make a lossless, matched, **and** reciprocal three port component!*

The Matched, Lossless, Reciprocal 4-Port Network

Guess what! I have determined that—unlike a 3-port device—a matched, lossless, reciprocal 4-port device is physically possible! In fact, I've found two general solutions!



The first solution is referred to as the **symmetric** solution:

$$\mathbf{S} = \begin{bmatrix} 0 & \alpha & j\beta & 0 \\ \alpha & 0 & 0 & j\beta \\ j\beta & 0 & 0 & \alpha \\ 0 & j\beta & \alpha & 0 \end{bmatrix}$$

Note for this symmetric solution, every row and every column of the scattering matrix has the **same** four values (i.e., α , $j\beta$, and two zeros)!

The second solution is referred to as the **anti-symmetric** solution:

$$\mathbf{S} = \begin{bmatrix} 0 & \alpha & \beta & 0 \\ \alpha & 0 & 0 & -\beta \\ \beta & 0 & 0 & \alpha \\ 0 & -\beta & \alpha & 0 \end{bmatrix}$$

Note that for this anti-symmetric solution, **two** rows and **two** columns have the same four values (i.e., α , β , and two zeros), while the **other** two row and columns have (slightly) **different** values (α , $-\beta$, and two zeros)

It is **quite** evident that each of these solutions are **matched** and **reciprocal**. However, to ensure that the solutions are indeed **lossless**, we must place an **additional** constraint on the values of α , β . Recall that a **necessary** condition for a lossless device is:

$$\sum_{m=1}^N |S_{mn}|^2 = 1 \quad \text{for all } n$$

Applying this to the **symmetric** case, we find:

$$|\alpha|^2 + |\beta|^2 = 1$$

Likewise, for the **anti-symmetric** case, we also get

$$|\alpha|^2 + |\beta|^2 = 1$$

It is evident that if the scattering matrix is **unitary** (i.e., lossless), the values α and β **cannot** be independent, but must **related** as:

$$|\alpha|^2 + |\beta|^2 = 1$$

Generally speaking, we will find that $|\alpha| \geq |\beta|$. Given the constraint on these two values, we can thus conclude that:

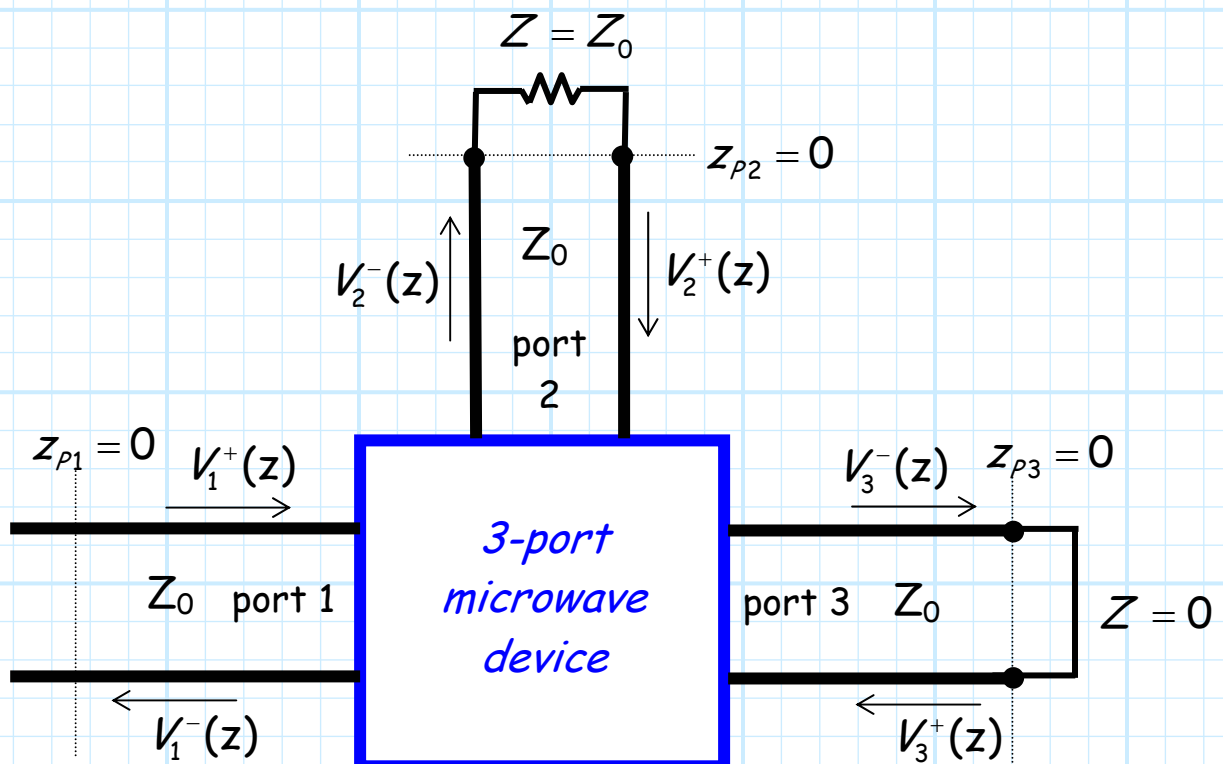
$$0 \leq |\beta| \leq \frac{1}{\sqrt{2}} \quad \text{and} \quad \frac{1}{\sqrt{2}} \leq |\alpha| \leq 1$$

Example: The Scattering Matrix

Say we have a 3-port network that is completely characterized at some frequency ω by the **scattering matrix**:

$$\mathcal{S} = \begin{bmatrix} 0.0 & 0.2 & 0.5 \\ 0.5 & 0.0 & 0.2 \\ 0.5 & 0.5 & 0.0 \end{bmatrix}$$

A **matched load** is attached to port 2, while a **short circuit** has been placed at port 3:



Because of the **matched** load at port 2 (i.e., $\Gamma_L = 0$), we know that:

$$\frac{V_2^+(z_2 = 0)}{V_2^-(z_2 = 0)} = \frac{V_{02}^+}{V_{02}^-} = 0$$

and therefore:

$$V_{02}^+ = 0$$



You've made a terrible mistake! Fortunately, I was here to correct it for you—since $\Gamma_L = 0$, the constant V_{02}^- (not V_{02}^+) is equal to zero.

NO!! Remember, the signal $V_2^-(z)$ is **incident** on the matched load, and $V_2^+(z)$ is the **reflected** wave from the load (i.e., $V_2^+(z)$ is incident on **port 2**). Therefore, $V_{02}^+ = 0$ is **correct!**

Likewise, because of the **short** circuit at port 3 ($\Gamma_L = -1$):

$$\frac{V_3^+(z_3 = 0)}{V_3^-(z_3 = 0)} = \frac{V_{03}^+}{V_{03}^-} = -1$$

and therefore:

$$V_{03}^+ = -V_{03}^-$$

Problem:

a) Find the **reflection** coefficient at port 1, i.e.:

$$\Gamma_1 \doteq \frac{V_{01}^-}{V_{01}^+}$$

b) Find the **transmission** coefficient from port 1 to port 2, i.e.,

$$T_{21} \doteq \frac{V_{02}^-}{V_{01}^+}$$

*I am amused by the trivial problems that **you** apparently find so difficult. I know that:*

$$\Gamma_1 = \frac{V_{01}^-}{V_{01}^+} = S_{11} = 0.0$$

and

$$T_{21} = \frac{V_{02}^-}{V_{01}^+} = S_{21} = 0.5$$



NO!!! The above statement is **not correct!**



Remember, $V_{01}^-/V_{01}^+ = S_{11}$ **only** if ports 2 and 3 are terminated in **matched** loads! In this problem port 3 is terminated with a **short circuit**.

Therefore:

$$\Gamma_1 = \frac{V_{01}^-}{V_{01}^+} \neq S_{11}$$

and similarly:

$$T_{21} = \frac{V_{02}^-}{V_{01}^+} \neq S_{21}$$

To determine the values T_{21} and Γ_1 , we must start with the **three** equations provided by the **scattering matrix**:

$$V_{01}^- = 0.2 V_{02}^+ + 0.5 V_{03}^+$$

$$V_{02}^- = 0.5 V_{01}^+ + 0.2 V_{03}^+$$

$$V_{03}^- = 0.5 V_{01}^+ + 0.5 V_{02}^+$$

and the **two** equations provided by the **attached loads**:

$$V_{02}^+ = 0$$

$$V_{03}^+ = -V_{03}^-$$

We can divide all of these equations by V_{01}^+ , resulting in:

$$\Gamma_1 = \frac{V_{01}^-}{V_{01}^+} = 0.2 \frac{V_{02}^+}{V_{01}^+} + 0.5 \frac{V_{03}^+}{V_{01}^+}$$

$$\mathcal{T}_{21} = \frac{V_{02}^-}{V_{01}^+} = 0.5 + 0.2 \frac{V_{03}^+}{V_{01}^+}$$

$$\frac{V_{03}^-}{V_{01}^+} = 0.5 + 0.5 \frac{V_{02}^+}{V_{01}^+}$$

$$\frac{V_{02}^+}{V_{01}^+} = 0$$

$$\frac{V_{03}^+}{V_{01}^+} = -\frac{V_{03}^-}{V_{01}^+}$$

Look what we have—**5** equations and **5** unknowns! Inserting equations 4 and 5 into equations 1 through 3, we get:

$$\Gamma_1 = \frac{V_{01}^-}{V_{01}^+} = -0.5 \frac{V_{03}^+}{V_{01}^+}$$

$$\mathcal{T}_{21} = \frac{V_{02}^-}{V_{01}^+} = 0.5 - 0.2 \frac{V_{03}^+}{V_{01}^+}$$

$$\frac{V_{03}^-}{V_{01}^+} = 0.5$$

Solving, we find:

$$\Gamma_1 = -0.5(0.5) = -0.25$$

$$T_{21} = 0.5 - 0.2(0.5) = 0.4$$

Example: Scattering Parameters

Consider a **two-port device** with a scattering matrix (at some specific frequency ω_0):

$$\mathcal{S}(\omega = \omega_0) = \begin{bmatrix} 0.1 & j0.7 \\ j0.7 & -0.2 \end{bmatrix}$$

and $Z_0 = 50\Omega$.

Say that the transmission line connected to **port 2** of this device is terminated in a **matched load**, and that the wave **incident on port 1** is:

$$V_1^+(z_1) = -j2 e^{-j\beta z_1}$$

where $z_{1p} = z_{2p} = 0$.

Determine:

1. the port voltages $V_1(z_1 = z_{1p})$ and $V_2(z_2 = z_{2p})$.
2. the port currents $I_1(z_1 = z_{1p})$ and $I_2(z_2 = z_{2p})$.
3. the net power flowing into port 1

1. Since the **incident** wave on port 1 is:

$$V_1^+(z_1) = -j2 e^{-j\beta z_1}$$

we can conclude (since $z_{1\rho} = 0$):

$$\begin{aligned} V_1^+(z_1 = z_{1\rho}) &= -j2 e^{-j\beta z_{1\rho}} \\ &= -j2 e^{-j\beta(0)} \\ &= -j2 \end{aligned}$$

and since port 2 is **matched** (and **only** because its matched!), we find:

$$\begin{aligned} V_1^-(z_1 = z_{1\rho}) &= S_{11} V_1^+(z_1 = z_{1\rho}) \\ &= 0.1(-j2) \\ &= -j0.2 \end{aligned}$$

The voltage at port 1 is thus:

$$\begin{aligned} V_1(z_1 = z_{1\rho}) &= V_1^+(z_1 = z_{1\rho}) + V_1^-(z_1 = z_{1\rho}) \\ &= -j2.0 - j0.2 \\ &= -j2.2 \\ &= 2.2 e^{-j\pi/2} \end{aligned}$$

Likewise, since port 2 is **matched**:

$$V_2^+(z_2 = z_{2\rho}) = 0$$

And also:

$$\begin{aligned} V_2^-(z_2 = z_{2P}) &= S_{21} V_1^+(z_1 = z_{1P}) \\ &= j0.7 (-j2) \\ &= 1.4 \end{aligned}$$

Therefore:

$$\begin{aligned} V_2(z_2 = z_{2P}) &= V_2^+(z_2 = z_{2P}) + V_2^-(z_2 = z_{2P}) \\ &= 0 + 1.4 \\ &= 1.4 \\ &= 1.4 e^{-j0} \end{aligned}$$

2. The port **currents** can be easily determined from the results of the previous section.

$$\begin{aligned} I_1(z_1 = z_{1P}) &= I_1^+(z_1 = z_{1P}) - I_1^-(z_1 = z_{1P}) \\ &= \frac{V_1^+(z_1 = z_{1P})}{Z_0} - \frac{V_1^-(z_1 = z_{1P})}{Z_0} \\ &= -j \frac{2.0}{50} + j \frac{0.2}{50} \\ &= -j \frac{1.8}{50} \\ &= -j0.036 \\ &= 0.036 e^{-j\pi/2} \end{aligned}$$

and:

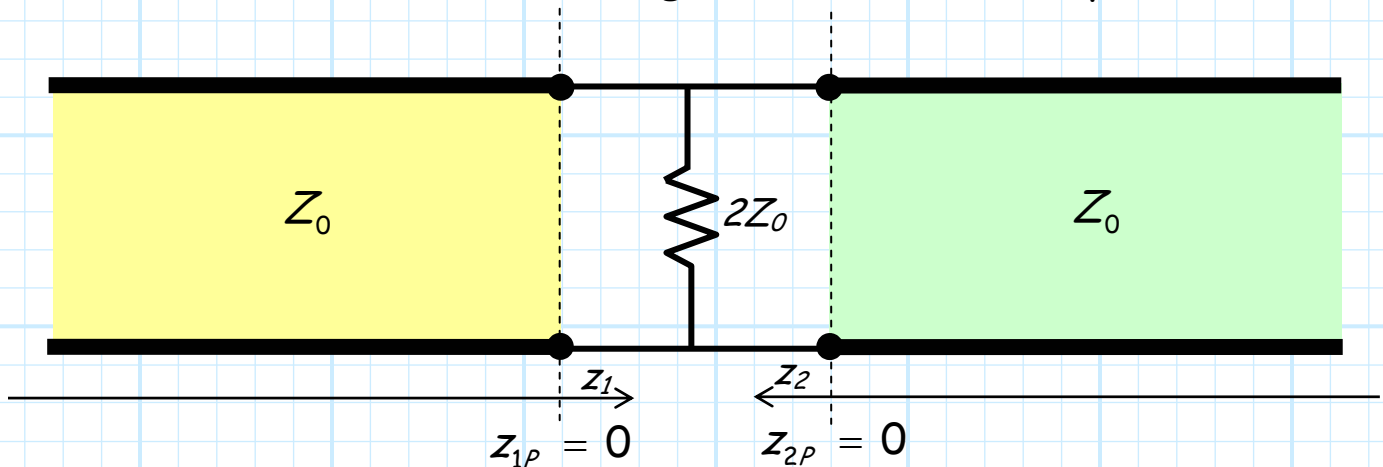
$$\begin{aligned}
 I_2(z_2 = z_{2P}) &= I_2^+(z_2 = z_{2P}) - I_2^-(z_2 = z_{2P}) \\
 &= \frac{V_2^+(z_2 = z_{2P})}{Z_0} - \frac{V_2^-(z_2 = z_{2P})}{Z_0} \\
 &= \frac{0}{50} - \frac{1.4}{50} \\
 &= -0.028 \\
 &= 0.028 e^{+j\pi}
 \end{aligned}$$

3. The net power flowing into port 1 is:

$$\begin{aligned}
 \Delta P_1 &= P_1^+ - P_1^- \\
 &= \frac{|V_{01}^+|^2}{2Z_0} - \frac{|V_{01}^-|^2}{2Z_0} \\
 &= \frac{(2)^2 - (0.2)^2}{2(50)} \\
 &= 0.0396 \text{ Watts}
 \end{aligned}$$

Example: Determining the Scattering Matrix

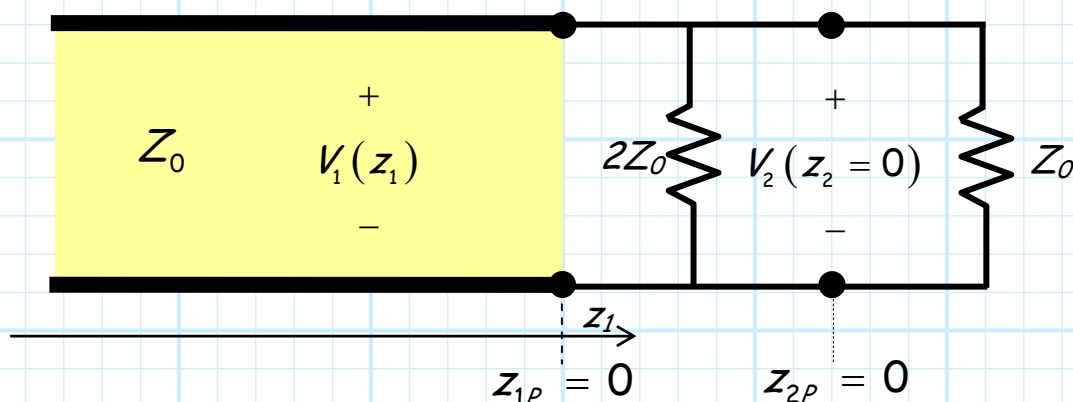
Let's determine the scattering matrix of this two-port device:



The first step is to terminate port 2 with a **matched load**, and then determine the values:

$$V_1^-(z_1 = z_{p1}) \quad \text{and} \quad V_2^-(z_2 = z_{p2})$$

in terms of $V_1^+(z_1 = z_{p1})$.



Recall that since port 2 is matched, we know that:

$$V_2^+(z_2 = z_{2p}) = 0$$

And thus:

$$\begin{aligned} V_2(z_2 = 0) &= V_2^+(z_2 = 0) + V_2^-(z_2 = 0) \\ &= 0 + V_2^-(z_2 = 0) \\ &= V_2^-(z_2 = 0) \end{aligned}$$

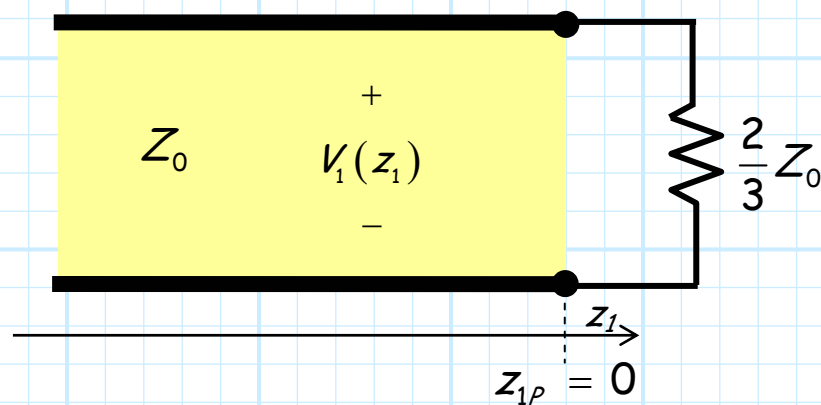
In other words, we **simply** need to determine $V_2^-(z_2 = 0)$ in order to find $V_2^-(z_2 = 0)$!

However, determining $V_1^-(z_1 = 0)$ is a bit **trickier**. Recall that:

$$V_1(z_1) = V_1^+(z_1) + V_1^-(z_1)$$

Therefore we find $V_1(z_1 = 0) \neq V_1^-(z_1 = 0)$!

Now, we can **simplify** this circuit:



And we know from the **telegraphers equations**:

$$\begin{aligned} V_1(z_1) &= V_1^+(z_1) + V_1^-(z_1) \\ &= V_{01}^+ e^{-j\beta z_1} + V_{01}^- e^{+j\beta z_1} \end{aligned}$$

Since the load $2Z_0/3$ is located at $z_1 = 0$, we know that the boundary condition leads to:

$$V_1(z_1) = V_{01}^+ (e^{-j\beta z_1} + \Gamma_L e^{+j\beta z_1})$$

where:

$$\begin{aligned} \Gamma_L &= \frac{(\frac{2}{3})Z_0 - Z_0}{(\frac{2}{3})Z_0 + Z_0} \\ &= \frac{(\frac{2}{3}) - 1}{(\frac{2}{3}) + 1} \\ &= \frac{-\frac{1}{3}}{\frac{5}{3}} \\ &= -0.2 \end{aligned}$$

Therefore:

$$V_1^+(z_1) = V_{01}^+ e^{-j\beta z_1} \quad \text{and} \quad V_1^-(z_1) = V_{01}^+ (-0.2) e^{+j\beta z_1}$$

and thus:

$$V_1^+(z_1 = 0) = V_{01}^+ e^{-j\beta(0)} = V_{01}^+$$

$$V_1^-(z_1 = 0) = V_{01}^+ (-0.2) e^{+j\beta(0)} = -0.2 V_{01}^+$$

We can now determine S_{11} !

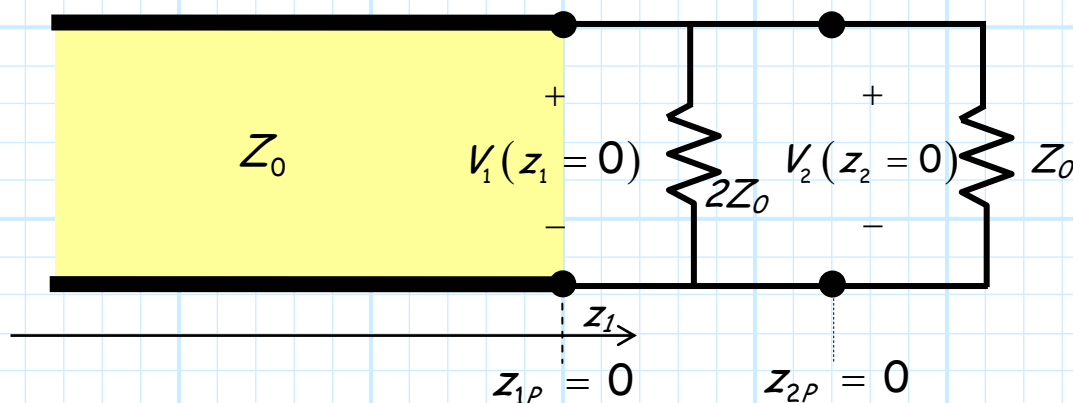
$$S_{11} = \frac{V_1^-(z_1 = 0)}{V_1^+(z_1 = 0)} = \frac{-0.2 V_{01}^+}{V_{01}^+} = -0.2$$

Now its time to find $V_2^-(z_2 = 0)$!

Again, since port 2 is terminated, the **incident** wave on port 2 must be **zero**, and thus the value of the **exiting** wave at port 2 is equal to the **total** voltage at port 2:

$$V_2^-(z_2 = 0) = V_2(z_2 = 0)$$

This **total** voltage is relatively **easy** to determine. Examining the circuit, it is evident that $V_1(z_1 = 0) = V_2(z_2 = 0)$.



Therefore:

$$\begin{aligned} V_2(z_2 = 0) &= V_1(z_1 = 0) \\ &= V_{01}^+ \left(e^{-j\beta(0)} - 0.2 e^{+j\beta(0)} \right) \\ &= V_{01}^+ (1 - 0.2) \\ &= V_{01}^+ (0.8) \end{aligned}$$

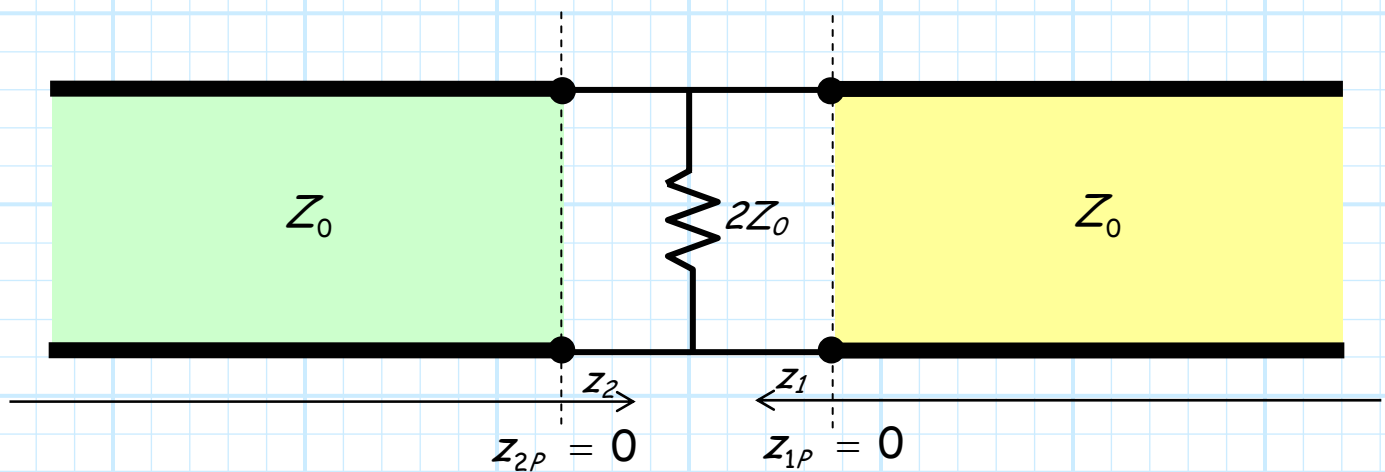
And thus the scattering parameter S_{21} is:

$$S_{21} = \frac{V_2^-(z_2 = 0)}{V_1^+(z_1 = 0)} = \frac{0.8 V_{01}^+}{V_{01}^+} = 0.8$$

Now we **just** need to find S_{12} and S_{22} .

Q: *Yikes! This has been an awful lot of work, and you mean that we are only **half-way** done!?*

A: Actually, we are nearly finished! Note that this circuit is **symmetric**—there is really **no** difference between port 1 and port 2. If we “flip” the circuit, it remains **unchanged**!



Thus, we can conclude due to this **symmetry** that:

$$S_{11} = S_{22} = -0.2$$

and:

$$S_{21} = S_{12} = 0.8$$

Note this last equation is **likewise** a result of **reciprocity**.

Thus, the **scattering matrix** for this two port network is:

$$\mathbf{S} = \begin{bmatrix} -0.2 & 0.8 \\ 0.8 & -0.2 \end{bmatrix}$$

Circuit Symmetry

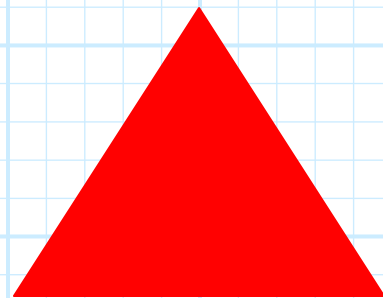
One of the most powerful concepts in for evaluating circuits is that of symmetry. **Normal** humans have a **conceptual** understanding of symmetry, based on an **esthetic** perception of structures and figures.



On the other hand, **mathematicians** (as they are wont to do) have defined symmetry in a very precise and unambiguous way. Using a branch of mathematics called **Group Theory**, first developed by the young genius **Évariste Galois** (1811-1832), **symmetry** is defined by a set of operations (a group) that leaves an object **unchanged**.

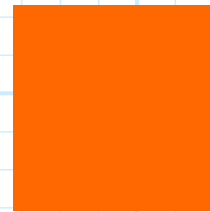
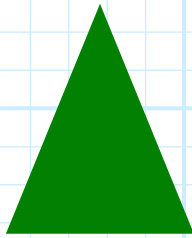
Initially, the symmetric "objects" under consideration by Galois were **polynomial functions**, but group theory can likewise be applied to evaluate the symmetry of **structures**.

For example, consider an ordinary **equilateral triangle**; we find that it is a highly **symmetric** object!

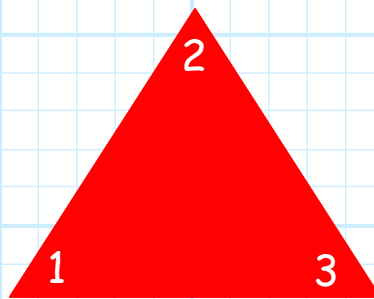


Q: *Obviously this is true. We don't need a mathematician to tell us that!*

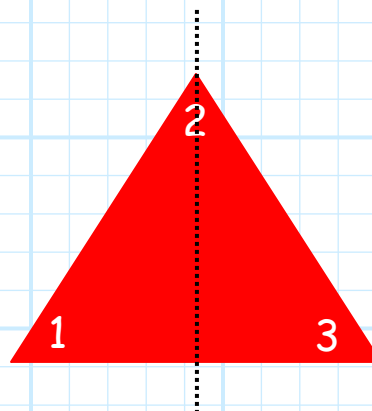
A: Yes, but **how** symmetric is it? How does the symmetry of an equilateral triangle **compare** to that of an isosceles triangle, a rectangle, or a square?



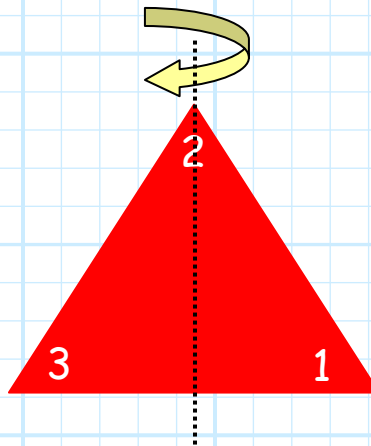
To determine its level of symmetry, let's first label each corner as corner 1, corner 2, and corner 3.



First, we note that the triangle exhibits a plane of **reflection symmetry**:



Thus, if we “reflect” the triangle across this plane we get:



Note that although corners 1 and 3 have changed places, the triangle itself remains **unchanged**—that is, it has the same **shape**, same **size**, and same **orientation** after reflecting across the symmetric plane!

Mathematicians say that these two triangles are **congruent**.

Note that we can write this reflection operation as a **permutation** (an exchange of position) of the corners, defined as:

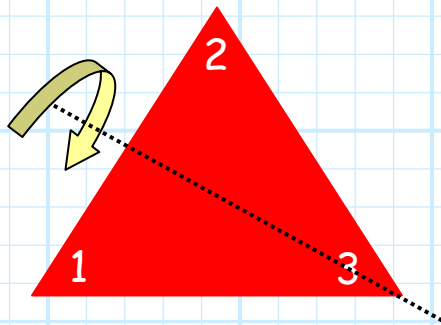
$$1 \rightarrow 3$$

$$2 \rightarrow 2$$

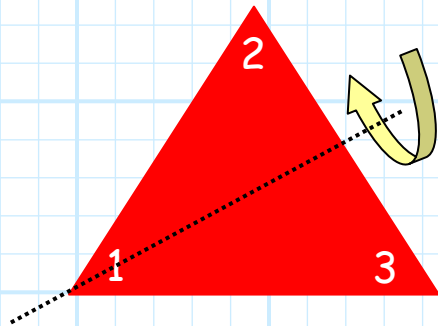
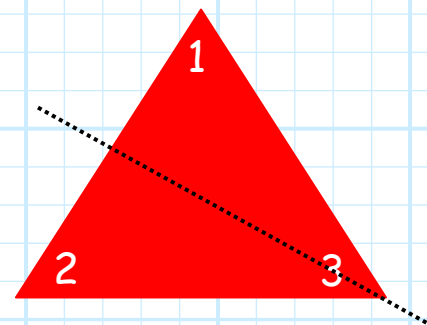
$$3 \rightarrow 1$$

Q: *But wait! Isn't there is more than just one plane of reflection symmetry?*

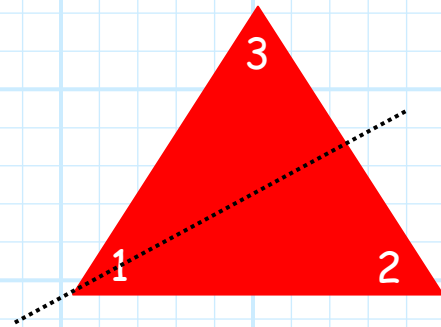
A: Definitely! There are **two more**:



$$\begin{aligned} 1 &\rightarrow 2 \\ 2 &\rightarrow 1 \\ 3 &\rightarrow 3 \end{aligned}$$

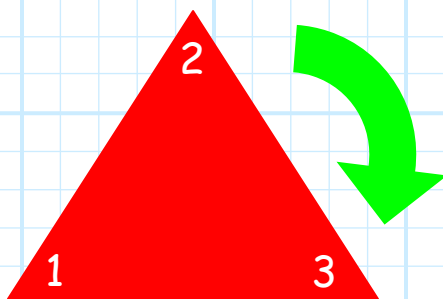


$$\begin{aligned} 1 &\rightarrow 1 \\ 2 &\rightarrow 3 \\ 3 &\rightarrow 2 \end{aligned}$$

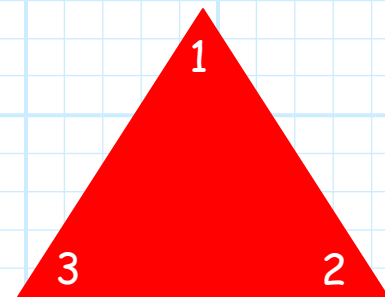


In addition, an equilateral triangle exhibits **rotation symmetry!**

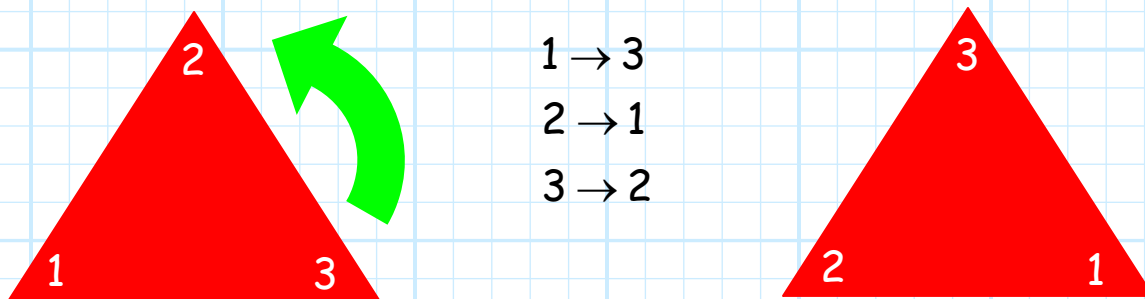
Rotating the triangle 120° clockwise also results in a **congruent** triangle:



$$\begin{aligned} 1 &\rightarrow 2 \\ 2 &\rightarrow 3 \\ 3 &\rightarrow 1 \end{aligned}$$

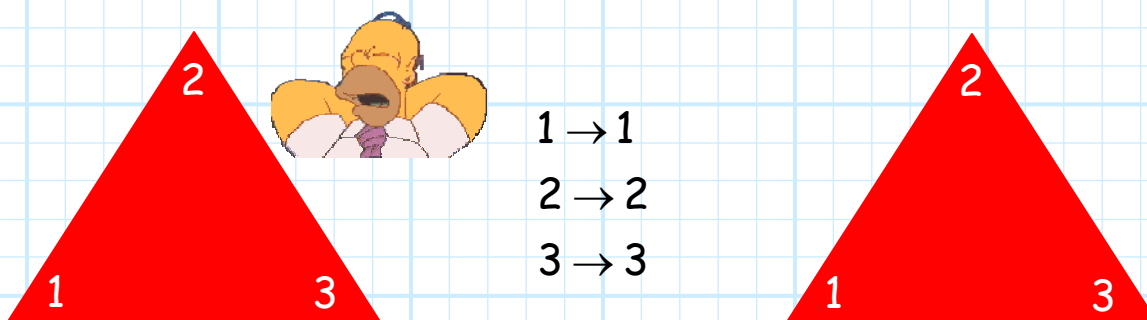


Likewise, rotating the triangle 120° **counter-clockwise** results in a congruent triangle:



$$\begin{aligned} 1 &\rightarrow 3 \\ 2 &\rightarrow 1 \\ 3 &\rightarrow 2 \end{aligned}$$

Additionally, there is **one more** operation that will result in a congruent triangle—do **nothing!**



$$\begin{aligned} 1 &\rightarrow 1 \\ 2 &\rightarrow 2 \\ 3 &\rightarrow 3 \end{aligned}$$

This seemingly **trivial** operation is known as the **identity operation**, and is an element of **every** symmetry group.

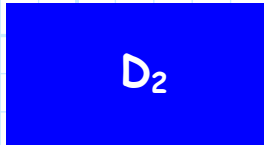
These 6 operations form the **dihedral symmetry group D_3** which has **order six** (i.e., it consists of six operations). An object that remains **congruent** when operated on by any and all of these six operations is said to have **D_3** symmetry.

➔ An equilateral triangle has **D_3** symmetry!

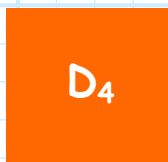
By applying a similar analysis to a isosceles triangle, rectangle, and square, we find that:



An isosceles trapezoid has D_1 symmetry, a dihedral group of order 2.



A rectangle has D_2 symmetry, a dihedral group of order 4.



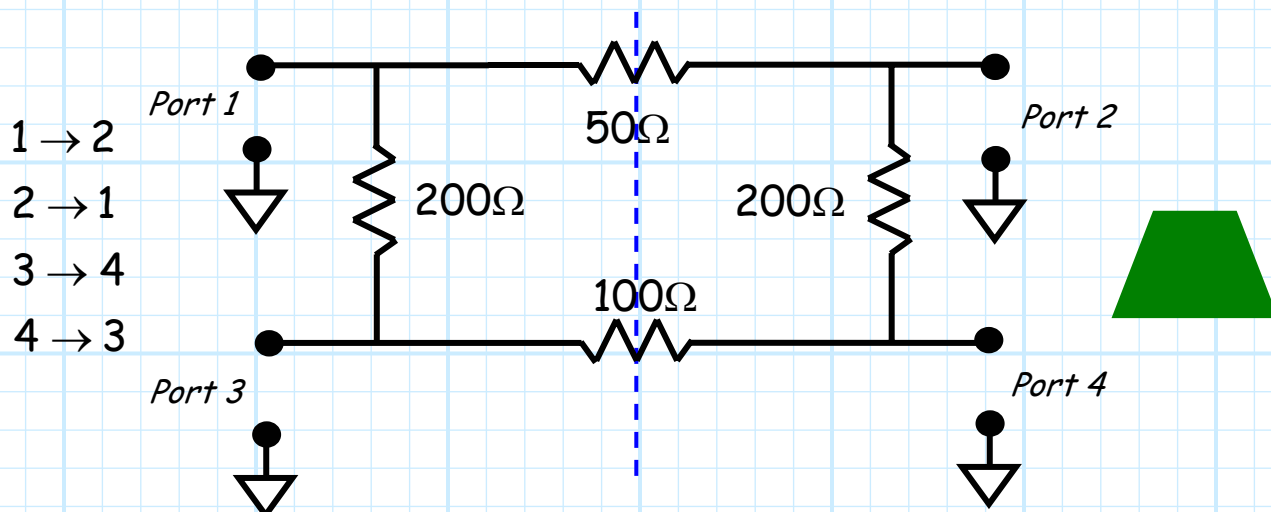
A square has D_4 symmetry, a dihedral group of order 8.

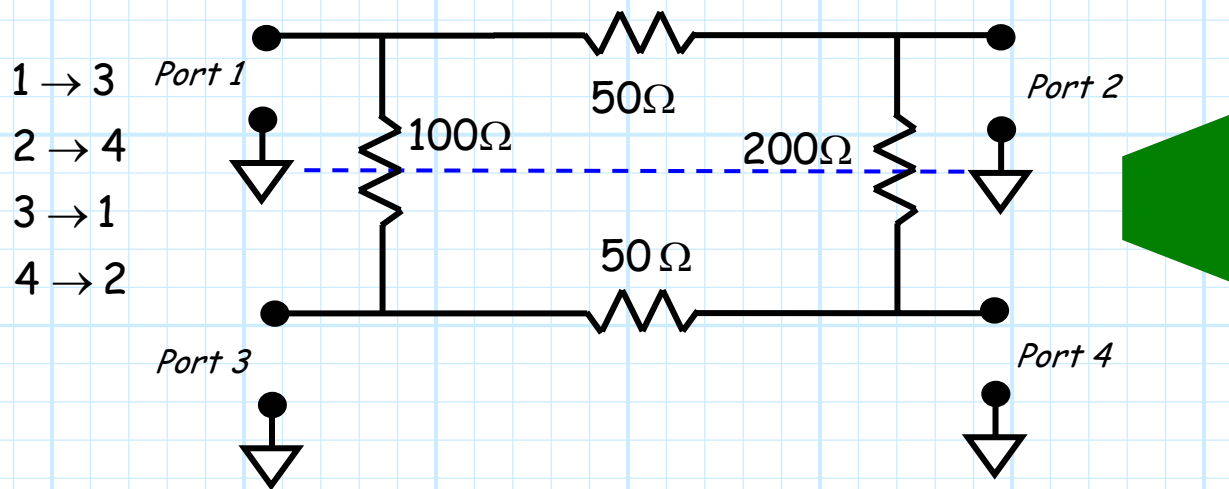
Thus, a square is the **most** symmetric object of the four we have discussed; the isosceles trapezoid is the **least**.

Q: *Well that's all just fascinating—but just what the heck does this have to do with **microwave circuits**!?!*

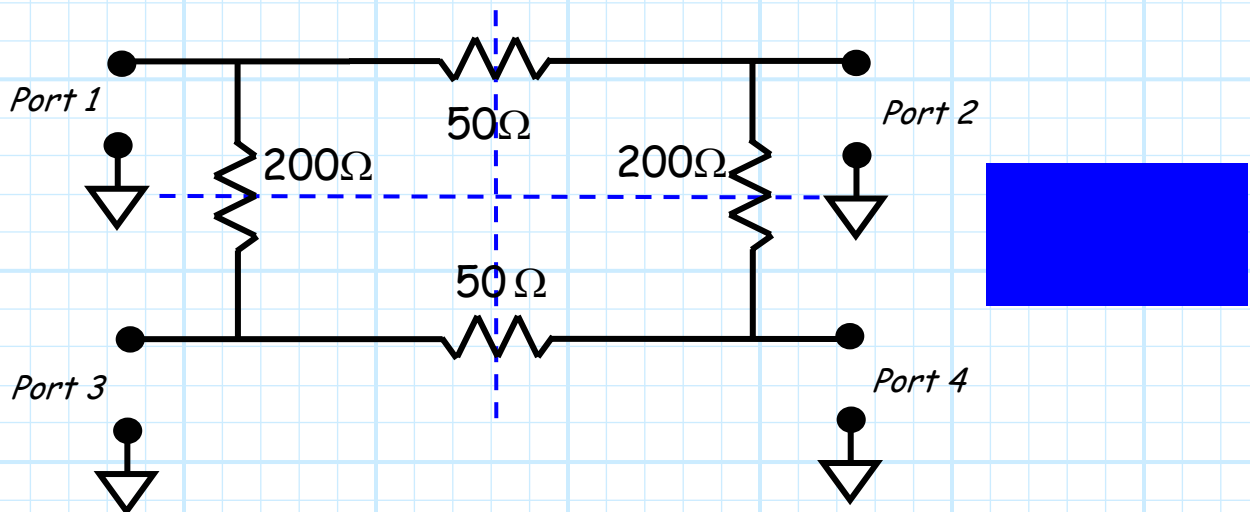
A: Plenty! **Useful circuits** often display high levels of symmetry.

For example consider these D_1 symmetric multi-port circuits:





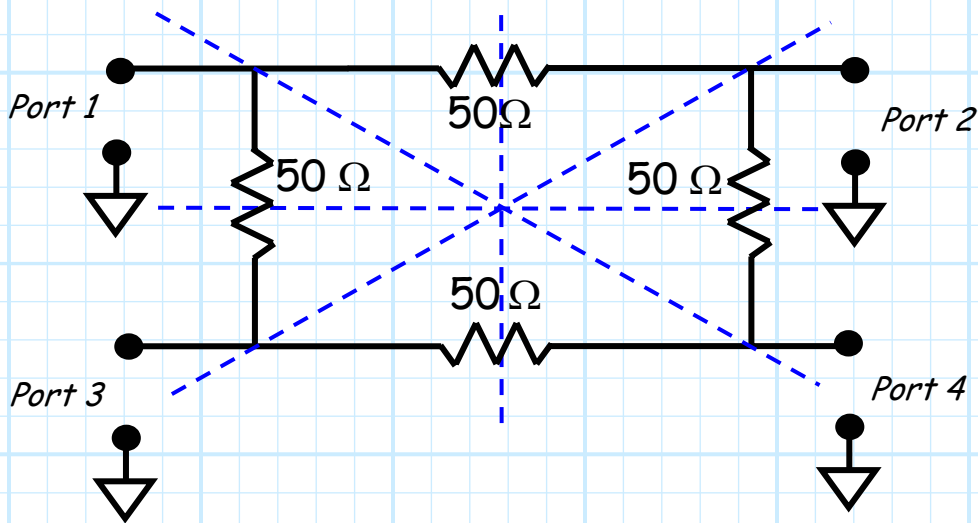
Or this circuit with D_2 symmetry:



which is **congruent** under these permutations:

- | | | |
|-------------------|-------------------|-------------------|
| $1 \rightarrow 3$ | $1 \rightarrow 2$ | $1 \rightarrow 4$ |
| $2 \rightarrow 4$ | $2 \rightarrow 1$ | $2 \rightarrow 3$ |
| $3 \rightarrow 1$ | $3 \rightarrow 4$ | $3 \rightarrow 2$ |
| $4 \rightarrow 2$ | $4 \rightarrow 3$ | $4 \rightarrow 1$ |

Or this circuit with D_4 symmetry:

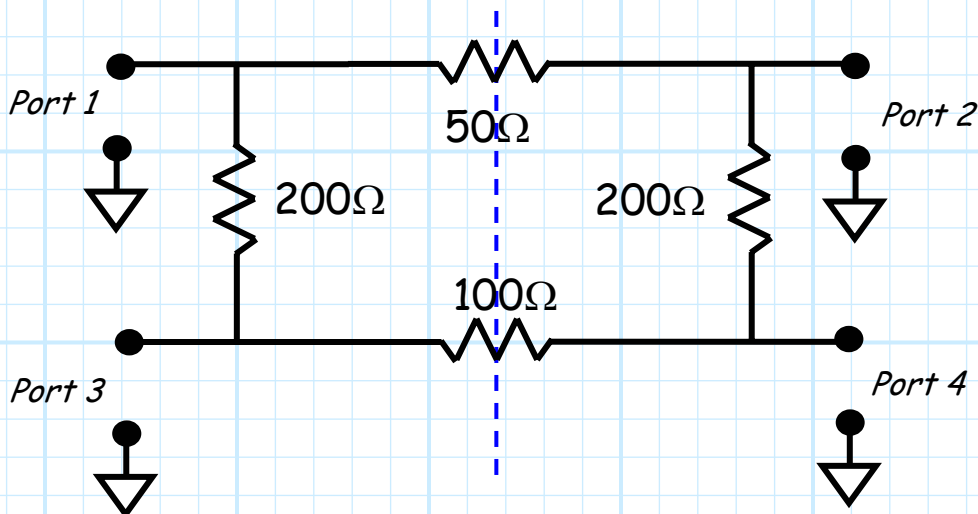


which is congruent under these permutations:

$1 \rightarrow 3$	$1 \rightarrow 2$	$1 \rightarrow 4$	$1 \rightarrow 4$	$1 \rightarrow 1$
$2 \rightarrow 4$	$2 \rightarrow 1$	$2 \rightarrow 3$	$2 \rightarrow 2$	$2 \rightarrow 3$
$3 \rightarrow 1$	$3 \rightarrow 4$	$3 \rightarrow 2$	$3 \rightarrow 3$	$3 \rightarrow 2$
$4 \rightarrow 2$	$4 \rightarrow 3$	$4 \rightarrow 1$	$4 \rightarrow 1$	$4 \rightarrow 4$

The **importance** of this can be seen when considering the scattering matrix, impedance matrix, or admittance matrix of these networks.

For **example**, consider again this **symmetric circuit**:



This four-port network has a single plane of **reflection symmetry** (i.e., D_1 symmetry), and thus is congruent under the permutation:

$$1 \rightarrow 2$$

$$2 \rightarrow 1$$

$$3 \rightarrow 4$$

$$4 \rightarrow 3$$

So, since (for example) $1 \rightarrow 2$, we find that for this circuit:

$$S_{11} = S_{22} \quad Z_{11} = Z_{22} \quad Y_{11} = Y_{22}$$

must be true!

Or, since $1 \rightarrow 2$ and $3 \rightarrow 4$ we find:

$$S_{13} = S_{24} \quad Z_{13} = Z_{24} \quad Y_{13} = Y_{24}$$

$$S_{31} = S_{42} \quad Z_{31} = Z_{42} \quad Y_{31} = Y_{42}$$

Continuing for **all** elements of the permutation, we find that for this symmetric circuit, the scattering matrix **must** have **this** form:

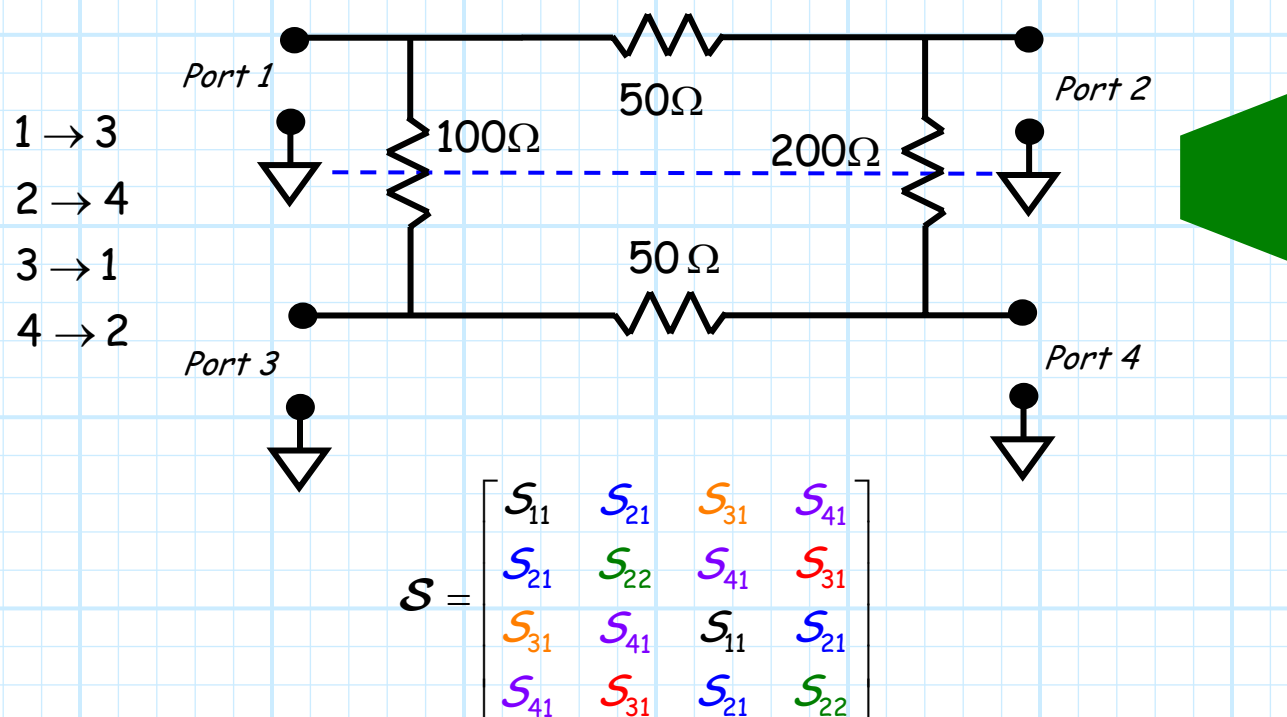
$$S = \begin{bmatrix} S_{11} & S_{21} & S_{13} & S_{14} \\ S_{21} & S_{11} & S_{14} & S_{13} \\ S_{31} & S_{41} & S_{33} & S_{43} \\ S_{41} & S_{31} & S_{43} & S_{33} \end{bmatrix}$$

and the **impedance** and **admittance** matrices would likewise have this same form.

Note there are just **8** independent elements in this matrix. If we also consider **reciprocity** (a constraint independent of symmetry) we find that $S_{31} = S_{13}$ and $S_{41} = S_{14}$, and the matrix reduces further to one with just **6** independent elements:

$$S = \begin{bmatrix} S_{11} & S_{21} & S_{31} & S_{41} \\ S_{21} & S_{11} & S_{41} & S_{31} \\ S_{31} & S_{41} & S_{33} & S_{43} \\ S_{41} & S_{31} & S_{43} & S_{33} \end{bmatrix}$$

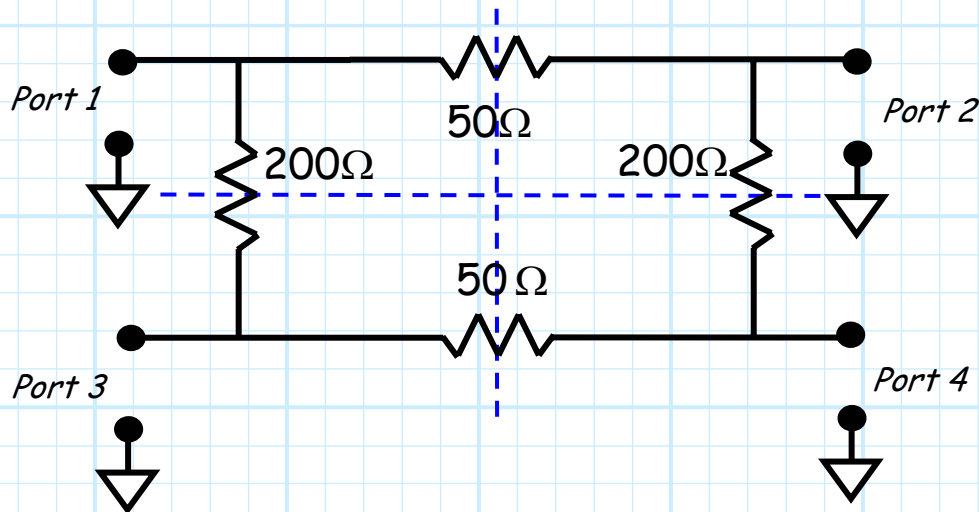
Or, for circuits with **this D_1** symmetry:



Q: *Interesting. But why do we care?*

A: This will greatly **simplify** the analysis of this symmetric circuit, as we need to determine **only** six matrix elements!

For a circuit with D_2 symmetry:

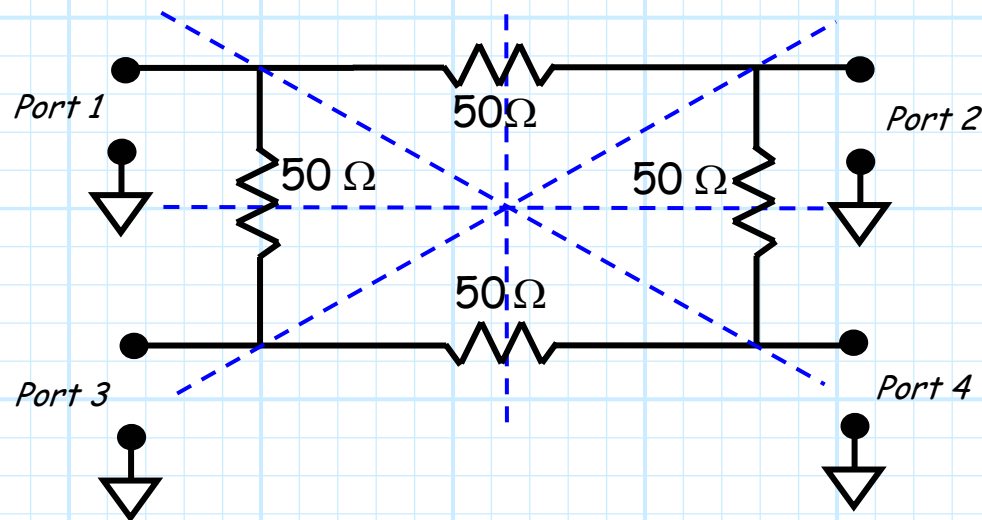


we find that the impedance (or scattering, or admittance) matrix has the form:

$$\mathbf{Z} = \begin{bmatrix} Z_{11} & Z_{21} & Z_{31} & Z_{41} \\ Z_{21} & Z_{11} & Z_{41} & Z_{31} \\ Z_{31} & Z_{41} & Z_{11} & Z_{21} \\ Z_{41} & Z_{31} & Z_{21} & Z_{11} \end{bmatrix}$$

Note here that there are just **four** independent values!

For a circuit with D_4 symmetry:



we find that the admittance (or scattering, or impedance) matrix has the form:

$$\mathbf{y} = \begin{bmatrix} y_{11} & y_{21} & y_{21} & y_{41} \\ y_{21} & y_{11} & y_{41} & y_{21} \\ y_{21} & y_{41} & y_{11} & y_{21} \\ y_{41} & y_{21} & y_{21} & y_{11} \end{bmatrix}$$

Note here that there are just **three** independent values!

One more interesting thing (yet **another** one!); recall that we earlier found that a matched, lossless, reciprocal **4-port** device must have a scattering matrix with one of **two forms**:

$$\mathcal{S} = \begin{bmatrix} 0 & \alpha & j\beta & 0 \\ \alpha & 0 & 0 & j\beta \\ j\beta & 0 & 0 & \alpha \\ 0 & j\beta & \alpha & 0 \end{bmatrix}$$

The "symmetric" solution

$$\mathcal{S} = \begin{bmatrix} 0 & \alpha & \beta & 0 \\ \alpha & 0 & 0 & -\beta \\ \beta & 0 & 0 & \alpha \\ 0 & -\beta & \alpha & 0 \end{bmatrix}$$

The "anti-symmetric" solution

Compare these to the matrix forms above. The "symmetric solution" has the **same form** as the scattering matrix of a circuit with D_2 symmetry!

$$\mathcal{S} = \begin{bmatrix} 0 & \alpha & j\beta & 0 \\ \alpha & 0 & 0 & j\beta \\ j\beta & 0 & 0 & \alpha \\ 0 & j\beta & \alpha & 0 \end{bmatrix}$$

Q: Does this mean that a matched, lossless, reciprocal four-port device with the "symmetric" scattering matrix **must** exhibit D_2 symmetry?

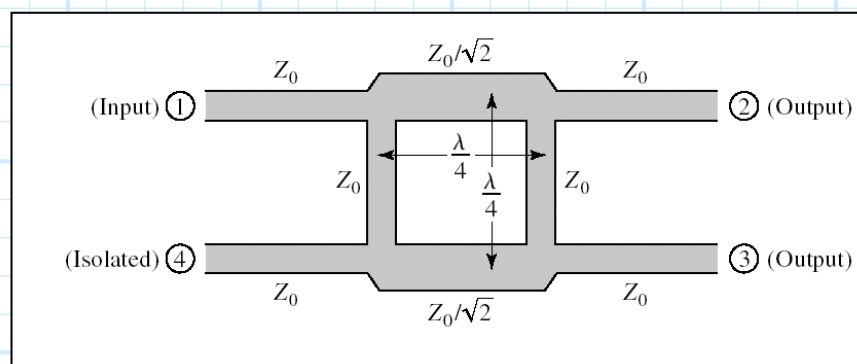
A: That's **exactly** what it means!

Not only can we determine from the **form** of the scattering matrix **whether** a particular design is possible (e.g., a matched, lossless, reciprocal 3-port device is impossible), we can also determine the **general structure** of a possible solutions (e.g. the circuit must have D_2 symmetry).

Likewise, the "anti-symmetric" matched, lossless, reciprocal four-port network **must** exhibit D_1 symmetry!

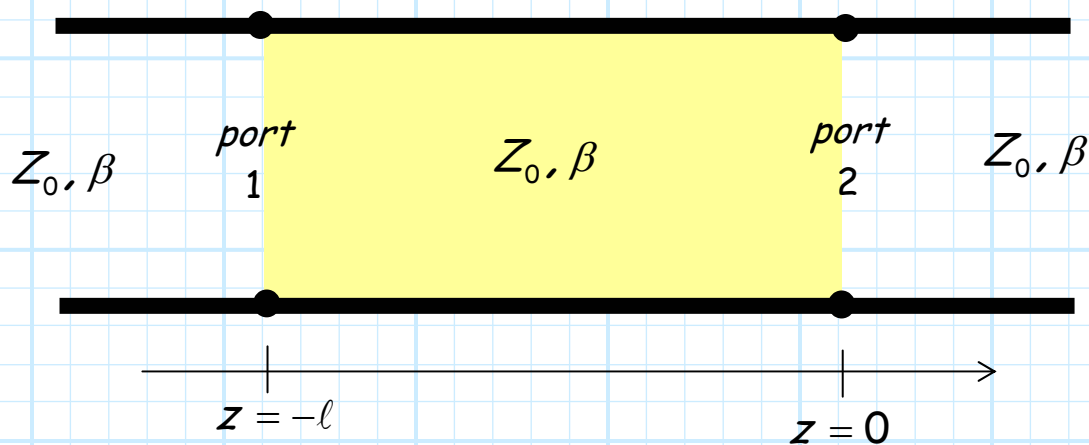
$$\mathcal{S} = \begin{bmatrix} 0 & \alpha & \beta & 0 \\ \alpha & 0 & 0 & -\beta \\ \beta & 0 & 0 & \alpha \\ 0 & -\beta & \alpha & 0 \end{bmatrix}$$

We'll see just what these symmetric, matched, lossless, reciprocal four-port circuits actually are later in the course!



Example: Using Symmetry to Determine a Scattering Matrix

Say we wish to determine the scattering matrix of the simple two-port device shown below:



We note that that attaching transmission lines of characteristic impedance Z_0 to each port of our "circuit" forms a **continuous** transmission line of characteristic impedance Z_0 .

Thus, the voltage **all along** this transmission line thus has the form:

$$V(z) = V_0^+ e^{-j\beta z} + V_0^- e^{+j\beta z}$$

We begin by defining the location of port 1 as $z_{1p} = -\ell$, and the port location of port 2 as $z_{2p} = 0$:

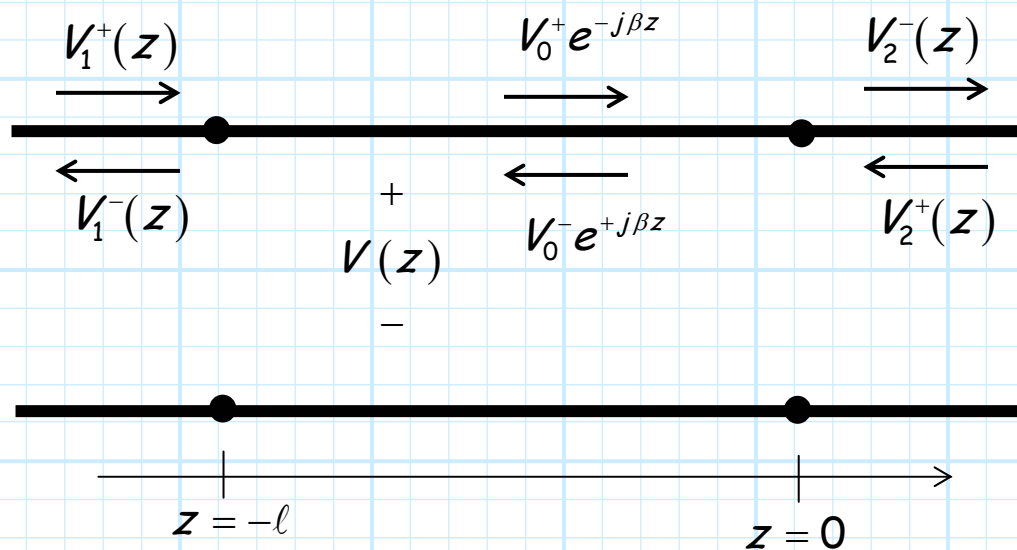
We can thus conclude:

$$V_1^+(z) = V_0^+ e^{-j\beta z} \quad (z \leq -\ell)$$

$$V_1^-(z) = V_0^- e^{+j\beta z} \quad (z \leq -\ell)$$

$$V_2^+(z) = V_0^- e^{+j\beta z} \quad (z \geq 0)$$

$$V_2^-(z) = V_0^+ e^{-j\beta z} \quad (z \geq 0)$$



Say the transmission line on port 2 is terminated in a **matched load**. We know that the $-z$ wave must be **zero** ($V_0^- = 0$), and so the voltage along the transmission line becomes simply the $+z$ wave voltage:

$$V(z) = V_0^+ e^{-j\beta z}$$

and so:

$$V_1^+(z) = V_0^+ e^{-j\beta z} \quad V_1^-(z) = 0 \quad (z \leq -\ell)$$

$$V_2^+(z) = 0 \quad V_2^-(z) = V_0^+ e^{-j\beta z} \quad (z \geq 0)$$

Now, **because** port 2 is terminated in a matched load, we can determine the scattering parameters S_{11} and S_{21} :

$$S_{11} = \left. \frac{V_1^-(z = z_{1\rho})}{V_1^+(z = z_{1\rho})} \right|_{V_2^+=0} = \left. \frac{V^-(z = -\ell)}{V^+(z = -\ell)} \right|_{V_2^+=0} = \frac{0}{V_0^+ e^{-j\beta(-\ell)}} = 0$$

$$S_{21} = \left. \frac{V_2^-(z = z_{2\rho})}{V_1^+(z = z_{1\rho})} \right|_{V_2^+=0} = \left. \frac{V_2^-(z = 0)}{V_1^+(z = -\ell)} \right|_{V_2^+=0} = \frac{V_0^+ e^{-j\beta(0)}}{V_0^+ e^{-j\beta(-\ell)}} = \frac{1}{e^{+j\beta\ell}} = e^{-j\beta\ell}$$

From the **symmetry** of the structure, we can conclude:

$$S_{22} = S_{11} = 0$$

And from both reciprocity **and** symmetry:

$$S_{12} = S_{21} = e^{-j\beta\ell}$$

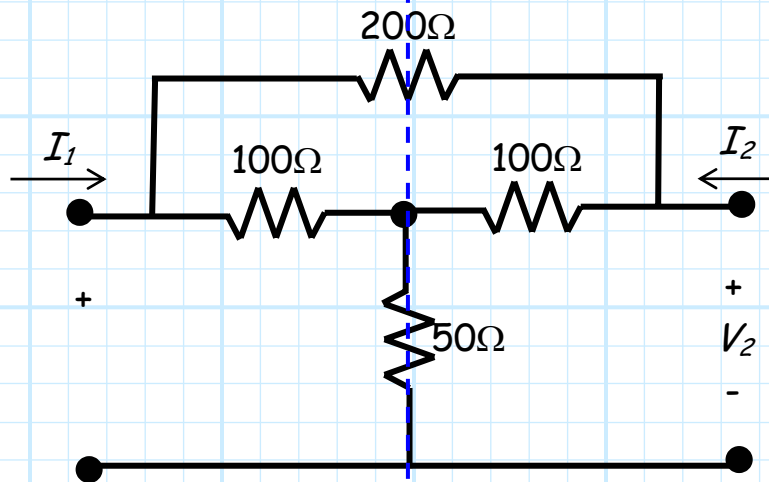
Thus:

$$\underline{\underline{S = \begin{bmatrix} 0 & e^{-j\beta\ell} \\ e^{-j\beta\ell} & 0 \end{bmatrix}}}$$



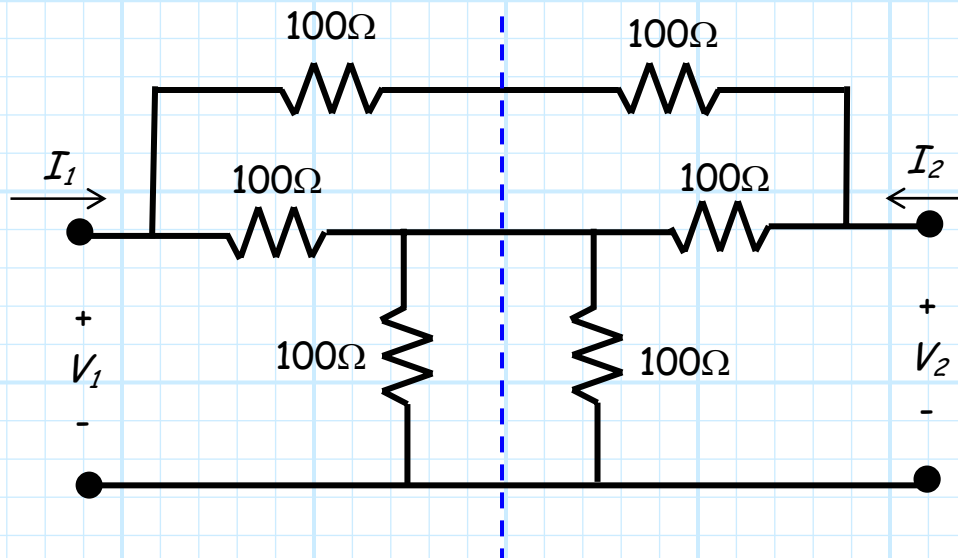
Symmetric Circuit Analysis

Consider the following D_1 symmetric two-port device:



Q: *Yikes! The plane of reflection symmetry slices through two resistors. What can we do about that?*

A: Resistors are easily split into two equal pieces: the 200Ω resistor into two 100Ω resistors in **series**, and the 50Ω resistor as two 100Ω resistors in **parallel**.



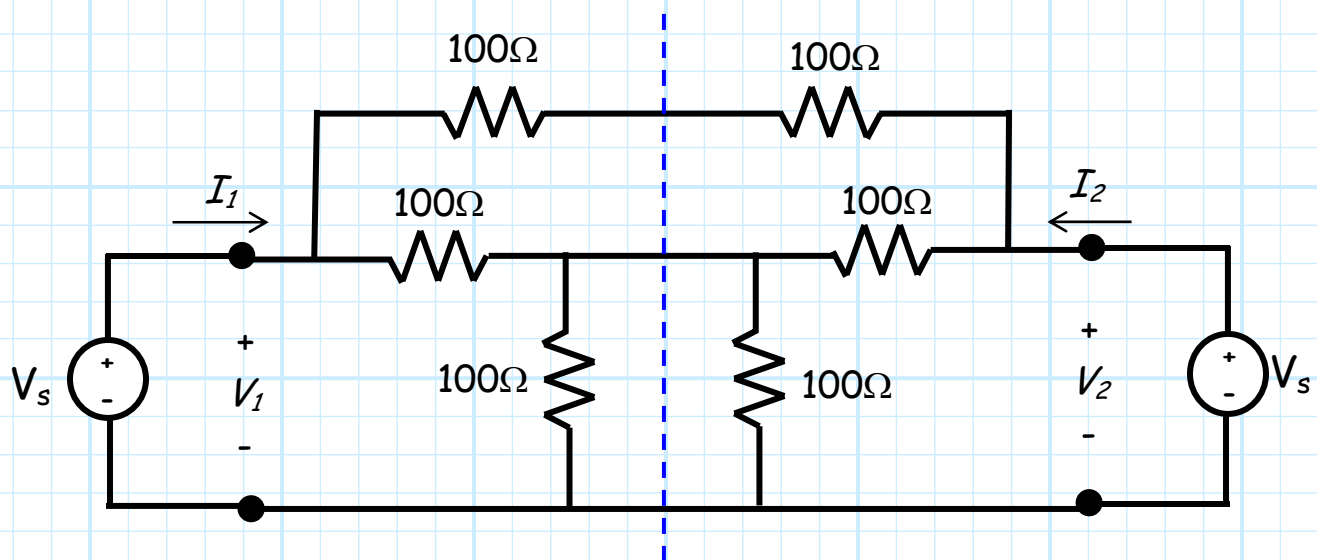
Recall that the **symmetry** of this 2-port device leads to **simplified** network matrices:

$$\mathbf{S} = \begin{bmatrix} S_{11} & S_{21} \\ S_{21} & S_{11} \end{bmatrix} \quad \mathbf{Z} = \begin{bmatrix} Z_{11} & Z_{21} \\ Z_{21} & Z_{11} \end{bmatrix} \quad \mathbf{Y} = \begin{bmatrix} Y_{11} & Y_{21} \\ Y_{21} & Y_{11} \end{bmatrix}$$

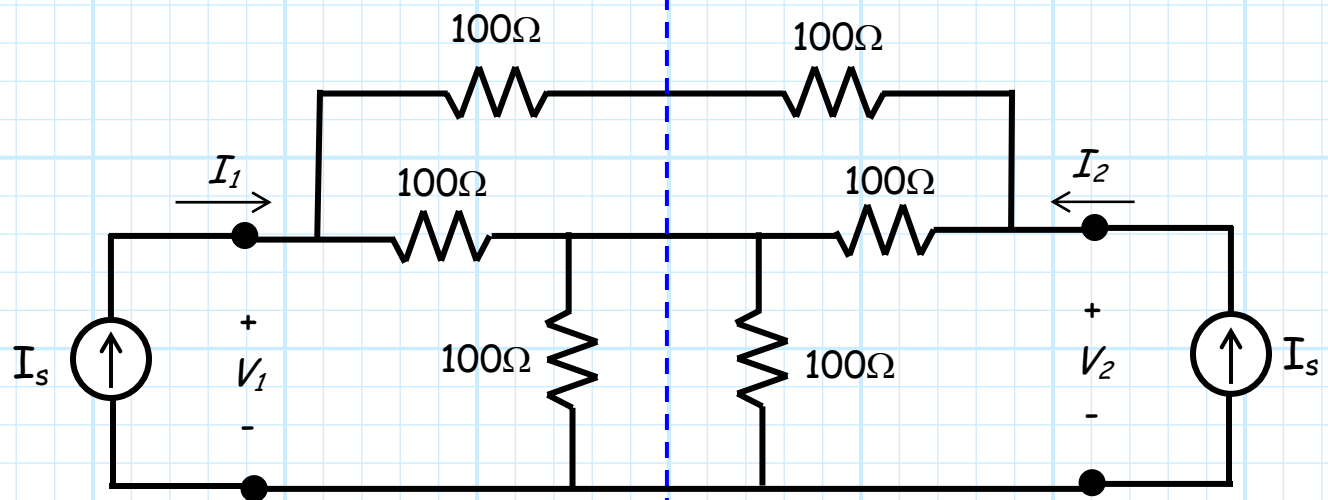
Q: *Yes, but can circuit symmetry likewise simplify the procedure of **determining** these elements? In other words, can symmetry be used to **simplify circuit analysis**?*

A: You bet!

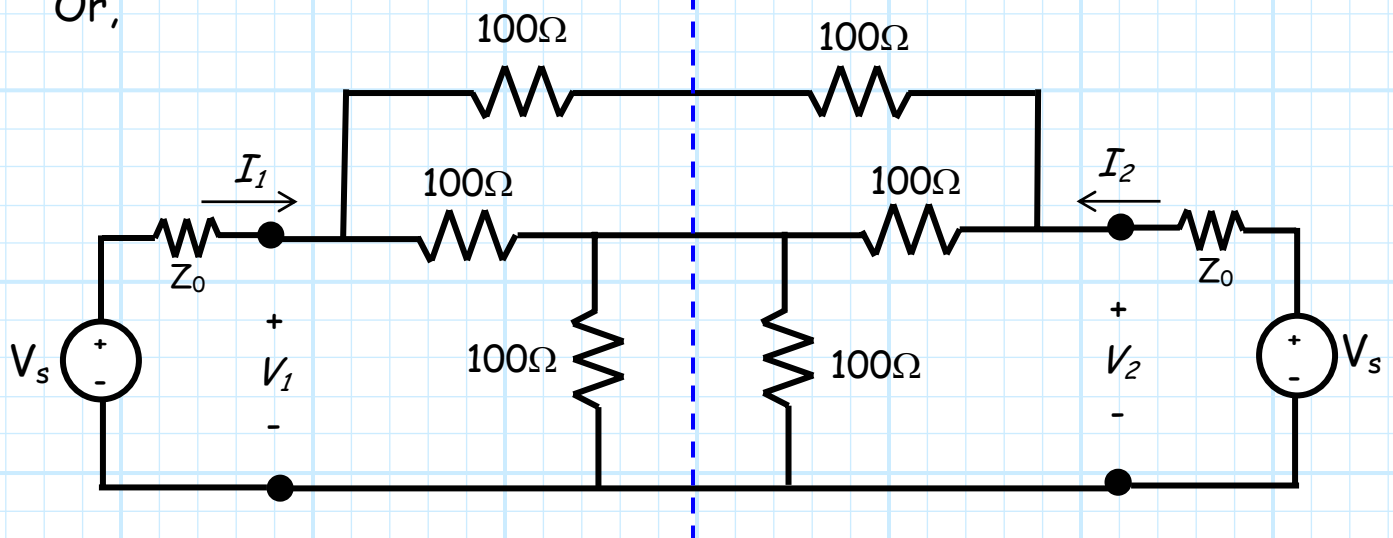
First, consider the case where we **attach sources** to circuit in a way that **preserves** the circuit **symmetry**:



Or,

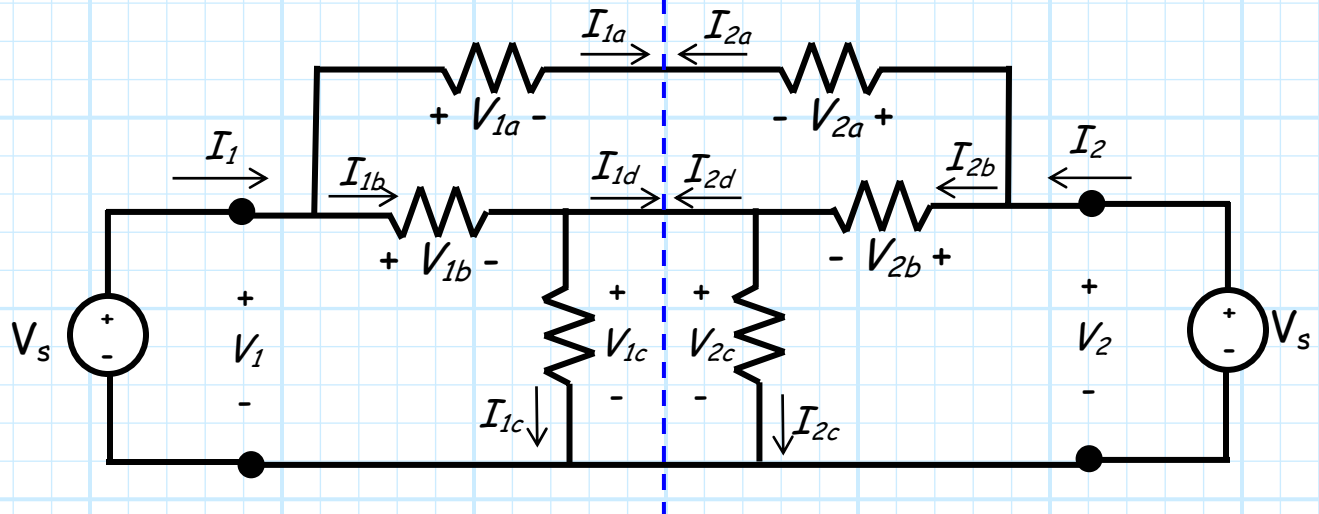


Or,



But remember! In order for **symmetry to be preserved**, the source values on both sides (i.e., I_s, V_s, Z_0) must be **identical**!

Now, consider the **voltages** and **currents** within this circuit under this symmetric configuration:



Since this circuit possesses **bilateral** (reflection) symmetry ($1 \rightarrow 2, 2 \rightarrow 1$), symmetric currents and voltages must be equal:

$$V_1 = V_2$$

$$V_{1a} = V_{2a}$$

$$V_{1b} = V_{2b}$$

$$V_{1c} = V_{2c}$$

$$I_1 = I_2$$

$$I_{1a} = I_{2a}$$

$$I_{1b} = I_{2b}$$

$$I_{1c} = I_{2c}$$

$$I_{1d} = I_{2d}$$

Q: Wait! This can't possibly be correct! Look at currents I_{1a} and I_{2a} , as well as currents I_{1d} and I_{2d} . From KCL, this must be true:

$$I_{1a} = -I_{2a}$$

$$I_{1d} = -I_{2d}$$

Yet you say that **this** must be true:

$$I_{1a} = I_{2a}$$

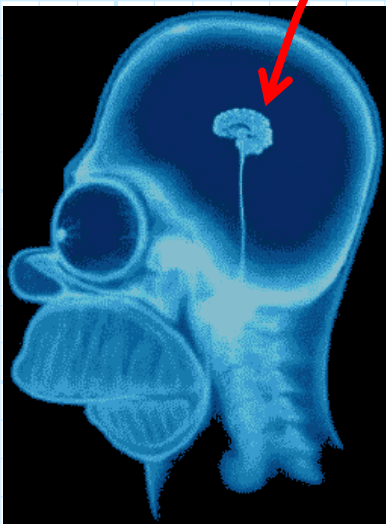
$$I_{1d} = I_{2d}$$

There is an obvious contradiction here! There is no way that both sets of equations can simultaneously be correct, is there?

A: Actually there is! There is **one** solution that will satisfy **both** sets of equations:

$$I_{1a} = I_{2a} = 0 \qquad I_{1d} = I_{2d} = 0$$

The currents are **zero!**

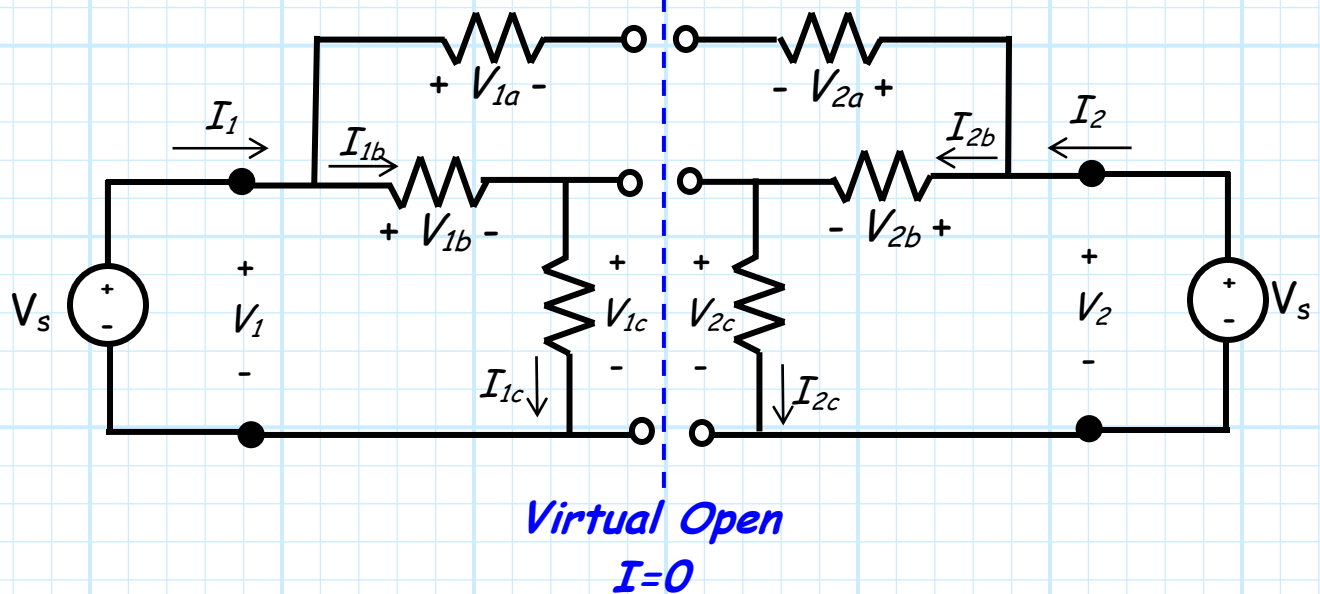


If you **think** about it, this makes **perfect sense!** The result says that **no current** will flow from one side of the symmetric circuit into the other.

If current **did** flow across the symmetry plane, then the circuit symmetry would be **destroyed**—one side would effectively become the “**source side**”, and the other the “**load side**” (i.e., the source side delivers current to the load side).

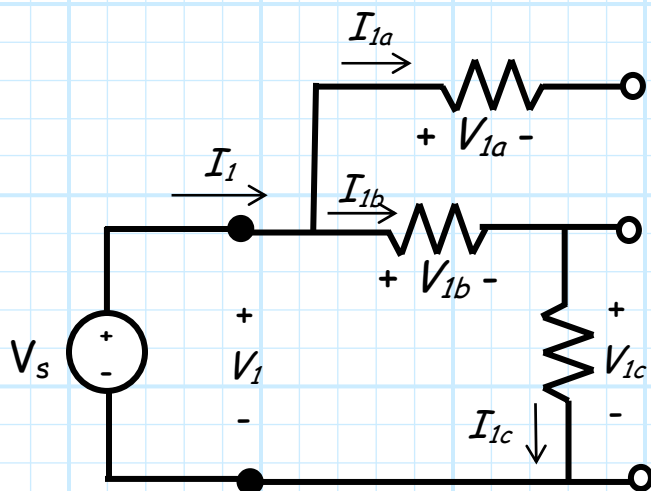
Thus, **no current** will flow **across** the reflection symmetry plane of a **symmetric circuit**—the symmetry plane thus acts as a **open circuit!**

The plane of symmetry thus becomes a **virtual open!**



Q: So what?

A: So what! This means that our circuit can be **split apart** into **two separate but identical** circuits. Solve **one** half-circuit, and you have **solved** the other!



$$V_1 = V_2 = V_s$$

$$V_{1a} = V_{2a} = 0$$

$$V_{1b} = V_{2b} = V_s/2$$

$$V_{1c} = V_{2c} = V_s/2$$

$$I_1 = I_2 = V_s/200$$

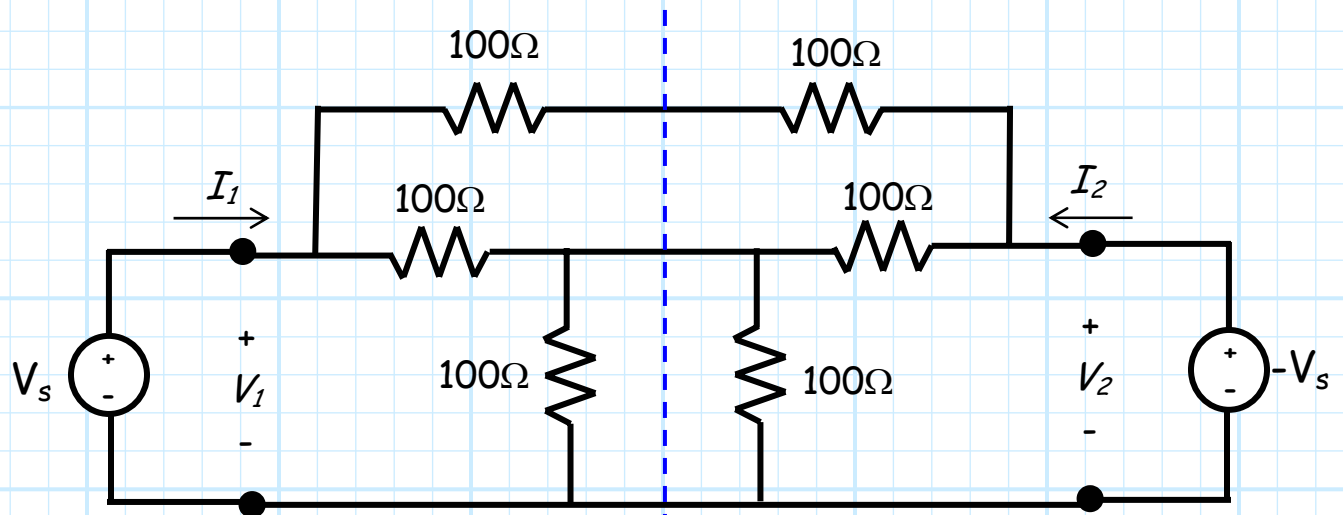
$$I_{1a} = I_{2a} = 0$$

$$I_{1b} = I_{2b} = V_s/200$$

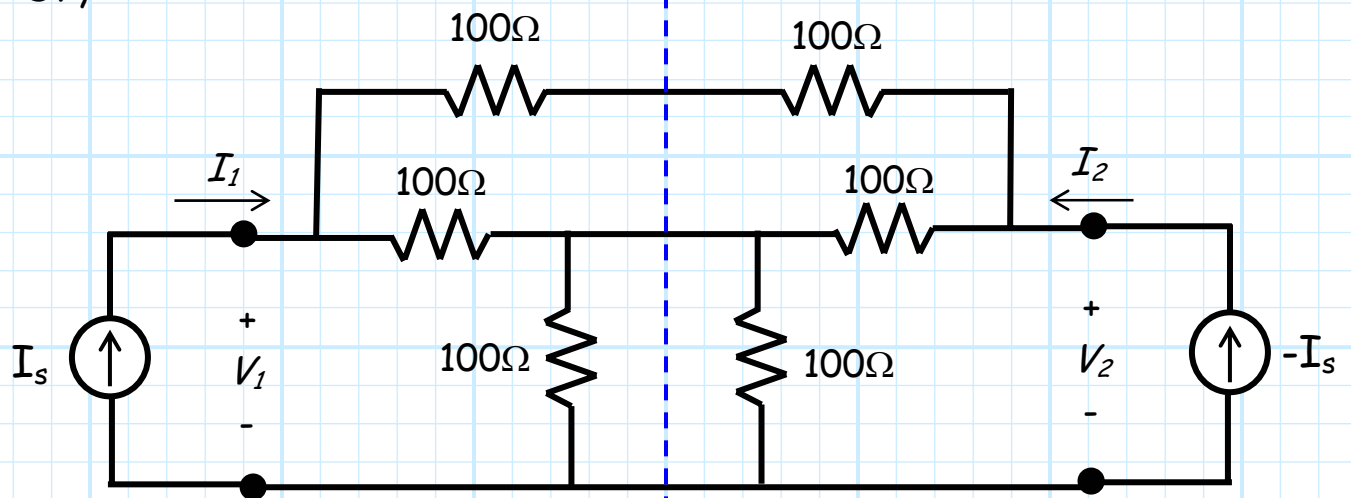
$$I_{1c} = I_{2c} = V_s/200$$

$$I_{1d} = I_{2d} = 0$$

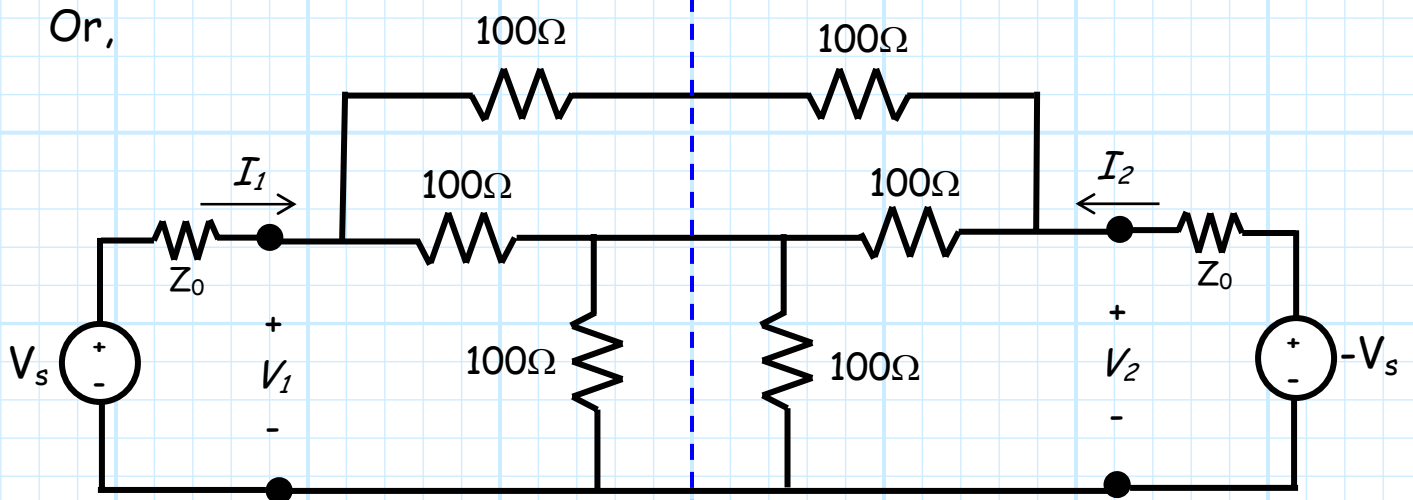
Now, consider **another** type of symmetry, where the sources are **equal but opposite** (i.e., **180 degrees** out of phase).



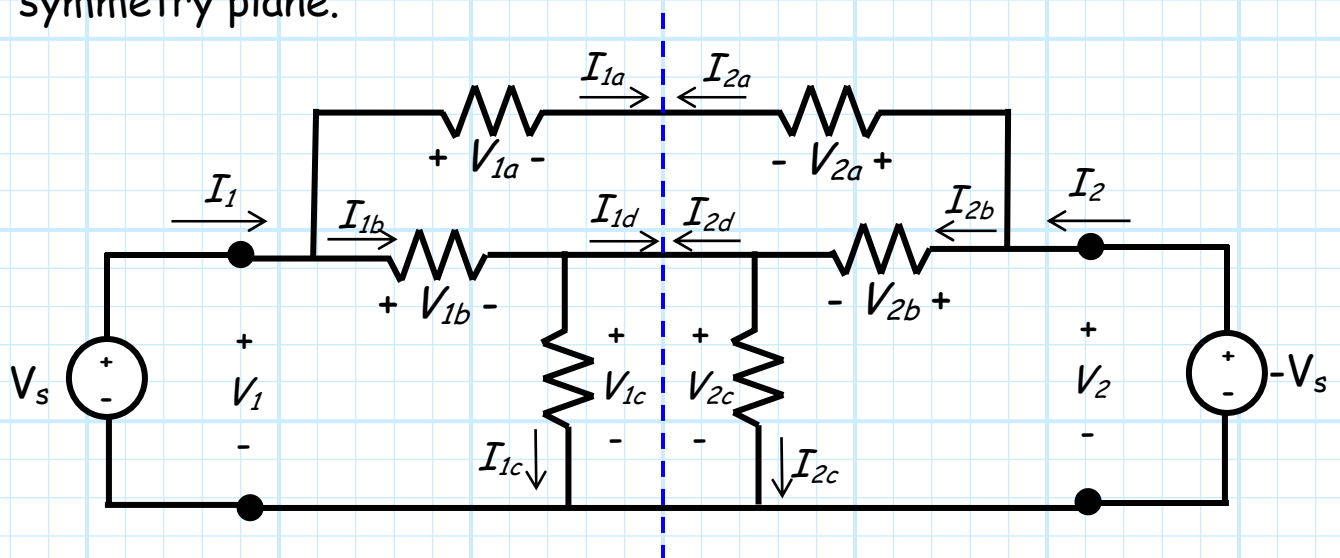
Or,



Or,



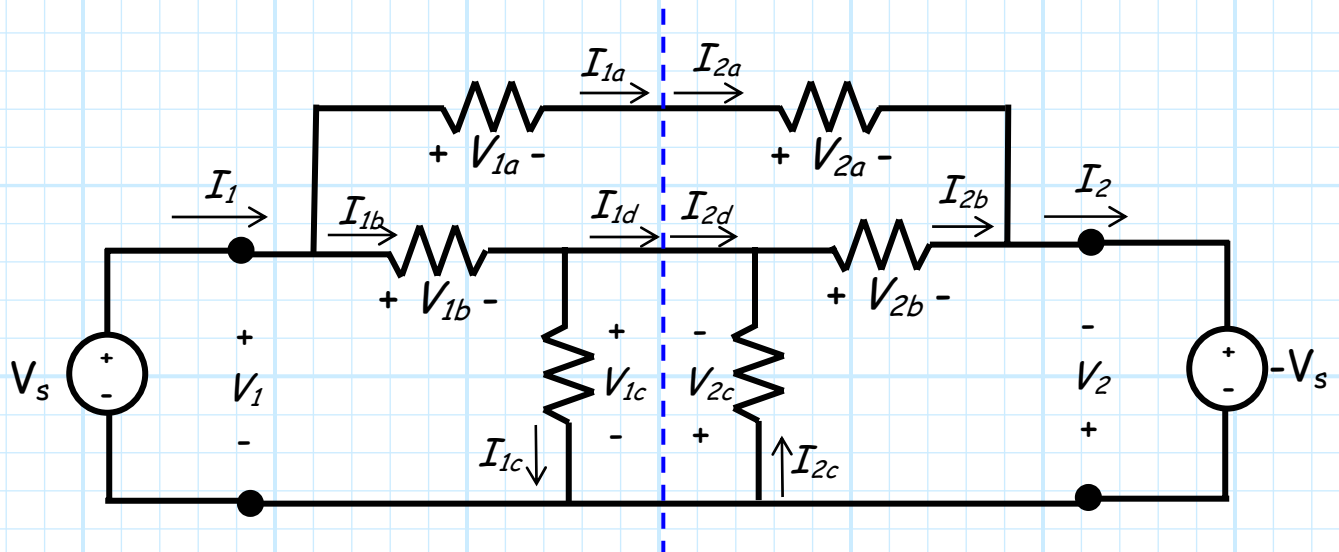
This situation still preserves the **symmetry** of the circuit—**somewhat**. The **voltages** and **currents** in the circuit will now possess **odd symmetry**—they will be **equal but opposite** (180 degrees out of phase) at symmetric points across the symmetry plane.



$$\begin{aligned}
 V_1 &= -V_2 \\
 V_{1a} &= -V_{2a} \\
 V_{1b} &= -V_{2b} \\
 V_{1c} &= -V_{2c}
 \end{aligned}$$

$$\begin{aligned}
 I_1 &= -I_2 \\
 I_{1a} &= -I_{2a} \\
 I_{1b} &= -I_{2b} \\
 I_{1c} &= -I_{2c} \\
 I_{1d} &= -I_{2d}
 \end{aligned}$$

Perhaps it would be easier to **redefine** the circuit variables as:



$$V_1 = V_2$$

$$V_{1a} = V_{2a}$$

$$V_{1b} = V_{2b}$$

$$V_{1c} = V_{2c}$$

$$I_1 = I_2$$

$$I_{1a} = I_{2a}$$

$$I_{1b} = I_{2b}$$

$$I_{1c} = I_{2c}$$

$$I_{1d} = I_{2d}$$

Q: But wait! *Again* I see a problem. By KVL it is evident that:

$$V_{1c} = -V_{2c}$$

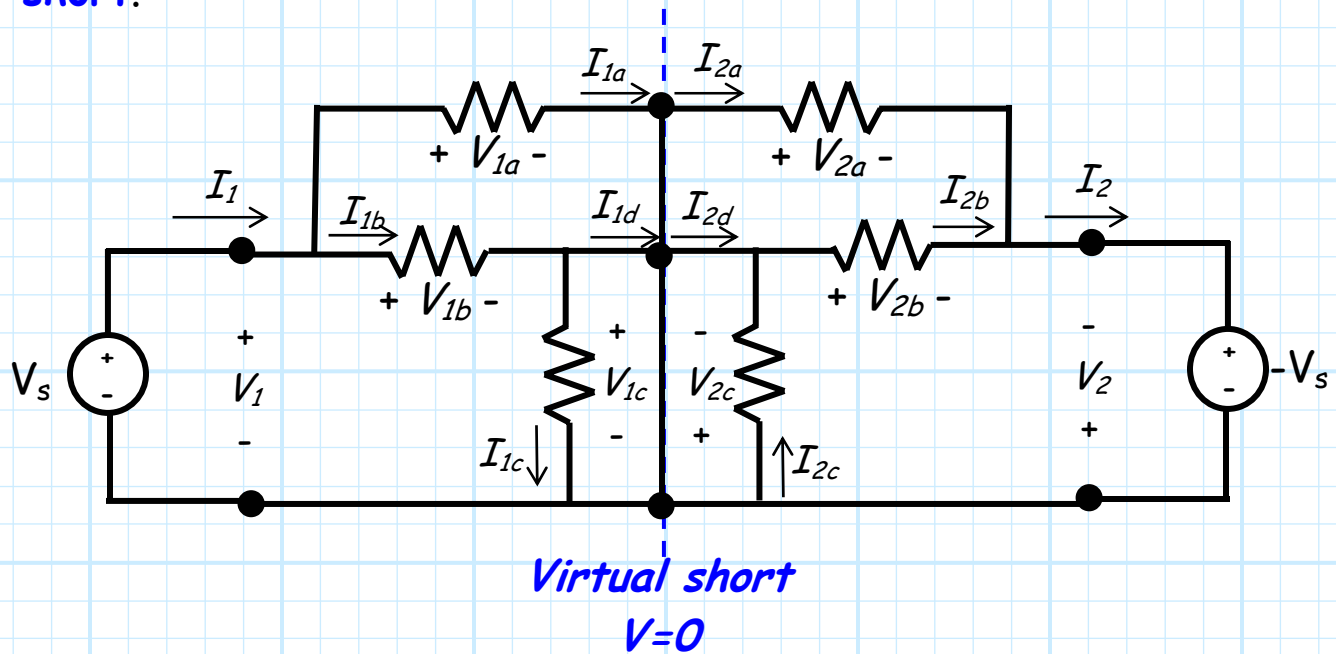
Yet you say that $V_{1c} = V_{2c}$ must be true!

A: Again, the solution to **both** equations is **zero!**

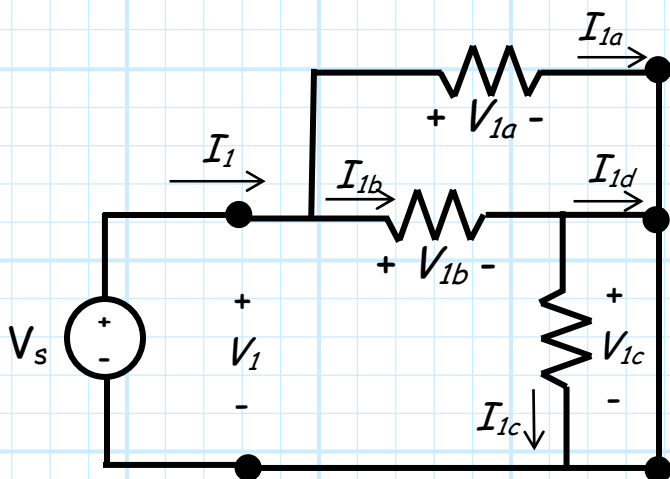
$$V_{1c} = V_{2c} = 0$$

For the case of **odd symmetry**, the symmetric plane must be a plane of **constant potential** (i.e., constant voltage)—just like a **short circuit!**

Thus, for odd symmetry, the symmetric plane forms a **virtual short**.



This **greatly** simplifies things, as we can again **break** the circuit into **two** independent and (effectively) identical circuits!



$$\begin{aligned} V_1 &= V_s \\ V_{1a} &= V_s \\ V_{1b} &= V_s \\ V_{1c} &= 0 \end{aligned}$$

$$\begin{aligned} I_1 &= V_s/50 \\ I_{1a} &= V_s/100 \\ I_{1b} &= V_s/100 \\ I_{1c} &= 0 \\ I_{1d} &= V_s/100 \end{aligned}$$

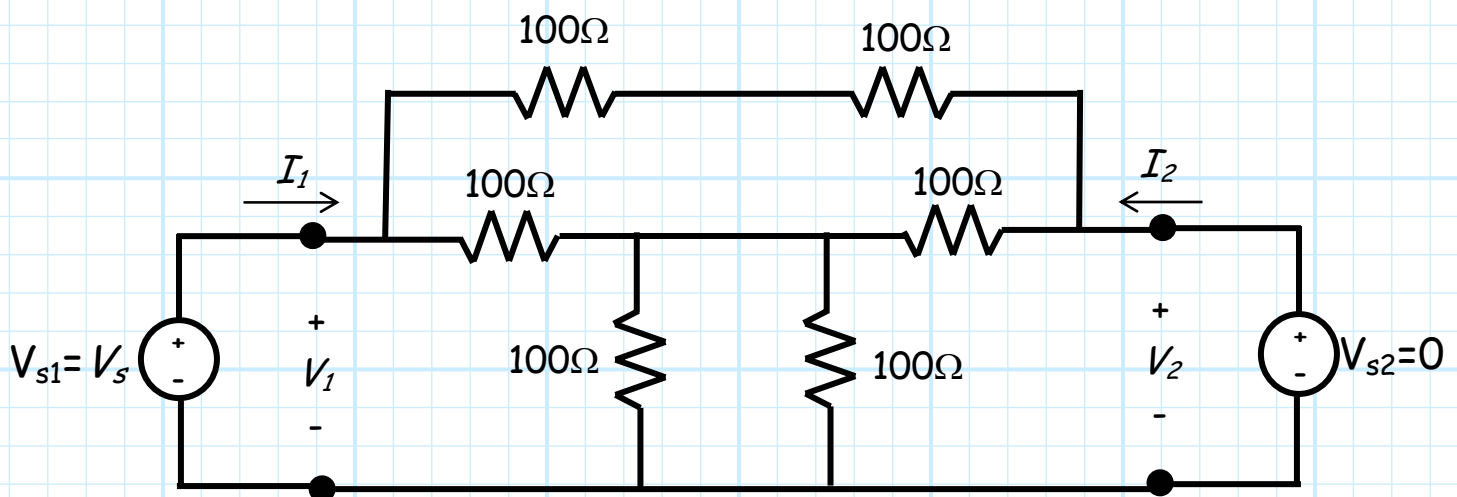
Odd/Even Mode Analysis

Q: *Although symmetric circuits appear to be plentiful in microwave engineering, it seems unlikely that we would often encounter symmetric sources. Do virtual shorts and opens typically ever occur?*

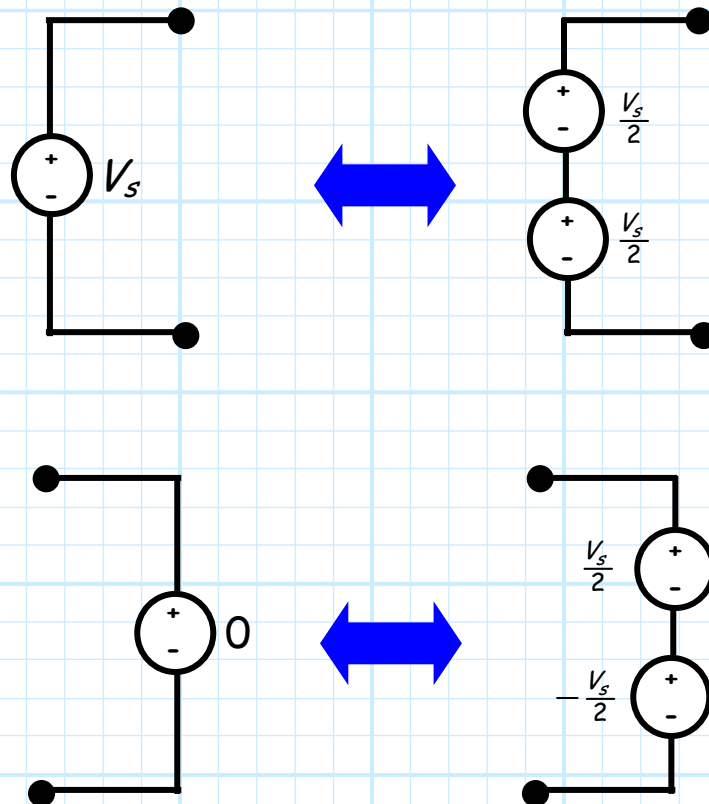
A: One word—**superposition!**

If the elements of our circuit are **independent** and **linear**, we can apply superposition to analyze **symmetric circuits** when **non-symmetric** sources are attached.

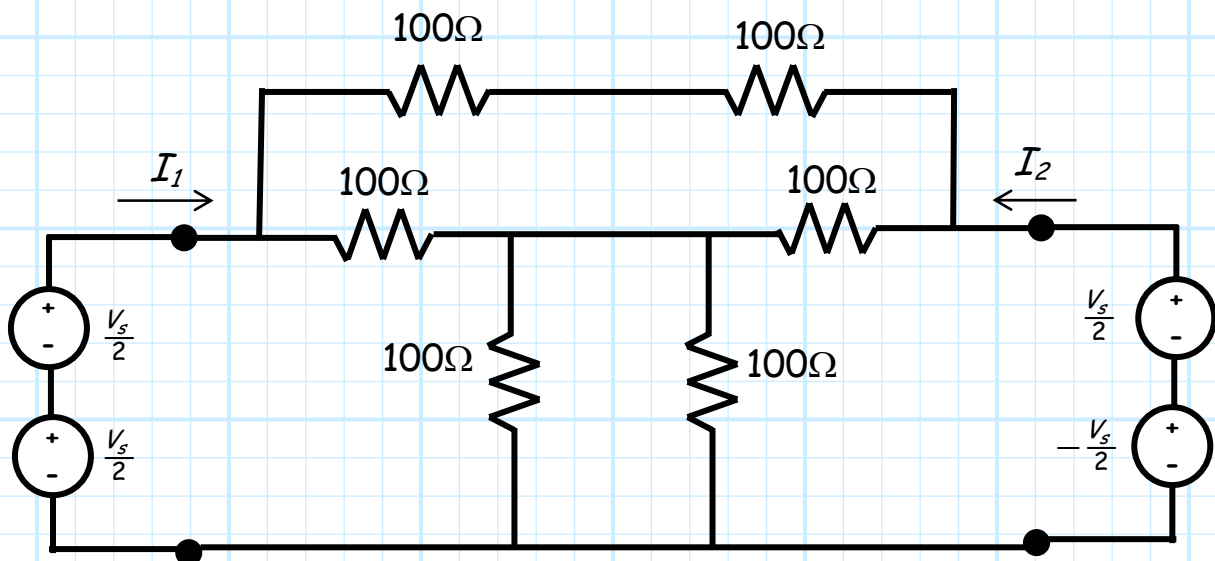
For example, say we wish to determine the **admittance matrix** of this circuit. We would place a **voltage source** at **port 1**, and a **short circuit** at **port 2**—a set of **asymmetric** sources if there ever was one!



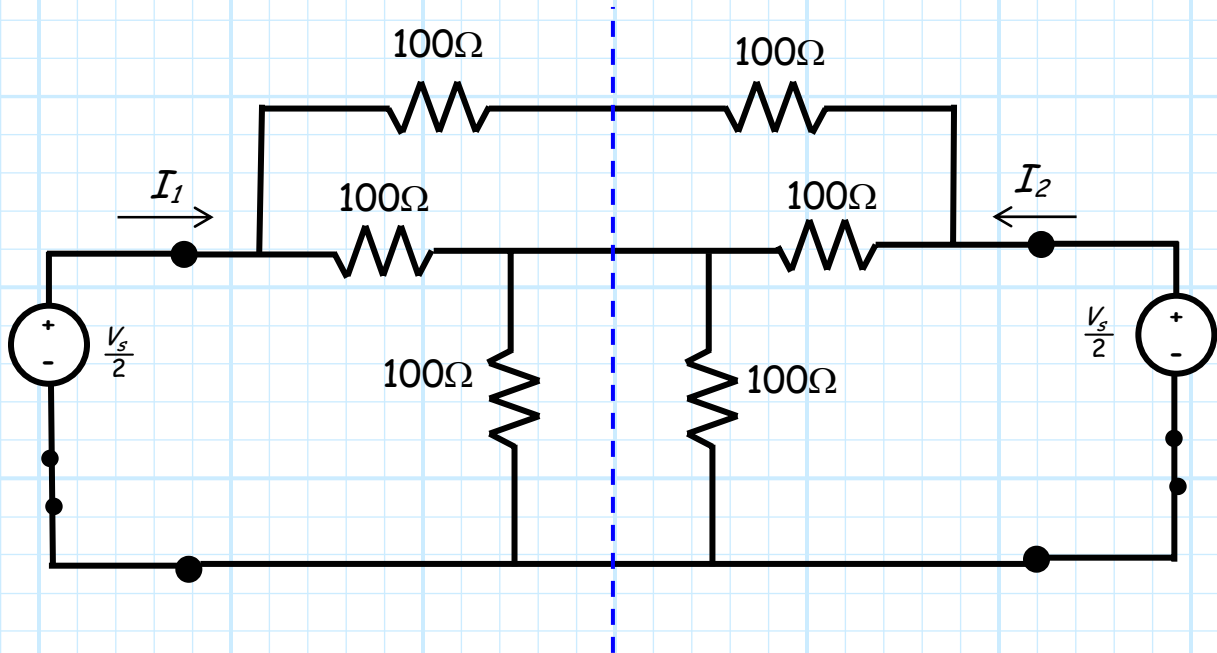
Here's the really **neat** part. We find that the source on port 1 can be model as **two equal** voltage sources in series, whereas the source at port 2 can be modeled as **two equal but opposite** sources in series.



Therefore an **equivalent** circuit is:



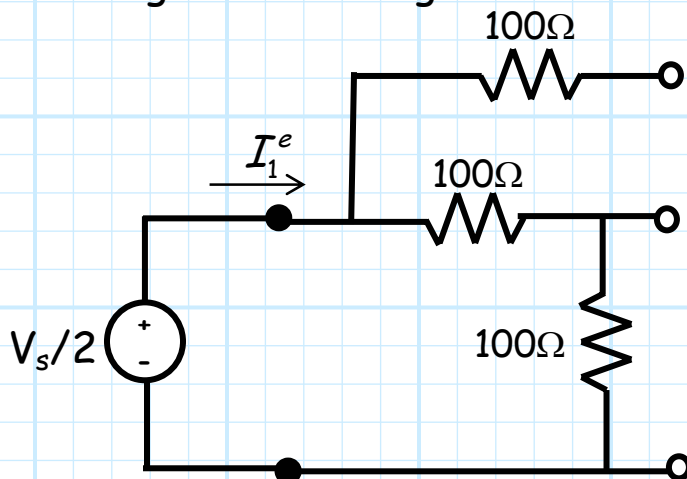
Now, the **above** circuit (due to the sources) is obviously **asymmetric**—no virtual ground, nor virtual short is present. But, let's say we **turn off** (i.e., set to $V=0$) the **bottom** source on **each side** of the circuit:



Our **symmetry** has been **restored**! The symmetry plane is a **virtual open**.

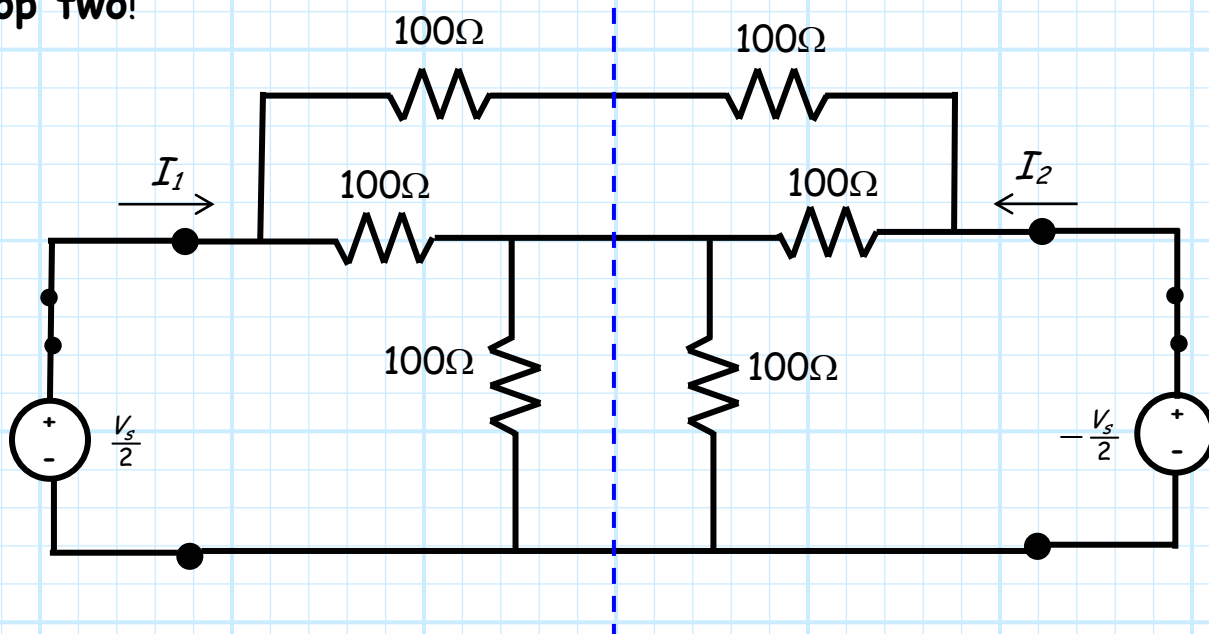
This circuit is referred to as its **even mode**, and analysis of it is known as the **even mode analysis**. The solutions are known as the even mode **currents** and **voltages**!

Evaluating the resulting **even mode** half circuit we find:



$$I_1^e = \frac{V_s}{2} \frac{1}{200} = \frac{V_s}{400} = I_2^e$$

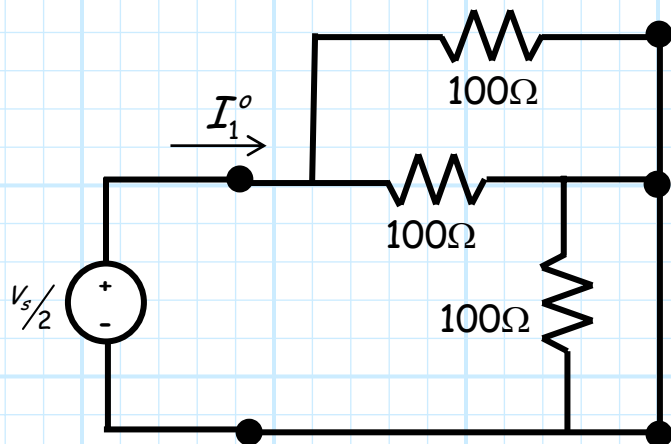
Now, let's turn the bottom sources **back on**—but turn **off** the **top two**!



We now have a circuit with **odd symmetry**—the symmetry plane is a **virtual short**!

This circuit is referred to as its **odd mode**, and analysis of it is known as the **odd mode analysis**. The solutions are known as the odd mode **currents** and **voltages**!

Evaluating the resulting **odd mode** half circuit we find:



$$I_1^o = \frac{V_s}{2} \frac{1}{50} = \frac{V_s}{100} = -I_2^o$$

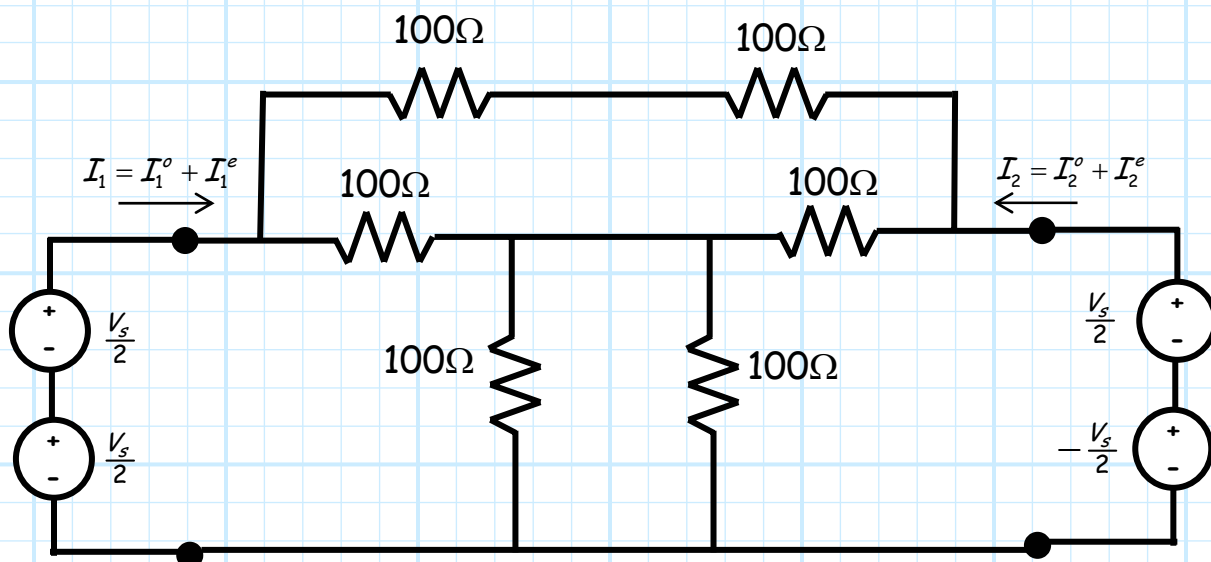
Q: But what good is this "even mode" and "odd mode" analysis? After all, the source on port 1 is $V_{s1} = V_s$, and the source on port 2 is $V_{s2} = 0$. What are the currents I_1 and I_2 for *these* sources?

A: Recall that these sources are the **sum** of the even and odd mode sources:

$$V_{s1} = V_s = \frac{V_s}{2} + \frac{V_s}{2} \quad V_{s2} = 0 = \frac{V_s}{2} - \frac{V_s}{2}$$

and thus—since all the devices in the circuit are **linear**—we know from superposition that the currents I_1 and I_2 are simply the **sum** of the **odd** and **even** mode currents!

$$I_1 = I_1^e + I_1^o \quad I_2 = I_2^e + I_2^o$$



Thus, **adding** the odd and even mode analysis results together:

$$\begin{aligned} I_1 &= I_1^e + I_1^o \\ &= \frac{V_s}{400} + \frac{V_s}{100} \\ &= \frac{V_s}{80} \end{aligned}$$

$$\begin{aligned} I_2 &= I_2^e + I_2^o \\ &= \frac{V_s}{400} - \frac{V_s}{100} \\ &= -\frac{3V_s}{400} \end{aligned}$$

And then the **admittance parameters** for this two port network is:

$$y_{11} = \left. \frac{I_1}{V_{s1}} \right|_{V_{s2}=0} = \frac{V_s}{80} \frac{1}{V_s} = \frac{1}{80}$$

$$y_{21} = \left. \frac{I_2}{V_{s1}} \right|_{V_{s2}=0} = -\frac{3V_s}{400} \frac{1}{V_s} = \frac{-3}{400}$$

And from the **symmetry** of the device we know:

$$y_{22} = y_{11} = \frac{1}{80}$$

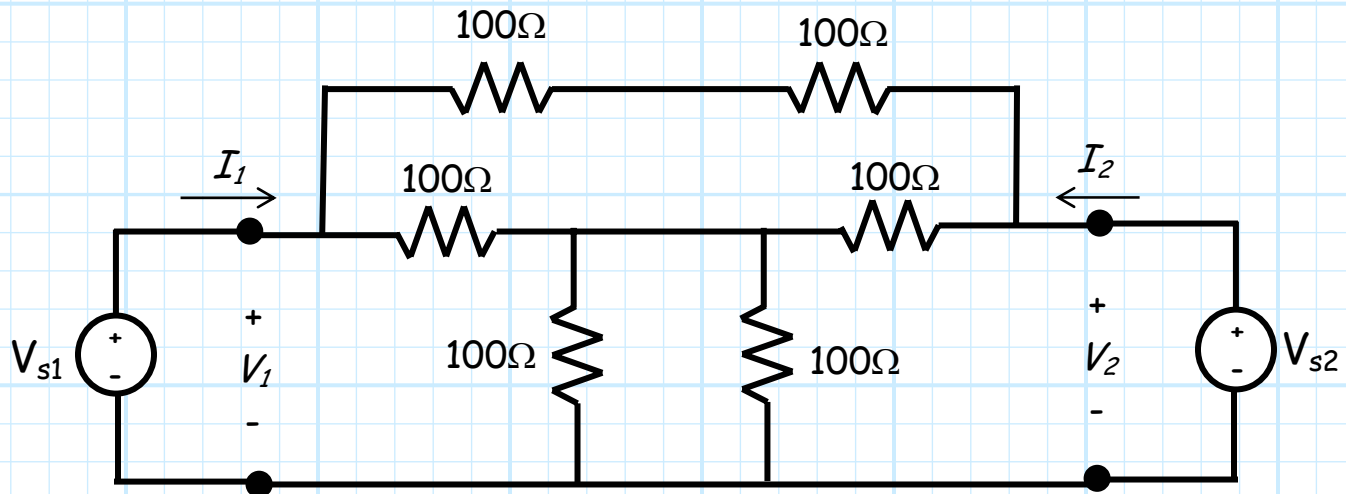
$$y_{12} = y_{21} = \frac{-3}{400}$$

Thus, the full **admittance matrix** is:

$$y = \begin{bmatrix} \frac{1}{80} & \frac{-3}{400} \\ \frac{-3}{400} & \frac{1}{80} \end{bmatrix}$$

Q: What happens if **both sources are non-zero**? Can we use symmetry then?

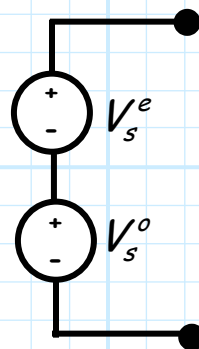
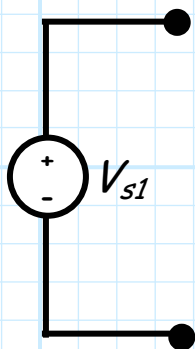
A: Absolutely! Consider the problem below, where **neither** source is equal to zero:



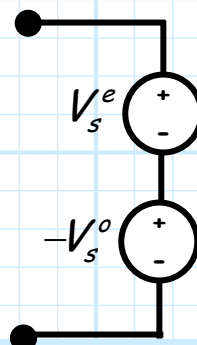
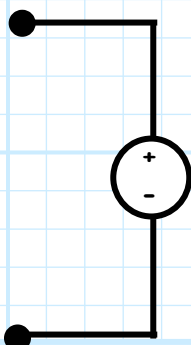
In this case we can define an even mode and an odd mode source as:

$$V_s^e = \frac{V_{s1} + V_{s2}}{2}$$

$$V_s^o = \frac{V_{s1} - V_{s2}}{2}$$

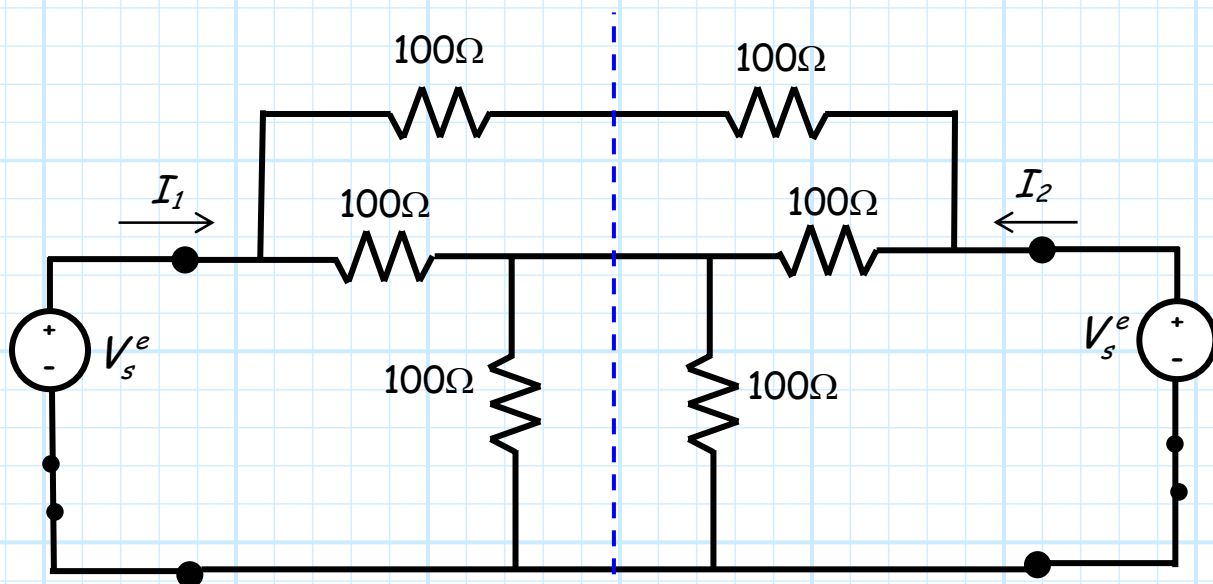


$$V_{s1} = V_s^e + V_s^o$$

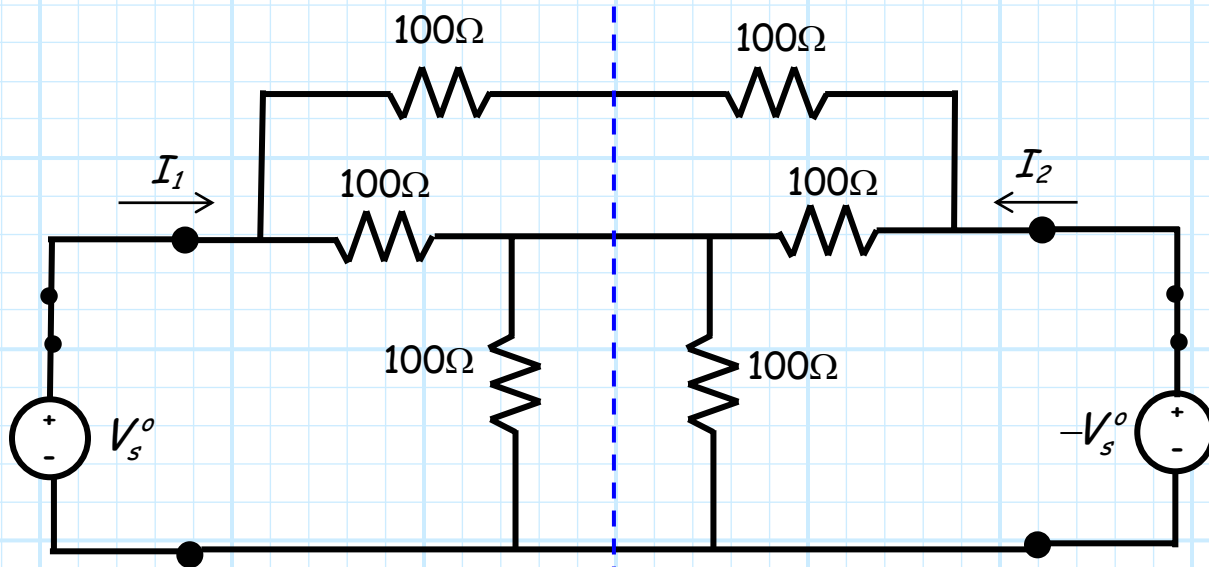


$$V_{s2} = V_s^e - V_s^o$$

We then can analyze the **even mode** circuit:



And then the **odd mode** circuit:



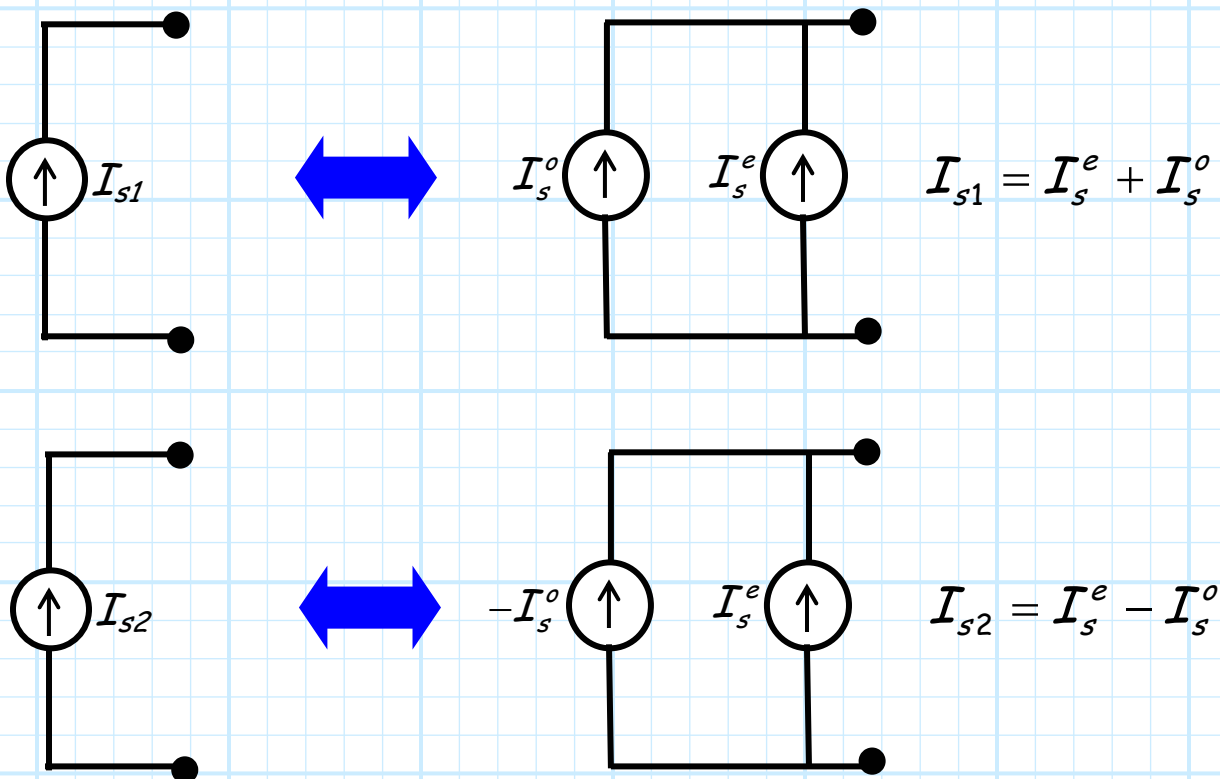
And then combine these results in a **linear superposition!**

Q: What about **current sources**? Can I likewise consider them to be a **sum of an odd mode source and an even mode source**?

A: Yes, but be **very careful!** The current of two source will add if they are placed in **parallel**—not in series! Therefore:

$$I_s^e = \frac{I_{s1} + I_{s2}}{2}$$

$$I_s^o = \frac{I_{s1} - I_{s2}}{2}$$

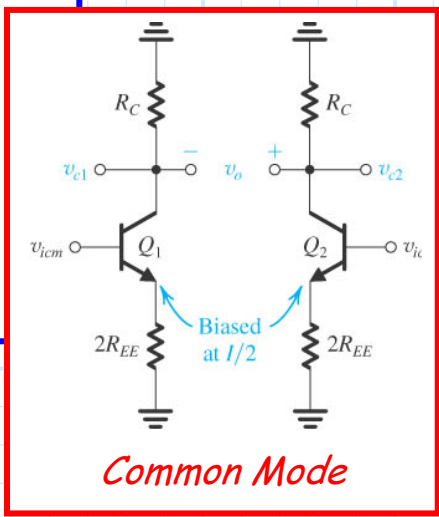
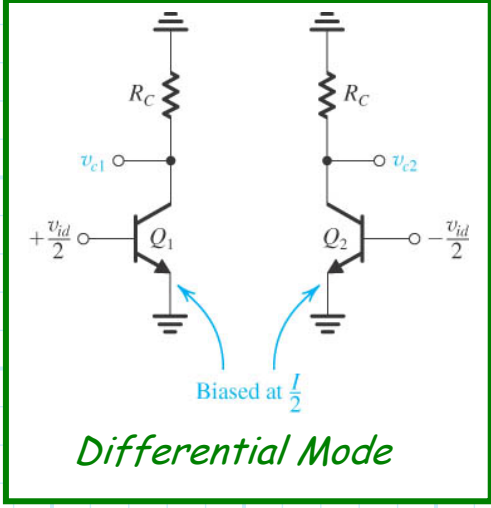
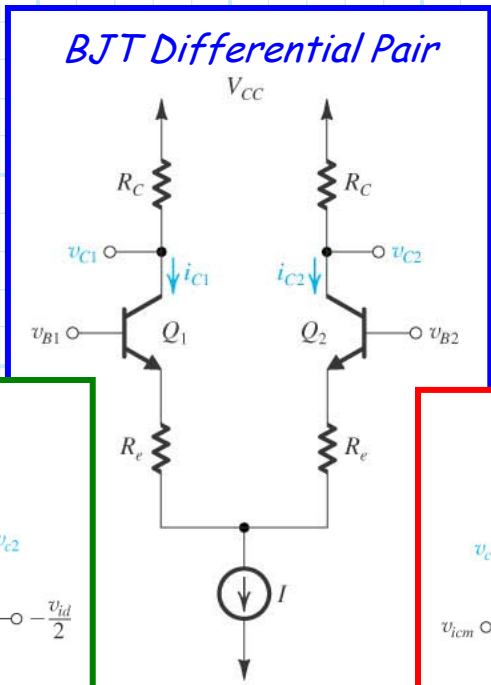


One **final** word (I promise!) about circuit symmetry and even/odd mode analysis: **precisely the same** concept exists in **electronic circuit design!**

Specifically, the **differential** (odd) and **common** (even) **mode** analysis of bilaterally symmetric electronic circuits, such as **differential amplifiers!**

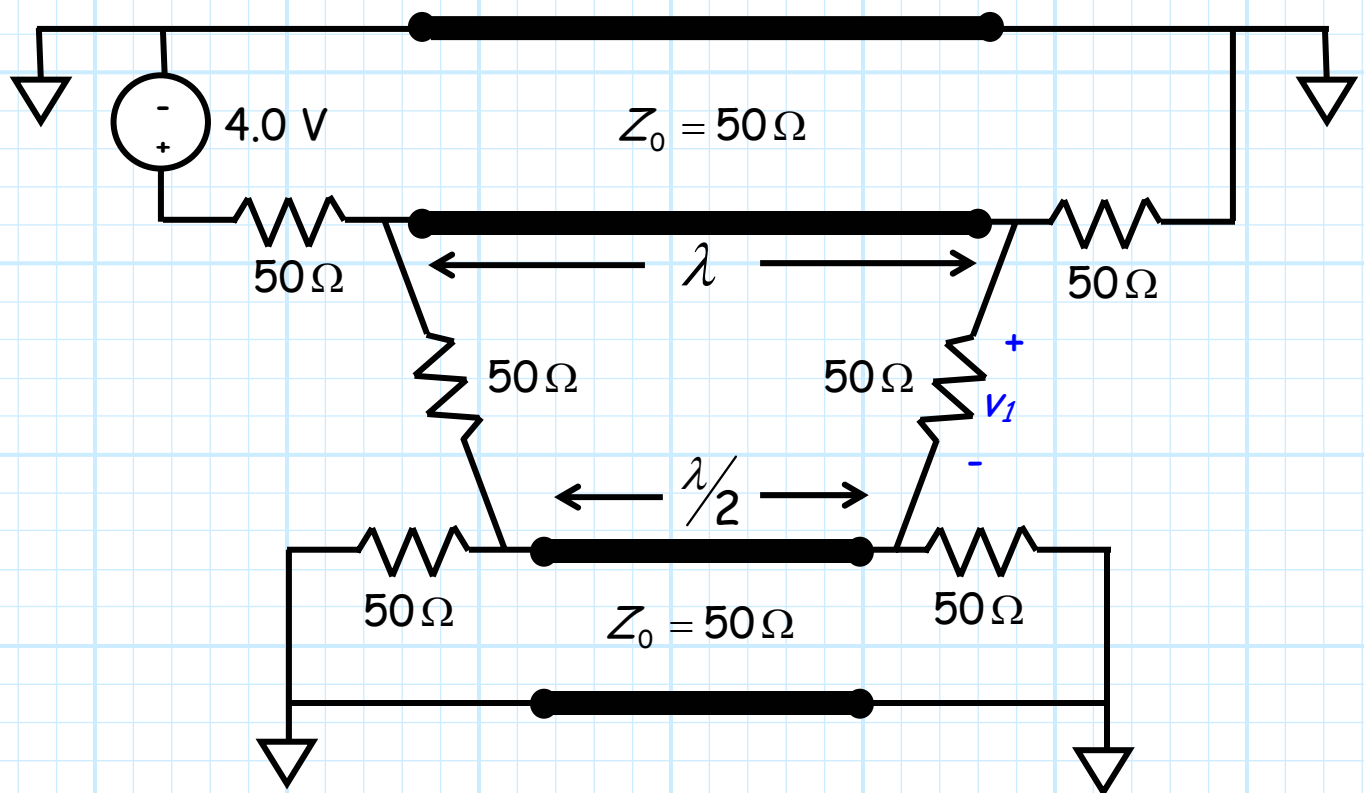


Hi! You might remember differential and common mode analysis from such classes as "EECS 412- Electronics II", or handouts such as "Differential Mode Small-Signal Analysis of BJT Differential Pairs"



Example: Odd-Even Mode Circuit Analysis

Carefully (*very* carefully) consider the **symmetric** circuit below.

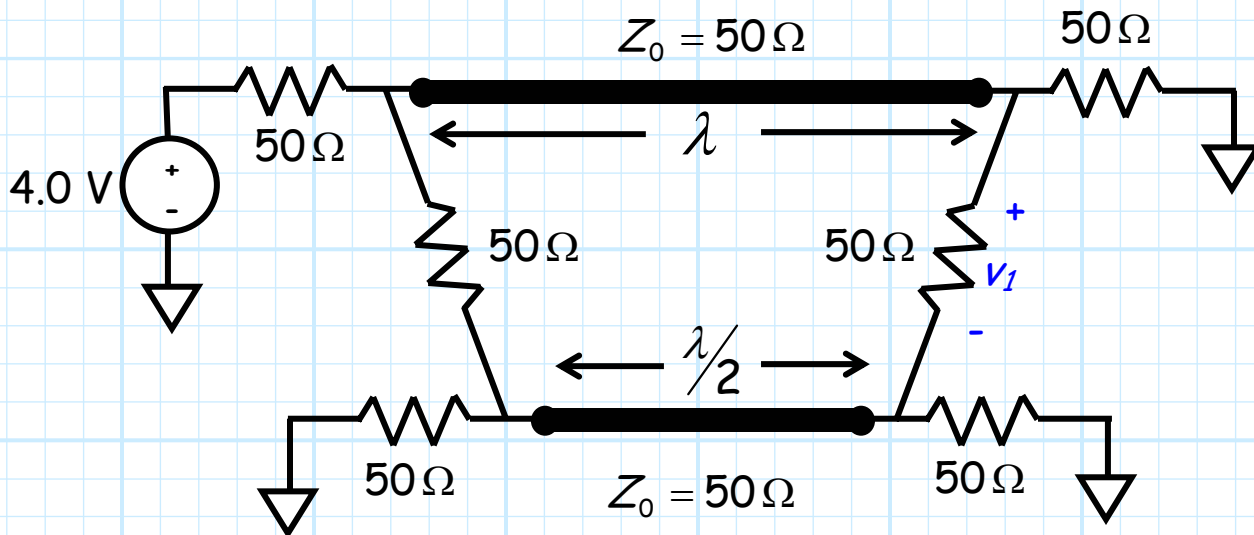


The two transmission lines each have a characteristic impedance of $50\ \Omega$.

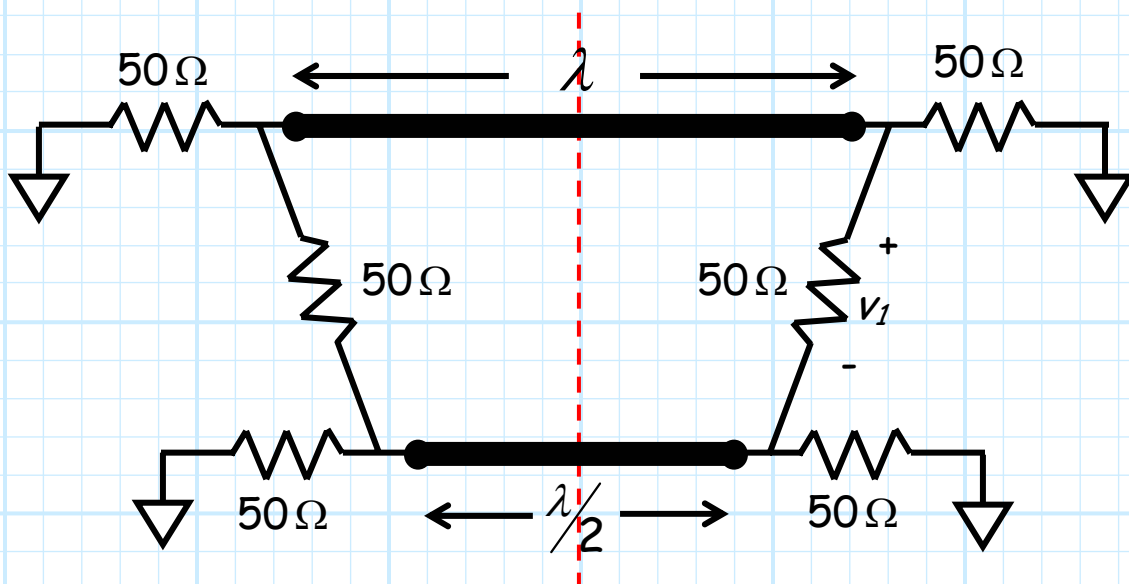
Use **odd-even mode analysis** to determine the value of voltage v_1 .

Solution

To simplify the circuit schematic, we first remove the bottom (i.e., ground) conductor of each transmission line:

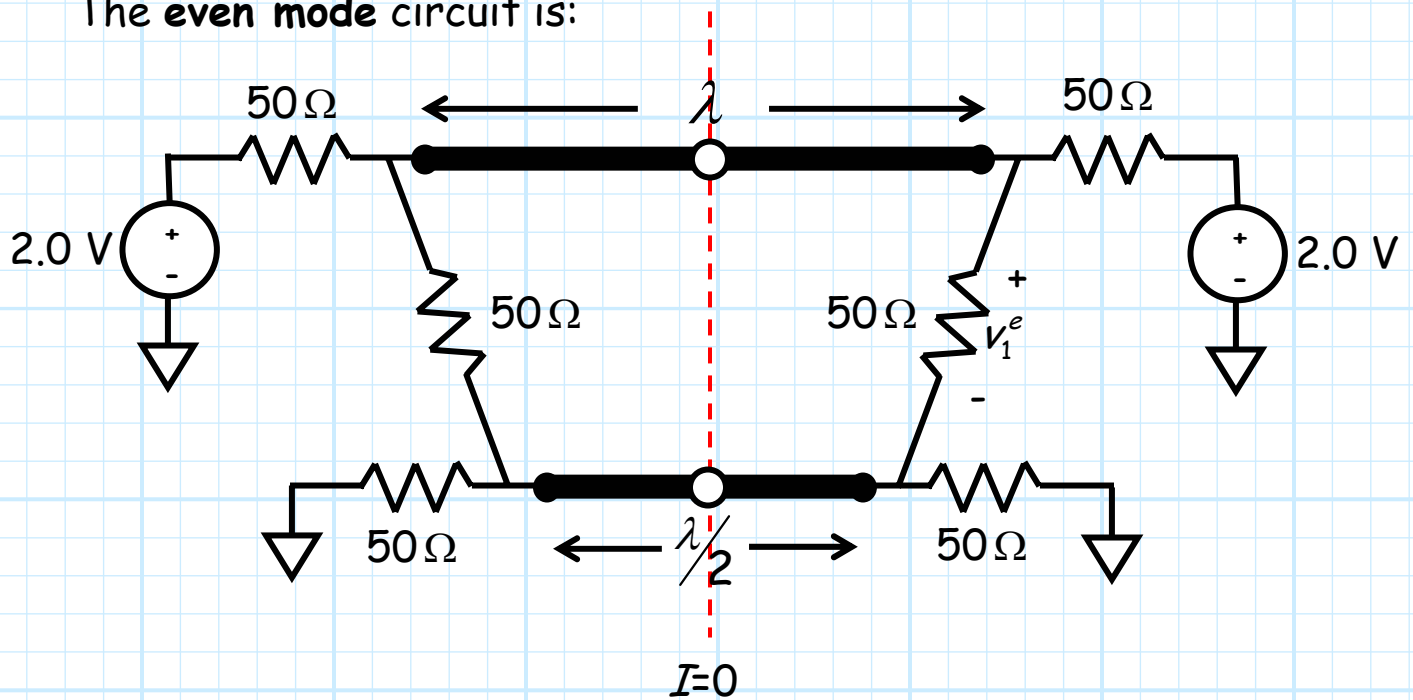


Note that the circuit has one plane of **bilateral symmetry**:

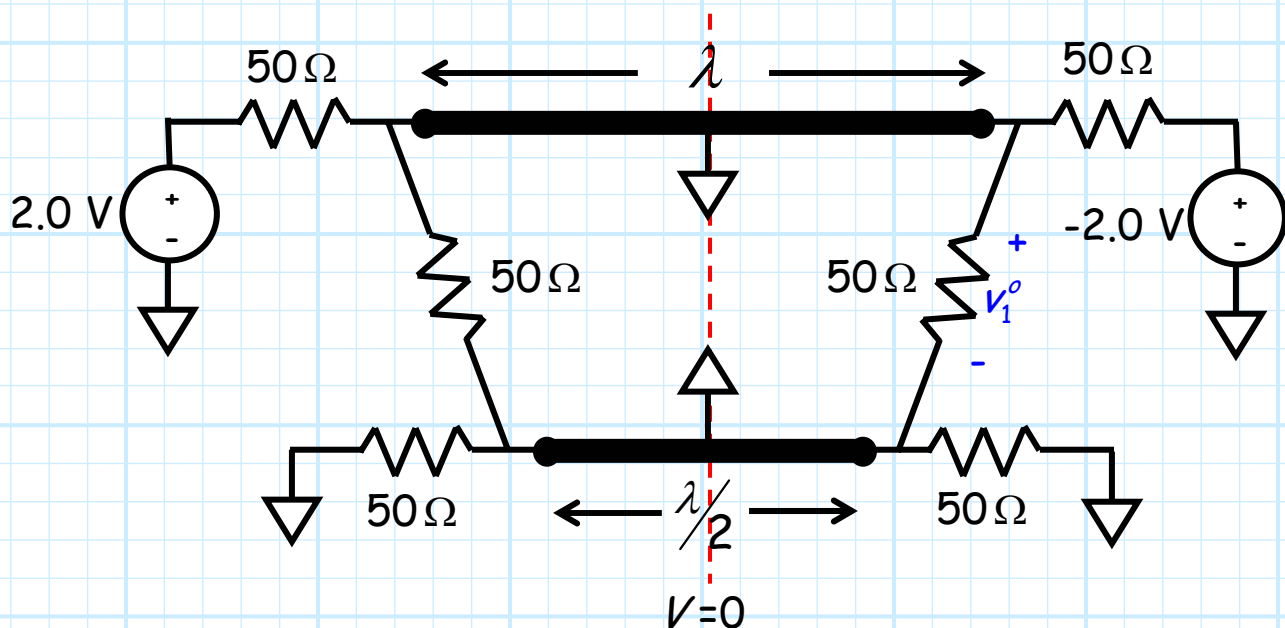


Thus, we can analyze the circuit using **even/odd mode analysis** (Yeah!).

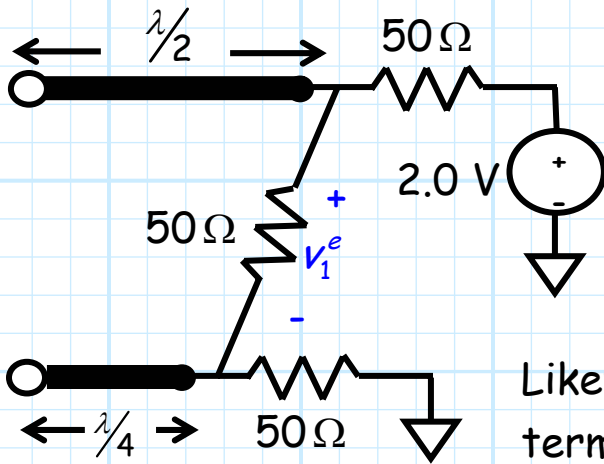
The **even mode** circuit is:



Whereas the **odd mode** circuit is:



We split the modes into half-circuits from which we can determine voltages v_1^e and v_1^o :

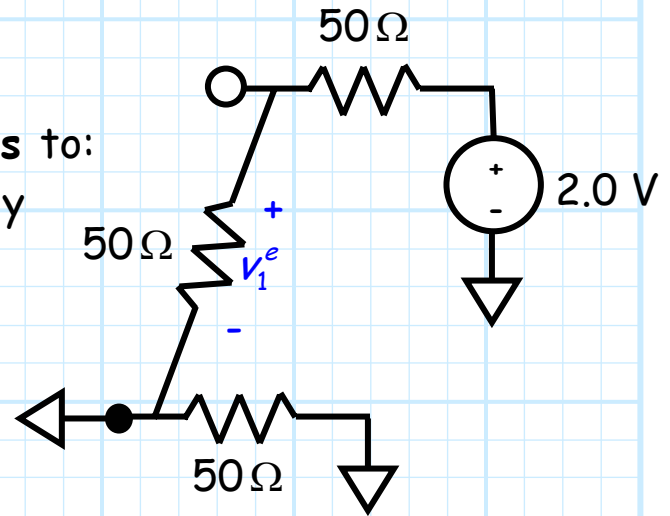


Recall that a $l = \lambda/2$ transmission line terminated in an open circuit has an input impedance of $Z_{in} = \infty$ —an **open** circuit!

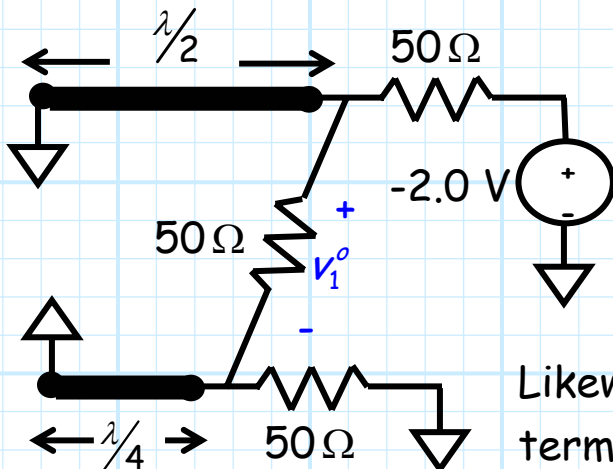
Likewise, a transmission line $l = \lambda/4$ terminated in an open circuit has an input impedance of $Z_{in} = 0$ —a **short** circuit!

Therefore, this half-circuit **simplifies** to:
And therefore the voltage v_1^e is easily determined via voltage division:

$$v_1^e = 2 \left(\frac{50}{50 + 50} \right) = 1.0 \text{ V}$$



Now, examine the right half-circuit of the **odd mode**:

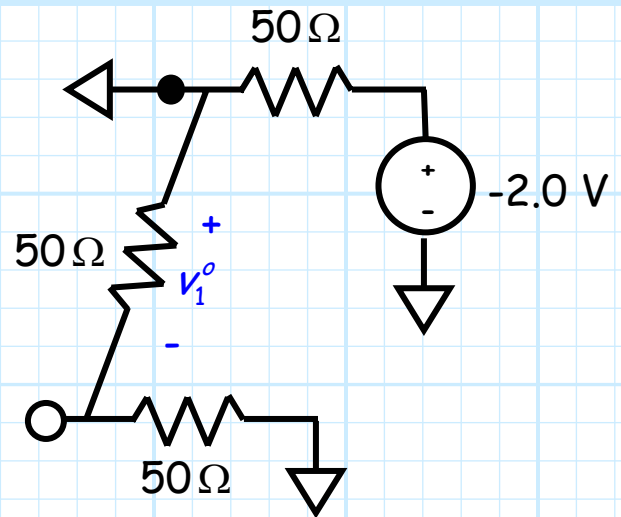


Recall that a $l = \lambda/2$ transmission line terminated in a short circuit has an input impedance of $Z_{in} = 0$ —a **short** circuit!

Likewise, a transmission line $l = \lambda/4$ terminated in an short circuit has an input impedance of $Z_{in} = \infty$ —an **open** circuit!

This half-circuit simplifies to →

It is apparent from the circuit that the voltage $v_1^o = 0$!

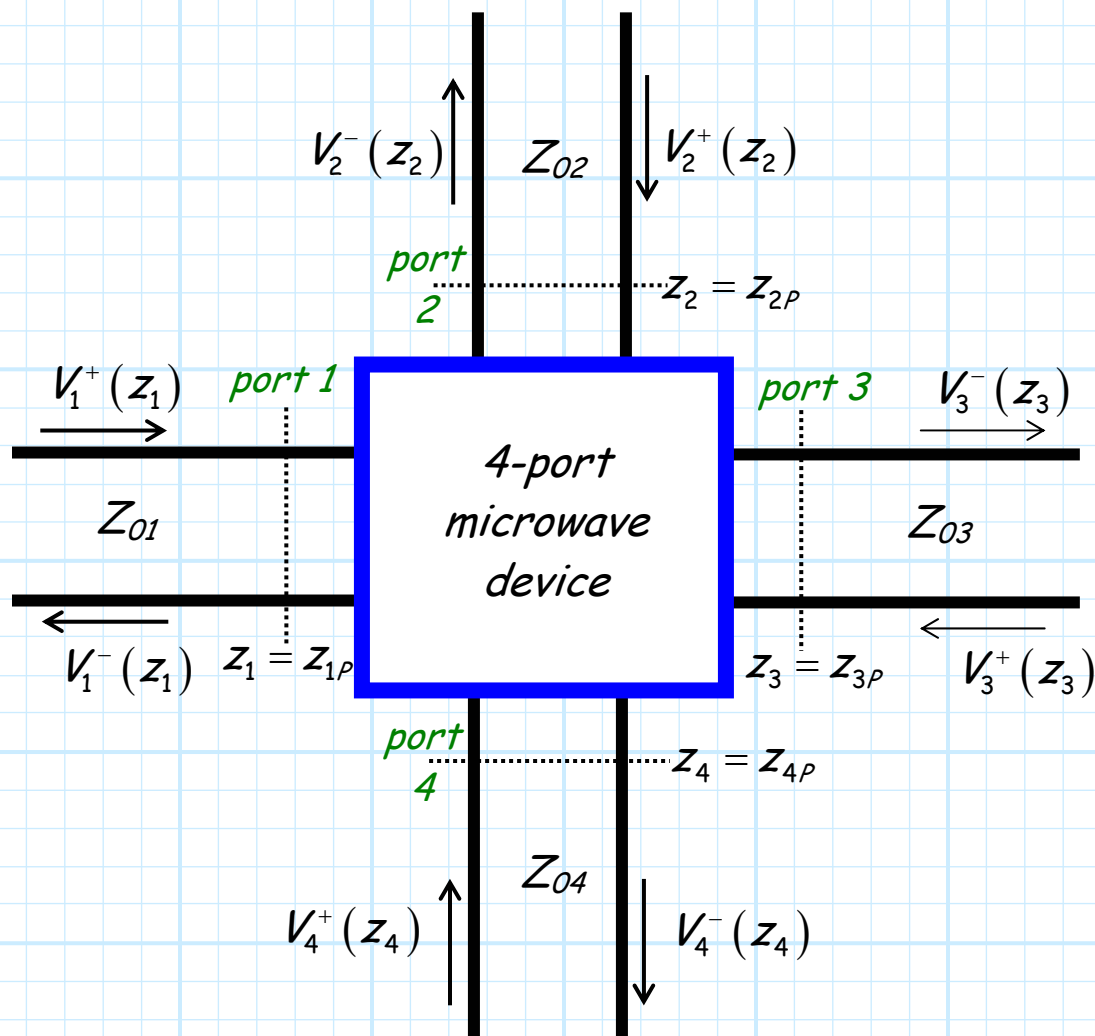


Thus, the superposition of the odd and even modes leads to the result:

$$\underline{v_1} = v_1^e + v_1^o = 1.0 + 0 = \underline{1.0 V}$$

Generalized Scattering Parameters

Consider now this microwave network:



Q: *Boring! We studied this before; this will lead to the definition of scattering parameters, right?*

A: Not exactly. For this network, the **characteristic impedance** of each transmission line is **different** (i.e., $Z_{01} \neq Z_{02} \neq Z_{03} \neq Z_{04}$)!

Q: *Yikes! You said scattering parameters are **dependent** on transmission line characteristic impedance Z_0 . If these values are **different** for each port, **which** Z_0 do we use?*

A: For this **general** case, we must use **generalized scattering parameters!** First, we define a slightly new form of complex wave amplitudes:

$$a_n = \frac{V_{0n}^+}{\sqrt{Z_{0n}}} \quad b_n = \frac{V_{0n}^-}{\sqrt{Z_{0n}}}$$

So for example:

$$a_1 = \frac{V_{01}^+}{\sqrt{Z_{01}}} \quad b_3 = \frac{V_{03}^-}{\sqrt{Z_{03}}}$$

The key things to note are:

a

A **variable a** (e.g., a_1, a_2, \dots) denotes the complex amplitude of an **incident (i.e., plus)** wave.

b

A **variable b** (e.g., b_1, b_2, \dots) denotes the complex amplitude of an **exiting (i.e., minus)** wave.

We now get to **rewrite** all our transmission line knowledge in terms of these generalized complex amplitudes!



First, our two propagating wave amplitudes (i.e., plus and minus) are **compactly** written as:

$$V_{0n}^+ = a_n \sqrt{Z_{0n}} \quad V_{0n}^- = b_n \sqrt{Z_{0n}}$$

And so:

$$V_n^+(z_n) = a_n \sqrt{Z_{0n}} e^{-j\beta z_n}$$

$$V_n^-(z_n) = b_n \sqrt{Z_{0n}} e^{+j\beta z_n}$$

$$\Gamma(z_n) = \frac{b_n}{a_n} e^{+j2\beta z_n}$$

Likewise, the total voltage, current, and impedance are:

$$V_n(z_n) = \sqrt{Z_{0n}} (a_n e^{-j\beta z_n} + b_n e^{+j\beta z_n})$$

$$I_n(z_n) = \frac{a_n e^{-j\beta z_n} - b_n e^{+j\beta z_n}}{\sqrt{Z_{0n}}}$$

$$Z(z_n) = \frac{a_n e^{-j\beta z_n} + b_n e^{+j\beta z_n}}{a_n e^{-j\beta z_n} - b_n e^{+j\beta z_n}}$$

Assuming that our port planes are defined with $z_{np} = 0$, we can determine the total voltage, current, and impedance **at port n** as:

$$V_n \doteq V_n(z_n=0) = \sqrt{Z_{0n}} (a_n + b_n) \quad I_n \doteq I_n(z_n=0) = \frac{a_n - b_n}{\sqrt{Z_{0n}}}$$

$$Z_n \doteq Z(z_n=0) = \frac{a_n + b_n}{a_n - b_n}$$

Likewise, the **power** associated with each wave is:

$$P_n^+ = \frac{|V_{0n}^+|^2}{2Z_{0n}} = \frac{|a_n|^2}{2} \quad P_n^- = \frac{|V_{0n}^-|^2}{2Z_{0n}} = \frac{|b_n|^2}{2}$$

As such, the power **delivered** to port n (i.e., the power **absorbed** by port n) is:

$$P_n = P_n^+ - P_n^- = \frac{|a_n|^2 - |b_n|^2}{2}$$

This result is also **verified**:

$$\begin{aligned} P_n &= \frac{1}{2} \operatorname{Re} \{ V_n I_n^* \} \\ &= \frac{1}{2} \operatorname{Re} \{ (a_n + b_n)(a_n^* - b_n^*) \} \\ &= \frac{1}{2} \operatorname{Re} \{ a_n a_n^* + b_n a_n^* - a_n b_n^* - b_n b_n^* \} \\ &= \frac{1}{2} \operatorname{Re} \{ |a_n|^2 + b_n a_n^* - (b_n a_n^*)^* - |b_n|^2 \} \\ &= \frac{1}{2} \operatorname{Re} \{ |a_n|^2 + j \operatorname{Im} \{ b_n a_n^* \} - |b_n|^2 \} \\ &= \frac{|a_n|^2 - |b_n|^2}{2} \end{aligned}$$

Q: *So what's the big deal? This is yet another way to express transmission line activity. Do we really need to know this, or is this simply a strategy for making the next exam even harder?*

$$Z_1 = \frac{a_1 + b_1}{a_1 - b_1}$$



A: You may have noticed that this notation (a_n, b_n) provides descriptions that are a bit “cleaner” and more symmetric between current and voltage.

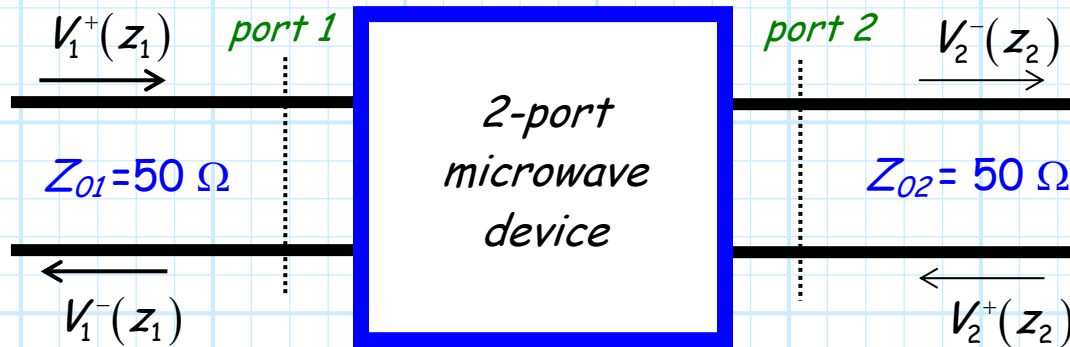
However, the **main reason** for this notation is for evaluating the **scattering parameters** of a device with **dissimilar** transmission line impedance (e.g., $Z_{01} \neq Z_{02} \neq Z_{03} \neq Z_{04}$).

For these cases we must use **generalized scattering parameters**:

$$S_{mn} = \frac{V_{0m}^-}{V_{0n}^+} \frac{\sqrt{Z_{0n}}}{\sqrt{Z_{0m}}} \quad (\text{when } V_k^+(z_k) = 0 \text{ for all } k \neq n)$$

Note that if the transmission lines at each port are identical ($Z_{0m} = Z_{0n}$), the scattering parameter definition "reverts back" to the original (i.e., $S_{mn} = V_{0m}^- / V_{0n}^+$ if $Z_{0m} = Z_{0n}$). E.G.:

$$S_{21} = \frac{V_{02}^-}{V_{01}^+} \quad \text{when } V_{02}^+ = 0$$



But, if the transmission lines at each port are **dissimilar** ($Z_{0m} \neq Z_{0n}$), our original scattering parameter definition is **not correct** (i.e., $S_{mn} \neq V_{0m}^- / V_{0n}^+$ if $Z_{0m} \neq Z_{0n}$)! E.G.:

$$S_{21} \neq \frac{V_{02}^-}{V_{01}^+} \quad \text{when } V_{02}^+ = 0$$



$$S_{21} = \frac{V_{02}^-}{V_{01}^+} \frac{\sqrt{50}}{\sqrt{75}} \quad \text{when } V_{02}^+ = 0$$

Note that the generalized scattering parameters can be more **compactly** written in terms of our **new** wave amplitude notation:

$$S_{mn} = \frac{V_{0m}^-}{V_{0n}^+} \frac{\sqrt{Z_{0n}}}{\sqrt{Z_{0m}}} = \frac{b_m}{a_n} \quad (\text{when } a_k = 0 \text{ for all } k \neq n)$$

Remember, this is the **generalized** form of scattering parameter—it **always** provides the correct answer, **regardless** of the values of Z_{0m} or Z_{0n} !

Q: *But why can't we define the scattering parameter as $S_{mn} = V_{0m}^- / V_{0n}^+$, regardless of Z_{0m} or Z_{0n} ?? Who says we must define it with those **awful** $\sqrt{Z_{0n}}$ values in there?*

A: Good question! Recall that a lossless device is will **always** have a **unitary** scattering matrix. As a result, the scattering parameters of a lossless device will **always** satisfy, for example:

$$1 = \sum_{m=1}^M |S_{mn}|^2$$

This is true **only** if the scattering parameters are **generalized**!

The scattering parameters of a lossless device will form a unitary matrix **only** if defined as $S_{mn} = b_m/a_n$. If we use $S_{mn} = V_{0m}^-/V_{0n}^+$, the matrix will be unitary **only** if the connecting transmission lines have the **same** characteristic impedance.

Q: *Do we really care if the matrix of a lossless device is unitary or not?*

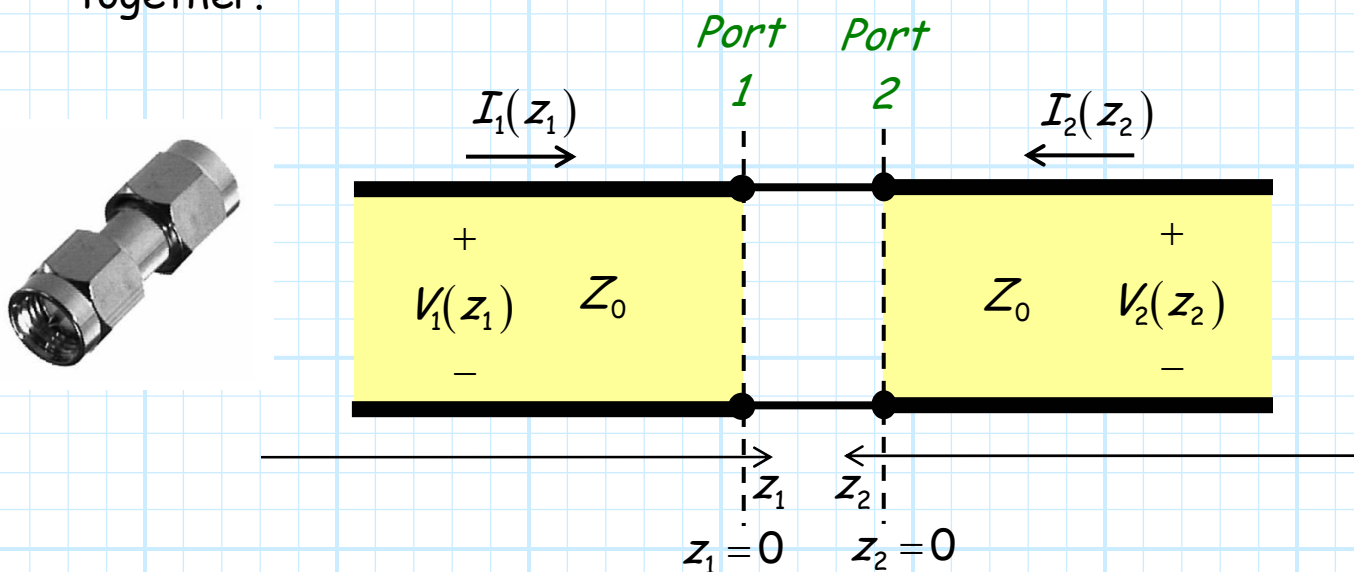
A: **Absolutely** we do! The:

lossless device \Leftrightarrow unitary scattering matrix

relationship is a very powerful one. It allows us to **identify** lossless devices, and it allows us to determine **if** specific lossless devices are **even possible!**

Example: The Scattering Matrix of a Connector

First, let's consider the scattering matrix of a **perfect connector**—an electrically **very small** two-port device that allows us to connect the ends of different transmission lines together.



If the connector is ideal, then it will exhibit **no series inductance nor shunt capacitance**, and thus from KVL and KCL:

$$V_1(z_1 = 0) = V_2(z_2 = 0) \quad I_1(z_1 = 0) = -I_2(z_2 = 0)$$

Terminating **port 2 in a matched load**, and then analyzing the resulting circuit, we find that (not surprisingly!):

$$V_{01}^- = 0 \quad \text{and} \quad V_{02}^- = V_{01}^+$$

From this we conclude that (since $V_{02}^+ = 0$):

$$S_{11} = \frac{V_{01}^-}{V_{01}^+} = \frac{0}{V_{01}^+} = 0.0$$

$$S_{21} = \frac{V_{02}^-}{V_{01}^+} = \frac{V_{01}^+}{V_{01}^+} = 1.0$$

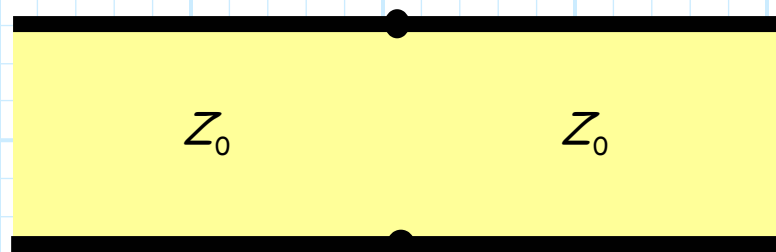
This two-port device has D_2 symmetry (a plane of bilateral symmetry), meaning:

$$S_{22} = S_{11} = 0.0 \quad \text{and} \quad S_{21} = S_{12} = 1.0$$

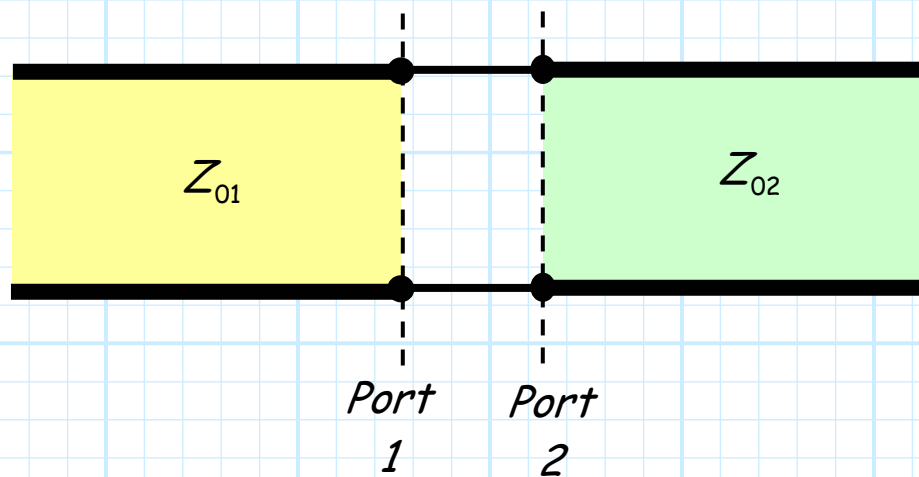
The **scattering matrix** for such this ideal connector is therefore:

$$S = \begin{bmatrix} 0 & 1 \\ 1 & 0 \end{bmatrix}$$

As a result, the perfect connector allows two transmission lines of **identical characteristic impedance** to be connected together into one "seamless" transmission line.



Now, however, consider the case where the transmission lines connected together have **dissimilar** characteristic impedances (i.e., $Z_0 \neq Z_1$):



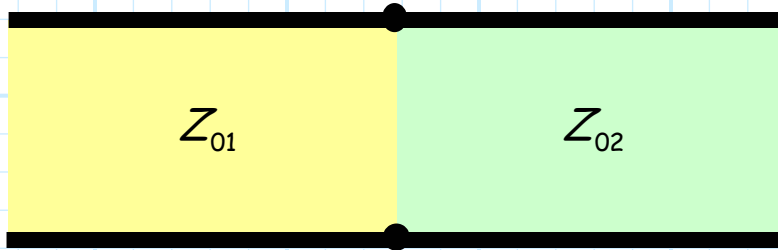
Q: *Won't the scattering matrix of this ideal connector remain the **same**? After all, the **device itself** has not changed!*

A: The impedance, admittance, and transmission matrix **will** remain unchanged—these matrix quantities **do not** depend on the characteristics of the transmission lines connected to the device.

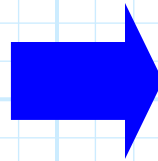
But remember, the **scattering matrix** depends on **both** the device **and** the characteristic impedance of the transmission lines attached to it.

➔ After all, the **incident** and **exiting** waves are traveling on these transmission lines!

The ideal connector in this case establishes a "seamless" **interface** between two **dissimilar** transmission lines.



Remember, this is the **same** structure that we evaluated in an **earlier** handout!



1/31/2007 The Transmission Coefficient T 5/6

Example: The Transmission Coefficient T

Consider this circuit:

I.E., a transmission line with characteristic impedance Z_1 transitions to a different transmission line at location $z=0$. This second transmission line has different characteristic impedance Z_2 ($Z_1 \neq Z_2$). This second line is terminated with a load $Z_L = Z_2$ (i.e., the second line is matched).

Q: What is the voltage and current along each of these two transmission lines? More specifically, what are V_{01}^- , V_{01}^+ , V_{02}^- and V_{02}^+ ??

A: Since a source has not been specified, we can only determine V_{01}^- , V_{02}^- and V_{02}^+ in terms of complex constant V_{01}^+ . To accomplish this, we must apply a boundary condition at $z=0$!

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In that analysis we found that—when $V_{02}^+ = 0$:

$$\frac{V_{01}^-}{V_{01}^+} = \frac{Z_{02} - Z_{01}}{Z_{02} + Z_{01}} \quad \text{and} \quad \frac{V_{02}^-}{V_{01}^+} = \frac{2Z_{02}}{Z_{02} + Z_{01}}$$

And so the (generalized) scattering parameters S_{11} and S_{21} are:

$$S_{11} = \frac{V_{01}^-}{V_{01}^+} \frac{\sqrt{Z_{01}}}{\sqrt{Z_{01}}} = \frac{Z_{02} - Z_{01}}{Z_{02} + Z_{01}} \quad \text{and} \quad S_{21} = \frac{V_{02}^-}{V_{01}^+} \frac{\sqrt{Z_{01}}}{\sqrt{Z_{02}}} = \frac{2\sqrt{Z_{01}Z_{02}}}{Z_{02} + Z_{01}}$$

As a result we can conclude that the **scattering matrix** of the ideal connector (when connecting dissimilar transmission lines) is:

$$S = \begin{bmatrix} \frac{Z_{02} - Z_{01}}{Z_{02} + Z_{01}} & \frac{2\sqrt{Z_{01}Z_{02}}}{Z_{01} + Z_{02}} \\ \frac{2\sqrt{Z_{01}Z_{02}}}{Z_{01} + Z_{02}} & \frac{Z_{01} - Z_{02}}{Z_{01} + Z_{02}} \end{bmatrix}$$